

OICOM

SERVICE MANUAL

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Icom Inc.

INTRODUCTION

This service manual describes the latest service information for the IC-725 HF ALL BAND TRANSCEIVER at the time of going to press.

If you require assistance or further information regarding the operation and capabilities of the **IC-725**, contact your nearest authorized Icom Dealer or Icom Service Center.

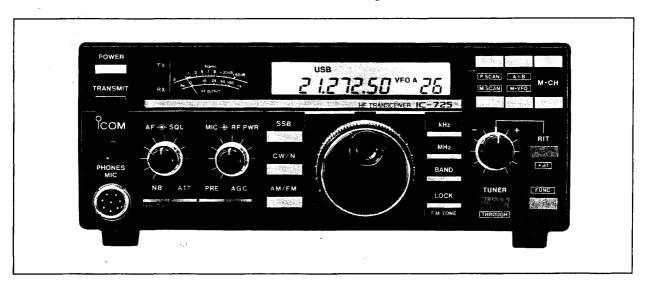
DANGER

NEVER connect the transceiver to an AC outlet or to a DC power supply that uses more than 16 V. This will ruin the transceiver.

DO NOT expose the transceiver to rain, snow or any liquids.

DO NOT reverse the polarities of the power supply when connecting the transceiver.

DO NOT apply an RF signal of more than 20 dBm (100 mW) to the antenna connector. This could damage the transceiver's front end.



ORDERING PARTS

Be sure to include the following four points when ordering replacement parts:

- 1. 10-digit order numbers
- 2. Component part number and name
- 3. Equipment model name and unit name
- Quantity required

<SAMPLE ORDER>

1110001310 IC µPC577HA IC-725 MAIN UNIT 5 pieces 8810005510 Screw PH M3 × 6 ZK BS IC-725 Top cover 10 pieces

Addresses are provided on the inside back cover for your convenience.

REPAIR NOTE

- Make sure a problem is internal before disassembling the transceiver.
- DO NOT open the transceiver until the transceiver is disconnected from a power source.
- DO NOT force any of the variable components. Turn them slowly and smoothly.
- DO NOT short any circuits or electronic parts.
 An insulated tuning tool MUST be used for all adjustments.
- 5. **DO NOT** keep power ON for a long time when the transceiver is defective.
- DO NOT transmit power into a signal generator or a sweep generator.
- 7 ALWAYS connect a 40 dB~50 dB attenuator between the transceiver and a deviation meter or spectrum analyzer when using such test equipment.
- 8. **READ** the instructions of test equipment thoroughly before connecting equipment to the transceiver.

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SECTION 1 SPECIFICATIONS

GENERAL

• Frequency coverage : Receive 500 kHz~30 MHz

Transmit 160-m band 1.8~ 2.0 MHz 17-m band 18.068~18.168 MHz

80-m band 3.5~ 4.0 MHz 15-m band 21.0 ~21.45 MHz 40-m band 7.0~ 7.3 MHz 12-m band 24.89 ~24.99 MHz

30-m band 10.1~10.15 MHz 10-m band 28.0 ~29.7 MHz

20-m band 14.0~14.35 MHz

• Modes : SSB (A3J), CW (A1), AM (A3), FM (F3)

(UI-7 AM · FM UNIT is required for AM transmit and FM transmit/receive.)

• Number of memory channels : 26

Antenna impedance : 50 Ω unbalanced

Usable temperature range : −10 °C~+60 °C (+14 °F~+140 °F)

Frequency stability: Less than ±200 Hz up to one hour after power is turned ON.

Less than ± 30 Hz after one hour at +25 °C (+77 °F). Less than ± 350 Hz at 0 °C $\sim +50$ °C (+32 °F $\sim +122$ °F).

• Power supply requirement : 13.8 V DC ±15 %, negative ground

Current drain (at 13.8 V DC)
 Receive squelched 1.2 A max. audio output 1.5 A

Transmit 20 A

• Dimensions : 241 (W) × 94 (H) × 239 (D) mm

9.5 (W) × 3.7 (H) × 9.4 (D) in (Projections not included)

• Weight : 4.6 kg (10.1 lb)

TRANSMITTER

Output power
 SSB, CW, FM 10~100 W continuously adjustable

AM 10~40 W continuously adjustable

• Spurious emissions : More than 50 dB below peak output power

Carrier suppression
 Unwanted sideband
 More than 40 dB below peak output power
 More than 50 dB down with 1 kHz AF input

• Microphone impedance : 600 Ω

■ RECEIVER

Receive system : SSB, CW, AM Double-conversion superheterodyne

FM Triple-conversion superheterodyne

• Intermediate frequencies : 1st SSB 70.4515 MHz

CW 70.4506 MHz AM, FM 70.4500 MHz

2nd SSB 9.0115 **M**Hz

CW 9.0106 MHz AM, FM 9.0100 MHz

3rd FM 455 kHz

• Sensitivity (preamplifier ON) : SSB, CW (10 dB S/N) 1.8~30 MHz Less than 0.15 μV (-123 dBm)

AM (10 dB S/N) $0.5\sim1.8$ MHz Less than 13.0 μ V (-85 dBm)

1.8 \sim 30 MHz Less than 2.0 μ V (-101 dBm)

FM (12 dB SINAD) 28 \sim 30 MHz Less than 0.5 μ V (-113 dBm)

• FM squelch sensitivity : Less than 0.3 μV (preamplifier ON)

• Selectivity : SSB, CW More than 2.3 kHz/-6 dB Less than 4.0 kHz/-60 dB

AM More than 6.0 kHz/-6 dB Less than 20.0 kHz/-40 dB FM More than 15 kHz/-6 dB Less than 30 kHz/-50 dB

• Spurious response rejection : More than 70 dB

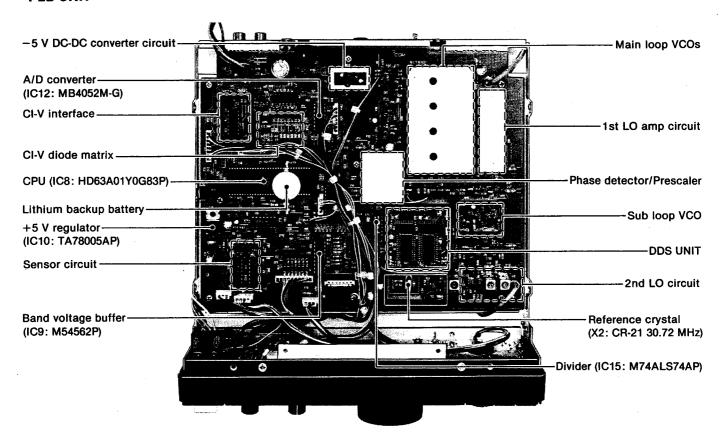
• Audio output impedance : 8 Ω

• Audio output power : More than 2.6 W at 10 % distortion with an 8 Ω load

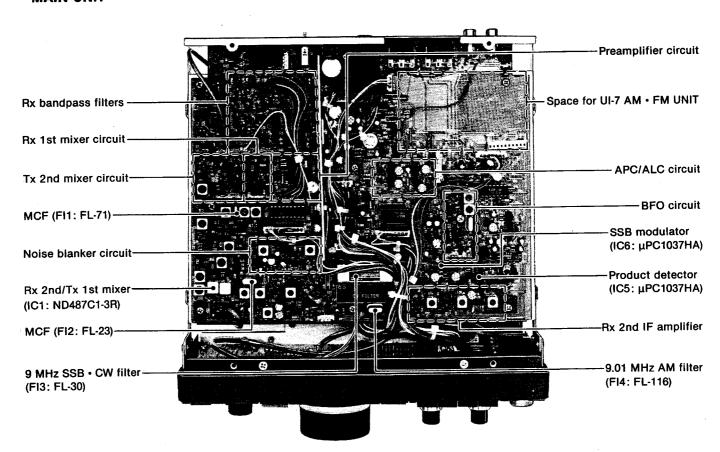
• RIT variable range : More than ±1 kHz

SECTION 2 INSIDE VIEWS

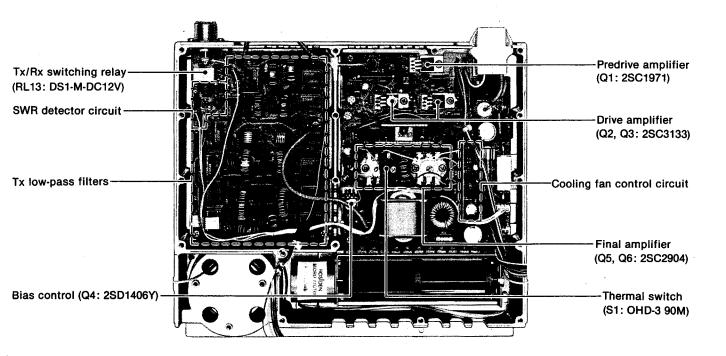
• PLL UNIT

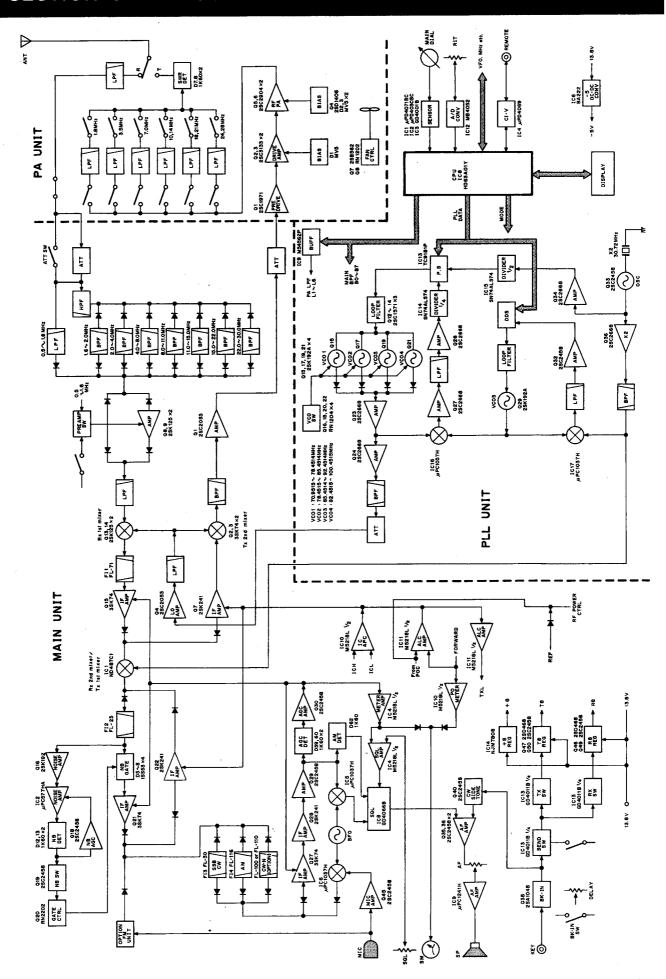


• MAIN UNIT



• PA AND FILTER UNITS





SECTION 4 CIRCUIT DESCRIPTION

4-1 RECEIVER CIRCUITS

4-1-1 RF SWITCHING CIRCUIT (PA AND MAIN UNITS)

RF signals from the antenna connector pass through the transmit/receive switching relay (RL13) and a low-pass filter, and are applied to the MAIN UNIT via P2 (MAIN UNIT: J12).

The signals from the PA UNIT either bypass or are attenuated at 20 dB attenuator (R102, R103, RL1). There are no non-linear components between the antenna connector and attenuator to prevent distortion caused by strong signals. The signals are then applied to RF filters.

4-1-2 RF BANDPASS FILTER CIRCUIT (MAIN UNIT)

The RF UNIT has 7 RF bandpass filters (BPF) for signals above 1.6 MHz and 1 low-pass filter (LPF) for signals below 1.6 MHz. The signals pass through one of the bandpass or low-pass filters depending on the receive frequency range.

(1) 0.5~1.6 MHz

A diode is not used at the low-pass filter entrance removing diode distortion from very strong signals. Signals bypass a preamplifier by the bypass switch (Q12).

(2) 1.6 MHz AND ABOVE

Signals are applied to a high-pass filter consisting of L42, L43, C143~C146. This filter suppresses strong signals below 1.6 MHz such as a broadcasting station.

The filtered signals are applied to one of 7 bandpass filters depending on the frequency of the signals and then to the preamplifier circuit (Q8, Q9).

(3) FILTER SWITCHING CIRCUIT

An RF bandpass filter is selected with BPF switching voltage (B0~B7) from the CPU via IC16 current amplifier. The switching voltage of the BPF entrance is higher than the BPF exit to improve multi-signal and strong signal characteristics.

4-1-3 PREAMPLIFIER CIRCUIT (MAIN UNIT)

The preamplifier circuit uses low-noise junction FETs (2SK125×2) to provide 10 dB gain over a wideband frequency range.

When the [PRE] switch is turned ON, the signals from the RF filter are amplified by the preamplifier circuit (Q8, Q9). When the [PRE] switch is turned OFF, the signals bypass the preamplifier through D30 and D32. When the operating frequency is below 1.6 MHz, Q12 turns ON and the signals bypass the preamplifier regardless of the [PRE] switch.

Amplified or bypassed signals are applied to the 1st mixer circuit via the low-pass filter. The low-pass filter cuts off at 35 MHz to suppress image frequency at the 1st mixer circuit (Q13, Q14).

PREAMP CIRCUIT

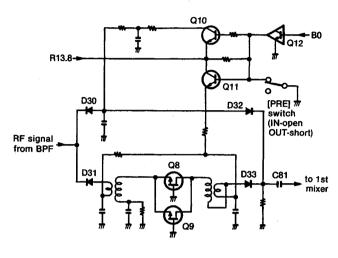


Fig. 1

4-1-4 1ST MIXER CIRCUITS (MAIN UNIT)

The signals from the low-pass filter enter the 1st mixer circuit (Q13, Q14) to be converted to a 70.45 MHz 1st IF signal.

EXACTNESS 1ST IF FREQUENCY

MODE	FREQUENCY (MHz)
SSB	70.4515
CW	70.4506
AM, FM	70.4500

The 1st mixer circuit employs a balanced mixer using low-noise junction FETs ($2SK125 \times 2$) to expand the dynamic range.

The 1st LO signal (70.9515~100.4515 MHz) enters the MAIN UNIT from the PLL UNIT via J5. The signal is amplified at Q4, filtered by a low-pass filter, and then applied to the 1st mixer circuit (Q13, Q14). The low-pass filter employs a ring core inductor to prevent 1st LO leakage signals. The output level from Q4 is approx. 25 dBm.

The 1st IF signal is applied to an MCF (Monolithic Crystal Filter; FI1) to suppress out-of-band signals. The signal is amplified at the 1st IF amplifier (Q15), and then applied to the 2nd mixer (IC1).

4-1-5 IF CIRCUITS (MAIN UNIT)

The 1st IF signal from Q15 is converted to a 9 MHz 2nd IF signal at the 2nd mixer (IC1). IC1 is a DBM (Double Balanced Mixer).

EXACTNESS 2ND IF FREQUENCY

MODE	FREQUENCY (MHz)
SSB	9.0115
CW	9.0106
AM, FM	9.0100

The 2nd LO signal (61.44 MHz) from the PLL UNIT via J4 is applied to the 2nd mixer. The converted 2nd IF signal passes through D4 (D35 for transmitting) and is applied to the MCF (FI2) to suppress unwanted signals.

The signal output from FI2 passes through the noise blanker gate (D5~D8) and is amplified at the 2nd IF amplifier (Q21). The signal enters one of the three 9 MHz filters (FI3, FI4, optional CW narrow filter) or optional AM · FM UNIT via D52. The filters are selected with mode selecting signals (SSB · CW, AM, CW-N) and the "T8" voltage line.

The signal from a 9 MHz filter is amplified at the 2nd IF amplifiers (Q27~Q29) and applied to the demodulator circuit.

Dual-gate FETs are used on the 1st and 2nd IF amplifiers (Q15, Q21, Q27). The 2nd gates of Q15, Q21 and Q27 are controlled by AGC bias voltage. A rapid time constant is used for Q27 to prevent raising the edge distortion of receive signals.

R140, connected to the gate of Q28, improves the temperature characteristics of the receiver gain. R138 adjusts the receiver gain.

4-1-6 NOISE BLANKER CIRCUITS (MAIN UNIT)

The IC-725 uses a noise trigger noise blanker circuit that cuts out pulse-type noise signals at the noise blanker gate $(D5\sim D8)$.

A portion of the signals from FI2 is amplified at the noise amplifiers (Q16, IC2) and detected at the noise detector (D12, D13). The detected voltage from the noise detector is applied to the noise blanker switch (Q19).

The threshold level of the noise blanker switch is set at 0.9 V. When the detected voltage exceeds the threshold level, Q20 outputs a blanking signal to activate the noise blanker gate (D5~D8).

A portion of the detected voltage is applied to the noise AGC circuit (Q18) and fed back to the noise amplifier (IC2) as noise AGC voltages. The time constant of the noise AGC circuit is determined by R43, R47 and C60. This AGC circuit does not operate to detect pulse-type noise.

When the operating frequency or mode is changed, the "DNB" signal line becomes "LOW," turning Q20 ON. The noise blanker gate prevents PLL click noise.

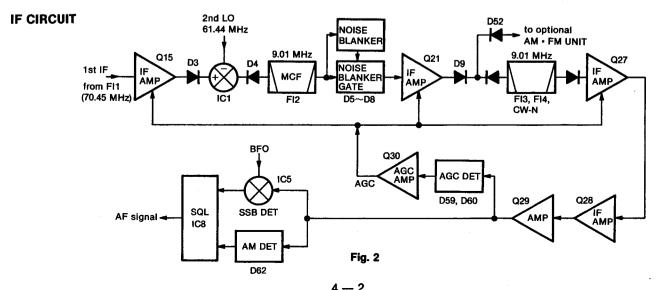
4-1-7 BFO CIRCUIT (MAIN UNIT)

A 9 MHz signal oscillated at the BFO circuit (Q31, X1) is buffer-amplified at Q42 and used at the balanced modulator (IC6) and a product detector (IC5). The BFO frequency is shifted with a mode signal using D67~D69.

In USB mode, the "USB" signal line becomes "HIGH," turning ON D69. The frequency is then adjusted with C294 to set the USB carrier point.

At CW mode transmitting, the "CW" signal line becomes "HIGH" and Q33 becomes OFF, turning ON D68. The frequency is then adjusted with L83 to set the CW transmit carrier point.

In LSB mode, the "LSB" signal line becomes "HIGH," turning ON D67. The frequency is then adjusted with L82 to set the LSB carrier point.



BFO FREQUENCY IN EACH MODE

MODE	FREQUENCY (MHz)
USB	9.0130
CW (Tx)	9.0106
LSB	9.0100
CW (Rx)	9.0098
AM	NO OUTPUT

4-1-8 DEMODULATOR CIRCUITS (MAIN UNIT)

The IC-725 has 2 detector circuits, a product detector and a diode detector to demodulate the SSB, CW signal and AM signal respectively.

In SSB or CW mode, the 2nd IF signal from the IF amplifier (Q29) is mixed with the BFO signal at the product detector (IC5) to demodulate the 2nd IF signal into an AF signal. The detected signal passes through the AF input mode selector switch (IC8).

In AM mode, the 2nd IF signal from Q29 passed through C121 is detected at D62 and passes through the AF input mode selector switch (IC8).

4-1-9 AF INPUT MODE SELECTOR SWITCH (MAIN UNIT)

The AF signal from a detector circuit or the optional AM FM UNIT is applied to the AF input mode selector switch (IC8). IC8 consists of 4 analog switches and they are selected with a mode signal from IC15 and the squelch control signal. The AF signal is applied to the AF amp circuit.

IC8 AF INPUT MODE SELECTOR SWITCH

MODE	ACTIVATING PIN NUMBERS	CONTROL PIN NUMBER
USB, CW	2→1	13
AM	3→4	5
FM	10→11	12
ANY MODES (for S-meter)	9→8	6

4-1-10 AF AMP CIRCUIT (MAIN UNIT)

The AF signal from the AF input mode selector switch is applied to the AF preamplifier (Q35, Q36). The CW sidetone signal is applied to Q36.

The output from the AF preamplifier is applied to the [AF] control (FRONT UNIT, R1 b) and the 2.8 kHz cut-off active low-pass filter (Q37). The AF signal is power-amplified at IC9 to drive the speaker.

4-1-11 AGC AND S-METER CIRCUIT (MAIN UNIT)

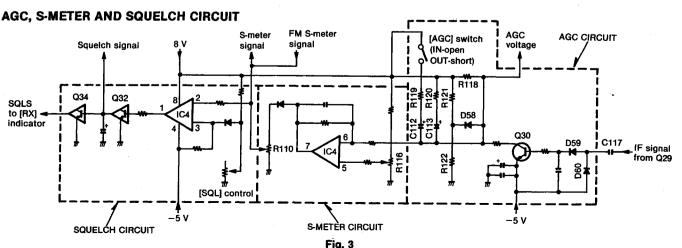
The receiver gain is determined by the voltage on the AGC line (Q30, collector). When strong signals are received, the AGC circuit decreases the voltage on this line.

The IF signal from the IF amplifier (Q29) passes through C117, is detected at D59 and D60, and applied to the base of Q30. A time constant (C113, R120) is connected to the AGC line that determines the AGC release time.

The time constant is controlled by the [AGC] switch. When the [AGC] switch is pushed OUT, C112 and R119 are connected in parallel with the AGC line to obtain a slow AGC release time.

The AGC bias voltage is applied to the differential amplifier (IC4, pin 6) where the difference between the bias and reference voltages is detected. The resulting S-meter signal passes through the meter switching circuit (IC8) and is then applied to the meter on the front panel. The reference voltage is adjusted with R116. IC8 pins 8 and 9 are connected inside the IC in receiving.

The FM S-meter signal from the optional AM \cdot FM UNIT is applied to the meter switching circuit (IC8) via D57. The signal is also applied to the squelch circuit (IC4 pin 2).



4-1-12 SQUELCH CIRCUIT (MAIN UNIT)

The squelch circuit mutes the audio output when the S-meter signal is lower than the [SQL] control setting level.

The S-meter signal from IC4 pin 7 is applied to the comparator (IC4 pin 2) to be compared to a threshold level controlled by the [SQL] control. The squelch control signal is applied to control terminals of the AF input mode selector switch (IC8).

When the S-meter signal is lower than the threshold level, the comparator turns "HIGH" and then Q32 turns OFF to deactivate the AF input mode selector switch. This signal is applied to Q34, turning OFF the [RX] indicator and is also applied to the [MIC] connector pin 4.

4-2 TRANSMITTER CIRCUITS

4-2-1 MIC AMPLIFIER (MAIN UNIT)

Audio signals from the [MIC] connector are applied to the [MIC] control and amplified at the mic amplifier (Q45). External modulation input from the [ACC(1)] socket pin 4 is also applied to Q45 via R255.

The AF signals from Q45 or CW keying signal is applied to the balanced modulator (IC6). Q44 cuts the signals from Q45 in CW or receiving.

4-2-2 BALANCED MODULATOR (MAIN UNIT)

Output signals from the mic amplifier or CW keying signal are applied to the balanced modulator circuit (IC6) to be converted to a 9 MHz IF signal using a BFO signal. The BFO signal, buffer-amplified at Q42, is applied to IC6 pin 7 as a carrier signal. IC6 outputs a double sideband signal and passes through a 9 MHz filter to create an SSB signal.

R177 and R179 adjust the balance level of IC6 for maximum carrier suppression. In CW mode, the CW keying signal upsets the balance to create a carrier signal.

4-2-3 IF CIRCUITS (MAIN UNIT)

The 9 MHz IF signal passes through one of the three 9 MHz filters where unwanted sideband or out-of-band signals are removed. The filters are selected with mode selecting signals and the "T8" voltage line. The optional CW narrow filter is not used in transmitting.

The resulting signal is amplified at Q22, and is then mixed with the 2nd LO signal to be converted to a 70.45 MHz IF signal at IC1. IC1 is used in receiving and transmitting. The FM signal from the optional AM · FM UNIT is amplified at Q22 and is then applied to IC1.

The 70.45 MHz IF signal is amplified at the IF amplifier (Q7) and is then converted to the displayed frequency at the balanced mixer (Q2, Q3).

The gates of the IF amplifiers (Q7, Q22) are controlled by ALC bias voltage from the ALC circuit. R89, connected to the gate of Q22, improves the temperature characteristics of the transmitter gain. R85 adjusts the transmitter gain.

4-2-4 RF CIRCUITS (MAIN AND PA UNITS)

The converted signal from Q2 and Q3 is applied to the bandpass filter where the unwanted LO signal emission is reduced. The converted signal is amplified at Q1, and is then applied to the PA UNIT via J11.

Incoming signals from the MAIN UNIT are amplified at the predrive amplifier (Q1), drive amplifier (Q2, Q3) and power amplifier (Q5, Q6) to obtain stable 100 W RF output power. The predrive amplifier is a class A amplifier with a Vcc of 13.8 V. The drive and power amplifiers are class AB push-pull amplifiers with a Vcc of 13.8 V. A stable bias voltage is applied to these amplifiers. D1 controls a bias voltage to the drive amplifier. Q4, D2 and D3 supply a bias voltage to the power amplifier.

A 0.012 Ω resistor (R26), inserted in the 13.8 V Vcc line, is provided for the Ic APC circuit. A voltage generated at both terminals of R26 is applied to the MAIN UNIT via the "ICH" and "ICL" signal line.

Thermal switch S1 and thermistor R32 detect the temperature of Q6 and Q5 respectively, and control the cooling fan speed.

TEMPERATURE °C (°F)		Below 50 (122)	50~90 (122~194)	Above 90 (194)
THERMAL SWITCH (S1)		OFF	OFF	ON
RESISTANCE OF R32		HIGH	LOW	LOW
COOLING RECEIVE		STOP	LOW	HIGH
FAN SPEED	TRANSMIT	L	ow	HIGH

COOLING FAN CONTROL CIRCUIT

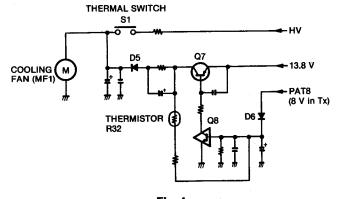


Fig. 4

4-2-5 RF FILTER CIRCUIT (PA UNIT)

The PA UNIT has 6 Chebyshev low-pass filters. The signal from the power amplifier (Q5, Q6), applied to one of the low-pass filters depending on the transmit frequency range, suppresses high harmonic components.

The filter switching voltage, obtained at the PLL UNIT, is applied to the PA UNIT via P7.

FREQUENCIES AND APPROPRIATE FILTERS

FILTER	FREQUENCY RANGE (MHz)
L1	Below 2
L2	2~4
L3	4~8
L4	8~15
L5	15~22
L6	22~30

The filtered signal passes through the SWR detector circuit (L51) and is then applied to the antenna connector. The forward signal from L51 is detected at D7 and applied to the MAIN UNIT as the "FOR" voltage. The reflection signal from L51 is detected at D8 and applied to the MAIN UNIT as the "REF" voltage.

4-2-6 ALC CIRCUIT (MAIN UNIT)

The ALC (Auto Level Control) circuit stably controls the RF output power using the [RF POWER] control.

The "FOR" voltage from the PA UNIT is applied to IC11 pin 2 and IC10 pin 3. The "POC" voltage controlled by the [RF PWR] control is also applied to IC11 pin 3 as the reference voltage.

When the "FOR" voltage exceeds the "POC" voltage, ALC bias voltage from IC11 pin 1 controls the IF amplifiers to reduce the output power until the "FOR" and "POC" voltages are equalized.

In AM mode, IC11 operates as an averaging ALC amplifier, because a capacitor on the optional AM · FM UNIT (C51) is connected to the cathode of D76. Q54 turns ON and the "POC" voltage is shifted for 40 W AM output power (maximum).

The ALC bias voltage from IC11 pin 1 is also applied to the inversion-amplifier (IC11 pin 6) to control an intensity of the [TX] indicator, showing the ALC level.

An external ALC input from the [ALC] jack is applied to the buffer amplifier (Q53). ALC operation is identical to that of the internal ALC.

4-2-7 APC CIRCUITS (MAIN UNIT)

The APC circuits protect the final transistors from high SWR and excessive current. The "REF" voltage from the PA UNIT is applied to Q56. When the "REF" voltage exceeds the reference voltage, determined by R203 and R204, Q56 turns ON and the "POC" voltage is shifted for 12 W output power.

The "ICH" and "ICL" voltages are applied to the Ic APC amplifier (IC10, pins 5 and 6) and then to the ALC bias voltage line to prevent excessive current flow.

4-2-8 CW KEYING CIRCUIT (MAIN UNIT)

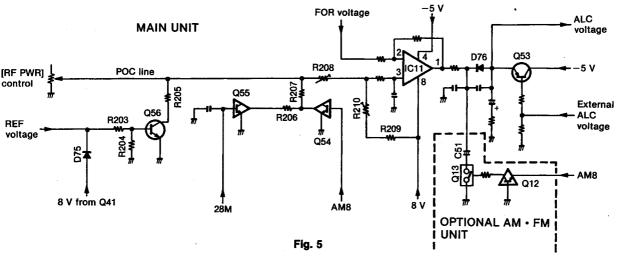
When the CW key is closed, the "KEY" signal line becomes "LOW." Q38 outputs 8 V to control break-in operation, sidetone signal and transmit signal.

When the [BK IN] switch is pushed IN, 8 V from Q38 charge C252 and Q26 is turned ON, turning ON Q52. Q52 grounds the SEND line for transmitting. The [DELAY] control (R244) adjusts the transmit release delay time.

The 8 V from Q38 charges C249 and D91 is turned OFF, disconnecting C249 from Q40. Q40 then oscillates a sidetone signal. R268 prevents sidetone click noise.

The 8 V from Q38 is applied to a time constant and then to the balanced modulator (IC6) to create a carrier signal. R241 in the time constant adjusts a transmit delay timing for 12 msec.

ALC CIRCUIT



While no CW transmit IF signal exists, Q39 and Q23 turn the switching diode (D35) OFF to ensure transmit isolation.

4-2-9 OUTPUT POWER METER CIRCUITS (MAIN UNIT)

The "FOR" voltage from the PA UNIT is applied to the Po meter amplifier (IC10 pin 3) and then to the meter. R189 and C261 are used for peak power measurement.

4-2-10 T/R SWITCHING CIRCUIT (MAIN UNIT)

When the PTT or [TRANSMIT] switch is set to transmit, IC13 pin 10 and IC13 pin 3 are "LOW." At this time, Q49 turns ON, and 0 V is present on the "R8" voltage line. Q50 turns OFF, and there is 8 V present on the "T8" voltage line.

When the PTT or [TRANSMIT] switch is set to receive, IC13 pin 10 and IC13 pin 3 are "HIGH." At this time, Q49 turns OFF, and 8 V is present on the "R8" voltage line. Q50 turns ON, and there_is 0 V present on the "T8" voltage line.

When PLL data or the operating mode is changed, the "DNB" signal line becomes "LOW," turning OFF the T8 — preventing unwanted transmission.

4-3 PLL CIRCUITS

4-3-1 GENERAL DESCRIPTION

The PLL UNIT generates a 1st LO signal (70.9515~100.4515 MHz variable) and 2nd LO signal (61.44 MHz fixed) used in the MAIN UNIT. The IC-725 uses a dual loop PLL system. A main loop PLL uses 4 VCO circuits for all HF band coverage within 512 kHz steps. A sub loop PLL uses a DDS (Direct Digital Synthesizer) system for 512 kHz coverage within 10 Hz steps. The DDS system provides a rapid lockup time and high quality frequency oscillation.

4-3-2 REFERENCE OSCILLATOR CIRCUIT (PLL UNIT)

A 30.72 MHz reference frequency is produced by the oscillator Q33 and X2. The reference frequency, buffer-amplified at Q34, is divided by 2 at IC15 and is then applied to the PLL circuit as the PLL reference frequency.

The signal oscillated at Q33 is multiplied by 2 at Q36. The resulting 61.44 MHz signal is filtered at the bandpass filter and is then applied to the MAIN UNIT via P4 as the 2nd LO signal.

4-3-3 MAIN LOOP (PLL UNIT)

The main loop uses a PLL IC (IC13) which contains a programmable divider, phase detector, data shift register and data latch circuits. The main loop generates 70.9515~100.4515 MHz signals in 512 kHz steps.

Because the sub loop produces 10 Hz steps, the PLL produces a 30 MHz frequency range in 10 Hz steps.

The oscillated signal at one of the 4 VCOs (Q15, Q17, Q19, Q21; see Section 4-3-4 for details) is amplified at Q23. The signal is mixed with the sub loop output (f_{LO} : 62.05 \sim 62.56199 MHz) at IC16. Q23 is an isolator which ensures that the mixer input does not affect the VCO output.

The mixed signal is amplified at Q27 and is then filtered at the low-pass filter (L23~L25, C92, C93, C99~C103). The filtered signal, amplified at Q26, is divided by 4 at IC14 and is then applied to the PLL IC (IC13).

The phase of the divided signal at IC14, detected at the PLL IC (IC13) using a reference frequency (f_{REF}) of 512 kHz, is then output from pin 17. The 512 kHz frequency is obtained from the reference oscillator (Q33). 30.72 MHz oscillated at Q33, is divided by 2 at IC15 and divided by 30 at the programmable divider section of IC13.

The phase detected signal is then converted to the lock voltage at the loop filter (Q12~Q14), and applied to the VCO. Thus, the VCO output (PLL output) is locked to produce stable oscillation.

The PLL oscillation frequency is obtained by the following calculation:

 $f_V = f_{LO} + N_T \times f_{REF}$

 f_V : Main loop output f_{LO} : Sub loop output

 N_T : Dividing ratio from the CPU f_{REF} : Reference frequency (512 kHz)

4-3-4 VCO CIRCUIT (PLL UNIT)

The transceiver's C/N ratio is determined by the VCO and the loop filter. 4 VCO circuits keep the low noise and reduce spurious emissions. Q16, Q18, Q20 and Q22 are VCO switches which select the operating VCO with "VCO1"~"VCO4" lines.

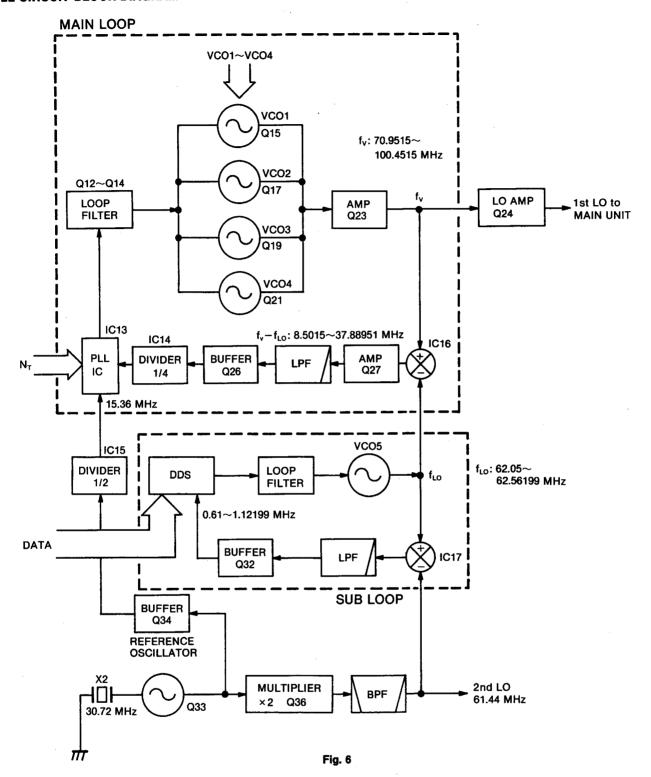
4-3-5 SUB LOOP (PLL UNIT)

The sub loop uses the DDS system that generates $62.05\sim62.56199$ MHz signals in 10 Hz steps.

The oscillated signal at the VCO (Q29) is buffer-amplified at Q30 and mixed with the 2nd LO signal (61.44 MHz) at IC17. The resulting signal passes through the low-pass filter, is amplified at Q32, and is then applied to the DDS UNIT.

The output pulse-type signal from the DDS UNIT passes through the loop filter (R133, R134, C114, C115, L42) where it is converted into a DC signal (lock voltage). The lock voltage is applied to the VCO to lock the oscillating frequency.

PLL CIRCUIT BLOCK DIAGRAM



4-4 LOGIC CIRCUITS

4-4-1 BAND SELECTION DATA (PLL UNIT)

To select the correct bandpass filter, the low-pass filter and VCOs on the MAIN and PLL UNITS, the CPU outputs the following data.

R29 \sim R40 and D29 \sim D35 convert the "B0" \sim "B7" signals into a band voltage (0 \sim 7.5 V) for external equipment.

FREQUENCY (MHz)	BPF	BAND VOLTAGE	LPF	vco
0.5~1.599	B0	B0 7.5 V		
1.6~1.999	B1	7.5 V	L1	VCO1
2.0~3.999	B2	5.9 V	L2	¥001
4.0~7.999	B3	5.0 V	L3	
8.0~10.999	B4	0.0 V	L4	VCO2
11.0~14.999	B 5	4.1 V	L4	VOOZ
15.0~21.999	B6	3.2 V	L5	VCO3
22.0~30.0	B7	2.2 V	L6	VCO4

4-4-2 CPU (PLL UNIT)

The CPU (IC8) contains an 8-bit CMOS CPU, 16k-byte ROM and 256-byte RAM. The CPU controls operating frequency, mode and the function display, etc. The memory contents are stored in the CPU using a lithium backup battery for more than 5 years.

The Icom CI-V network system allows that the IC-725 can be remotely controlled by a personal computer using an RS-232C signal line.

4-4-3 RIT CIRCUIT (PLL UNIT)

IC12 is an A/D converter which outputs 8-bit serial data regarding analog input voltage. A voltage, controlled by the [RIT] control, is applied to IC12 pin 4 and the resulting serial data is applied to the CPU matrix $Y4 \rightarrow DB4$.

4-4-4 KEY MATRIX

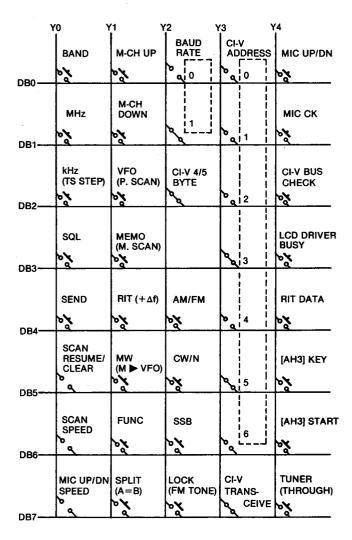


Fig. 7

4-4-5 PARALLEL/SERIAL CONVERTER (PLL UNIT)

IC11 is a parallel/serial converter IC. Parallel data from the CPU are converted into serial data to transfer the PLL N-data, DDS N-data, data for LCD driver, etc.

When the power is turned ON, the CPU also outputs programmable divider data and a control signal for universal ports to the PLL IC (IC13).

4-5 REGULATOR CIRCUITS

Either 8, 5 or -5 V DC are supplied from corresponding regulator circuits. 8, 5 and -5 V DC are regulated at the following circuits using 13.8 V DC.

(1) 5 V REGULATOR (PLL UNIT)

5 V DC are regulated by the three-terminal voltage regulator (IC10).

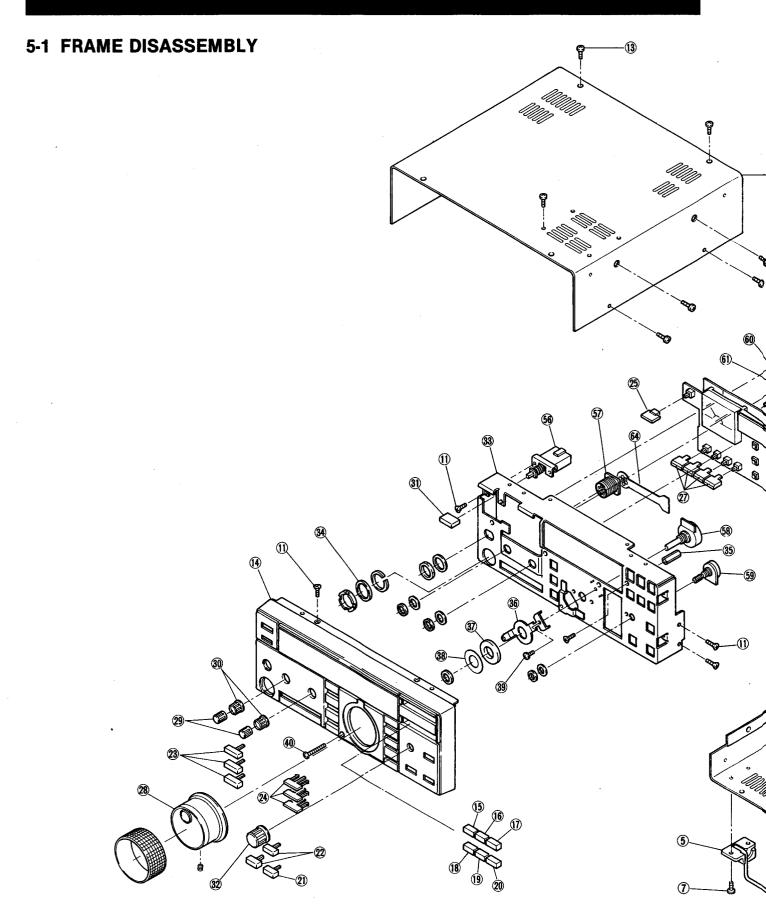
(2) 8 V REGULATOR (MAIN UNIT)

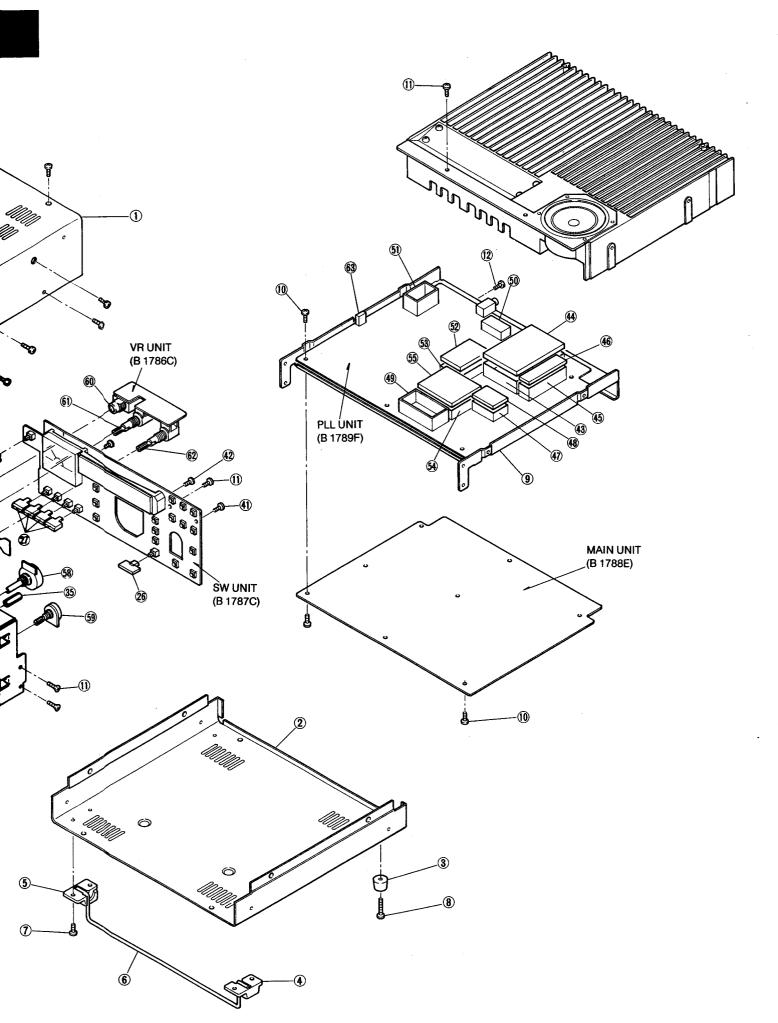
8 V DC are regulated by the three-terminal voltage regulator (IC14).

(3) -5 V REGULATOR (PLL UNIT)

IC6 generates a negative pulse-type voltage by converting the DC input to AC voltages (approx. 6.7 kHz) as a multivibrator. The voltage is rectified at D8 and D9, regulated by a Zener diode (D10) and C13, and is then applied to the MAIN UNIT.

SECTION 5 MECHANICAL PARTS AND DISASSEMBLY





• FRAME DISASSEMBLY

LABEL NUMBER	ORDER NO.	DESCRIPTION	QTY.	LABEL NUMBER	ORDER NO.	DESCRIPTION	QTY.
①	8110003270	Top cover	1	35)	8930000720	Thread spacer (V)	4
2	8110003280	Bottom cover	1	36	8930013990	610 Brake plate	1
3	8930002900	Rubber foot (A)	2	37)	8930014030	610 Brake pat	1
4	8930005790	Foot (A)	1	38	8930013940	610 Brake sheet	1
(5)	8930005800	Foot (B)	1	39	8810001110	PH B0 M3×6	1
6	8010001520	Stand (C)	1	40	8810005470	PH M2.6 × 14 ZK	1
7	8810005520	PH B1 M3×8 ZK	4	41)	8810001650	PH FT M3×6	9
8	8810005540	PH B1 M4×10	2	42	8810001320	PH B1 M2.6×6 Ni	4
9	8010007851	610 Chassis-1	1	43	8510001330	79 shield case	1
10	8810001350	PH B1 M3×6	16	44)	8510001340	79 shield case cover	1
11	8810002160	FH M3×5	16	45	8510001060	Shield case	1
(2)	8810003670	ICOM screw A 6	2	46	8510001740	Shield case cover	1
(13)	8810005510	FH M3×6 ZK BS	16	47)	8510000881	194 VCO case-1	1
14)	8210004670	610 Front panel (B)	1	48	8510003460	194 VCO case cover (A)	1
15	8610004640	Button K119 [VFO]	1	49	8510000230	220 shield case	1
16	8610004650	Button K119 (A) [SPLIT]	1	50	8510002200	VCO case	1
17	8610004660	Button K119 (B) [UP]	1	51)	8510000881	194 VCO case-1	1
(18)	8610004670	Button K119 (C) [MEMO]	1	52	8510002690	PA shield case (B)	1
19	8610004680	Button K119 (D) [MW]	1	53	8510004360	PA shield case (B) cover (A)	1
. 20	8610004690	Button K119 (E) [DOWN]	1	54	8510005310	DDS shield case	1
21)	8610004700	Button K119 (F) [FUNC]	1	55	8510005320	DDS shield case cover	1
22	8610004710	Button K119 (G) [RIT, TUNER]	2	56	2230000120	Switch [POWER] SDDSA3159A	1
23	8610004720	Button K120 [SSB, CW/N, AM/FM]	3	57)	6510000190	Connector [MIC] FM214-8SS (P)	1
24)	8610004730	Button K121 [kHz, MHz, BAND]	3	58	7600000100	Rotary encoder EC24B50B0013A	1
25	8610003850	Button K98 [TRANSMIT]	1	59	7210000570	Variable resistor [RIT]	1
26	8610004741	Button K122-1 [LOCK]	1	60	6450000910	Connector [PHONES]	
27)	8610004751	Button K123-1 [NB, ATT, PRE, AGC]	4	(60)	6450000810	HLJ4306-01-3070	1
28	8610004760	Dial N104 (A) (incl. rubber ring and screw)	1	61)	7210001320	Variable resistor [AF/SQL] RK124221002DA	1
29	8610004770	Knob N45C [AF, MIC]	2	60	7210001550	Variable resistor [MIC/RF PWR]	
30	8610000500	Knob N69 [SQL, RF PWR]	2	62	1210001330	RK1242210032A	1
31)	8610001560	Button K42 [POWER]	1	6	7210001530	Variable resistor [RIT]	
32	8610004780	Knob N87 (B) [RIT]	1	63	1210001330	RK09K1110AEGA	1
33	8010007860	610 Sub chassis	1	64)	0910006330	Flexible cable P.C. Board B 792	1
34)	8930003200	Spacer (P)	1				

Screw abbreviations

BS: Brass

PH: Pan head FH: Flat head B0, B1, FT: Self-tapping screw ZK: Black

Ni: Nickel

5-2 PA UNIT AND ACCESSORIES 1 FILTER UNIT (B 1791C) PA UNIT (B 1790D) £ 69 00

• PA UNIT

LABEL NUMBER	ORDER NO.	DESCRIPTION	QTY.
①	8410000781	401 Heatsink-1	1
2	8510005462	PA cover-2	1
3	8810001910	PH M3×6 Ni BS	2
4	8850000420	Spring washer M3 Ni	2
(5)	8810001350	PH B1 M3×6	24
6	8810003170	Set screw A M3×8	7
1	6910000310	Bushing B312D	1
8	8810003670	ICOM screw A6	2
9	8810003210	Set screw A M3×15	1
10	8810000220	PH M3×5	4
10	8810001980	PH M5×16 Ni BS	1
(2)	8850000590	Star washer M5	1
(3)	8850000440	Spring washer M5 Ni	1
14)	8830000210	Nut M5 Ni BS	1
15	8850000150	Flat washer M5 Ni BS	2
16	8830000360	Wing nut M5 Ni	1
10	6510004880	ANT connector MR-DS-E 01	1
18	2510000040	Speaker C065K12I0810	1
19	6510003780	DC power socket LLR-6	1

Screw abbreviations

PH: Pan head B1: Self-tapping screw

Ni: Nickel

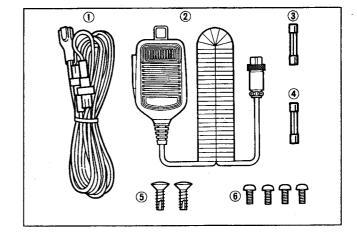
BS: Brass

• ACCESSORIES

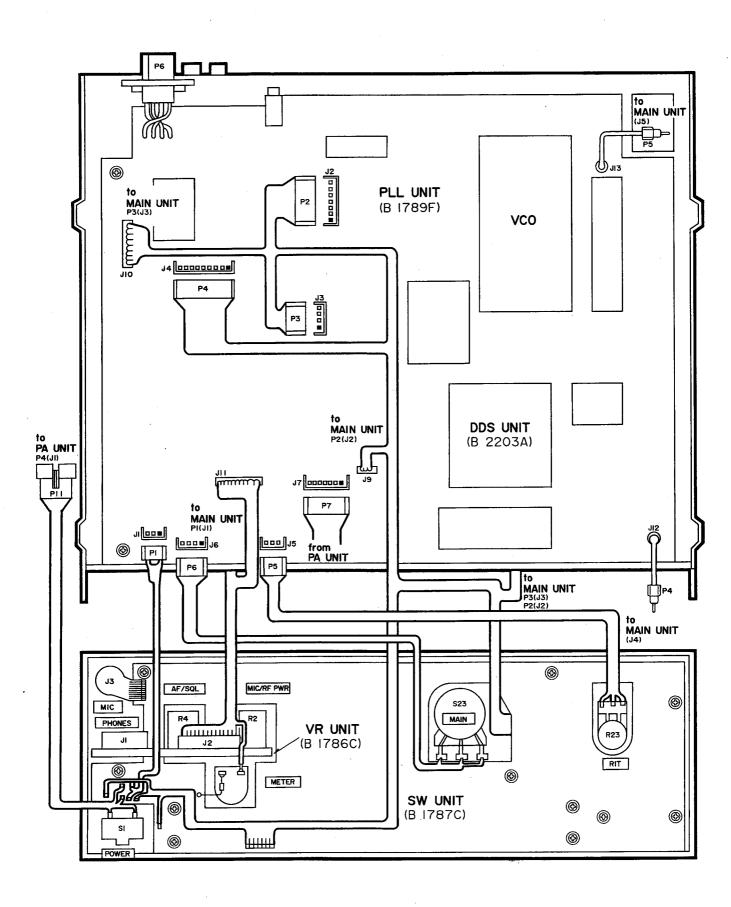
LABEL NUMBER	- DESCRIPTION		QTY.
1	Optional product	DC power cable OPC-025 A	1
2	Optional product	Hand microphone HM-12	1
3	5210000080	Spare fuse FGB 20A	1
4	5210000130	Spare fuse FGB 4A	1
⑤	8810005500	FH B1 M4×12 CR	2
6	8810001600	PH ST M3×6	4

Screw abbreviations

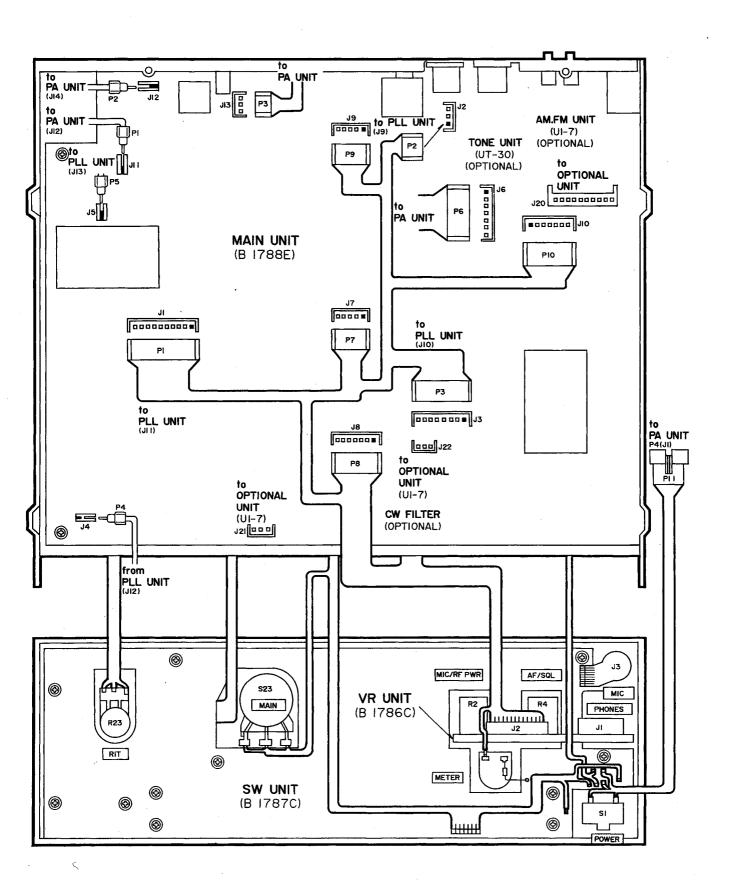
FH: Flat head PH: Pan head B1, ST: Self-tapping screw



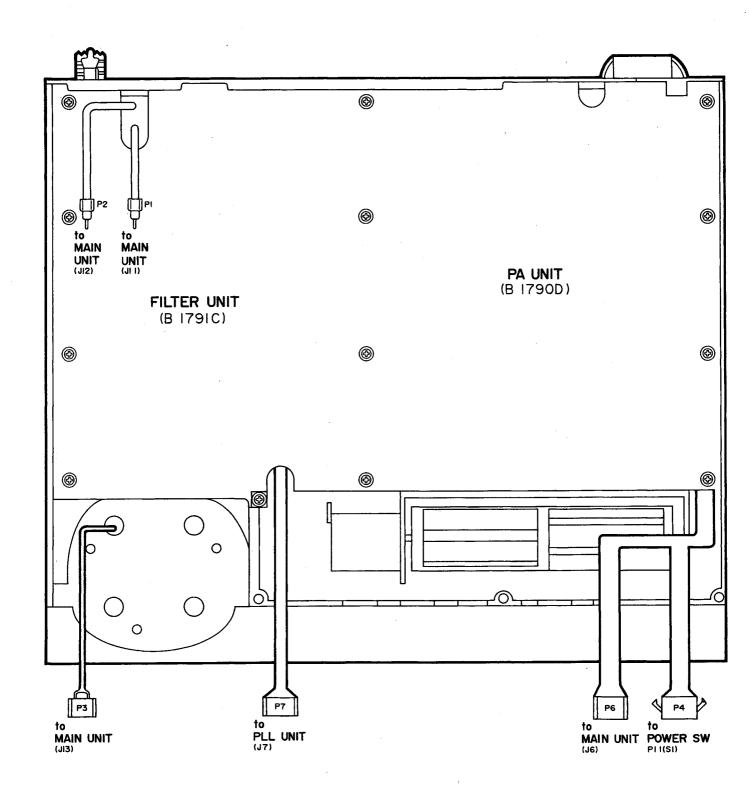
5-3 FRONT AND PLL UNITS CONNECTOR ASSEMBLY



5-4 FRONT AND MAIN UNITS CONNECTOR ASSEMBLY



5-5 PA AND FILTER UNITS CONNECTOR ASSEMBLY



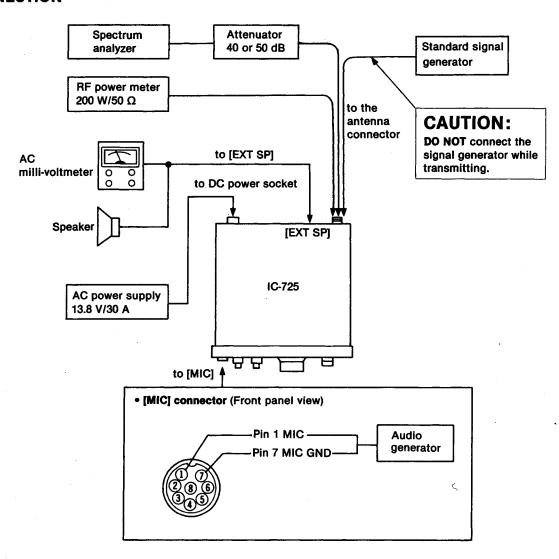
SECTION 6 ADJUSTMENT PROCEDURES

6-1 PREPARATION BEFORE SERVICING

REQUIRED TEST EQUIPMENT

EQUIPMENT	GRADE AND RANGE	EQUIPMENT	GRADE AND RANGE			
AC power supply	Output voltage : 13.8 V DC Current capacity : 30 A or more	DC voltmeter	Input impedance : 50 kΩ/DC or better			
		AC milli-voltmeter	Measuring range : 10 mV~10 V			
RF power meter	Measuring range : 10~200 W Frequency range : 1.8~30 MHz	External speaker	Impedance : 8 Ω			
(terminated type)	Frequency range : 1.8~30 MHz Impedance : 50 Ω	Ammeter	Measurement capability: 1 A and 30 A			
	SWR : Less than 1.2:1	Audio generator	Frequency range : 300~3000 Hz			
Frequency counter	Frequency range : 0.1~100 MHz Frequency accuracy: ±1 ppm or better Sensitivity : 100 mV or better		Output level : 1~500 mV			
		Attenuator	Power attenuation : 40 or 50 dB Capacity : 150 W or more			
RF voltmeter	Frequency range : 0.1~100 MHz Measuring range : 0.01~10 V	Spectrum analyzer	Frequency minimum: At least 90 MHz Spectrum bandwidth: ±100 kHz or more			
Oscilloscope	Frequency range : DC~20 MHz Measuring range : 0.01~10 V					
Standard signal generator (SSG)	Frequency range : 0.1~30 MHz Output level : -127~-17 dBm (0.1 µV~32 mV)					

CONNECTION

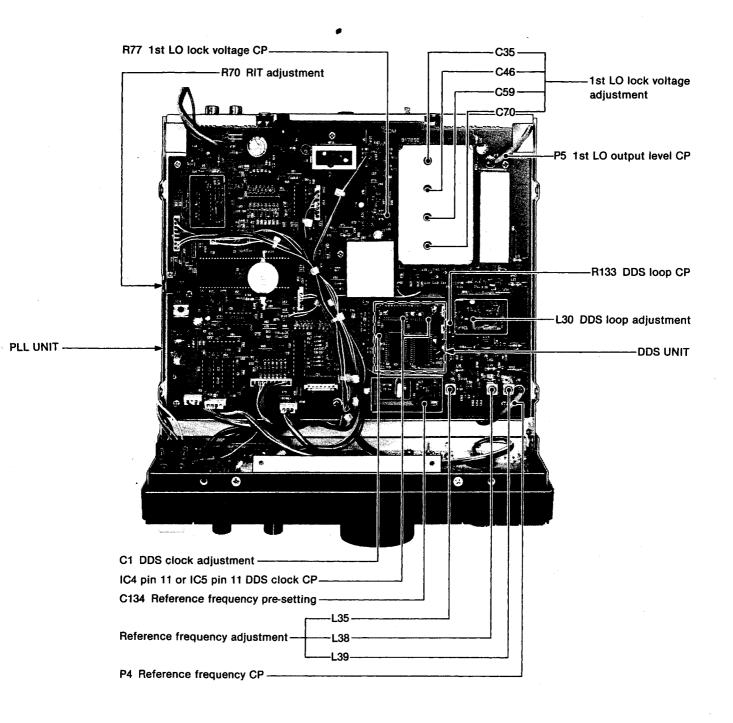


6-2 PLL ADJUSTMENT

ADJUSTMENT		ADJUSTMENT CONDITIONS	N	IEASUREMENT	VALUE	ADJUSTMENT POINT	
ADJUSTME	NI	ADJUGITMENT CONDITIONS	UNIT	LOCATION	VALUE	UNIT	ADJUST
REFERENCE FREQUENCY	1	Displayed frequency: 14.10000 MHz Mode : USB Receiving	PLL	Terminate P4 to ground with a 50 Ω resistor.	Pre-set to center.	PLL	C134
	2	•		Connect the RF voltmeter to P4.	Maximum level (More than +3 dBm)	1.	L38, L39
i	3		·	Connect the frequency counter to P4.	61.4400 MHz		L35
	4	After adjustment, remove the resistor f	irom P4 a	nd re-plug P4.		- 	
DDS CLOCK	1	Displayed frequency: 14.10000 MHz Mode : USB Receiving	DDS	Connect the frequency counter to IC4 pin 11 or IC5 pin 11.	5.24288 MHz	DDS	C1
DDS LOOP	1	Displayed frequency: 14.12650 MHz Mode : AM Receiving		PLL	L30		
	2	Displayed frequency: 14.12649 MHz			Approx. 2.0 V DC		Verify
1ST LO LOCK VOLTAGE	1	Displayed frequency: 7.99999 MHz Mode : USB Receiving	PLL	Connect the oscilloscope to R77. (shielding case side)	6.5 V DC	PLL	C35
	2	Displayed frequency: 14.99999 MHz			6.5 V DC		C46
	3	Displayed frequency: 21.99999 MHz			6.5 V DC		C59
,	4	Displayed frequency: 33.00000 MHz			7.5 V DC		C70
	5	Displayed frequencies: 0.50000 MHz, 8.00000 MHz, 15.00000 MHz and 22.00000 MHz			More than 2.0 V DC		Verify
1ST LO OUTPUT LEVEL	1	Displayed frequency: 14.10000 MHz Mode : USB Receiving	PLL	Terminate P5 to ground with a 50 Ω resistor. Connect the RF voltmeter to P5.	More than 0 dBm		Verify
	2	After adjustment, remove the resistor f	rom P5 a	nd re-plug P5.	1		
RIT	1	Displayed frequency: 14.10000 MHz Mode : USB Set the signal generator;	Top cover	Speaker	Pre-set to center.	Front panel	[RIT] control
	2	Level : 50 μV (−73 dBm) Modulation: OFF • [RIT] switch : ON and OFF • Receiving			Same tone pitch on both conditions.	PLL	R70







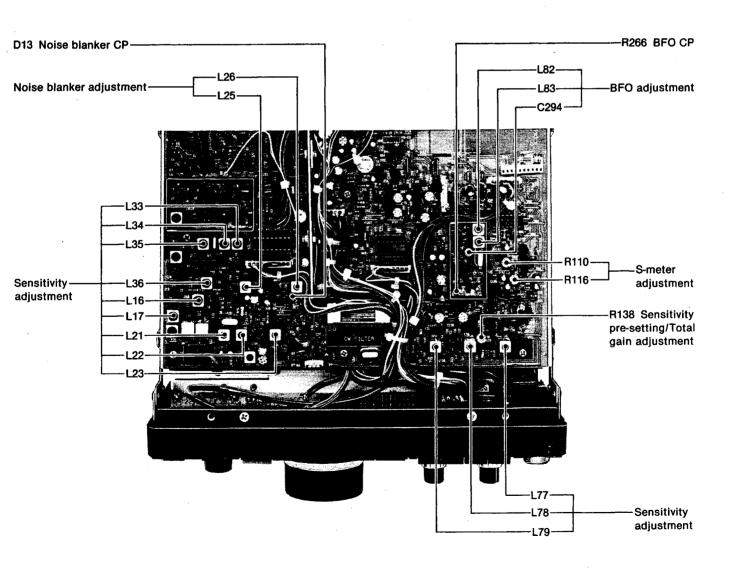
6-3 RECEIVER ADJUSTMENT

4.0.1107145		AD WATER CONDITIONS	N	IEASUREMENT	WALLE	ADJUSTMENT POINT	
ADJUSTME	NT	ADJUSTMENT CONDITIONS	UNIT LOCATION		VALUE	UNIT	ADJUST
BFO FREQUENCY	1	Displayed frequency: 14.10000 MHz Mode : USB Receiving	MAIN	Connect the frequency counter to R266.	9.01300 MHz	MAIN	C294
	2	Mode : CW Transmitting			9.01060 MHz		L83
	3	Mode : LSB Receiving			9.01000 MHz		L82
	4	• Mode : CW			9.00980 MHz (±150 Hz)		Verify
	5	• Mode : AM	,		No output		
SENSITIVITY	1	Displayed frequency: 14.10000 MHz Mode : USB [RIT] switch : OFF	Rear panel	Connect the AC milli- voltmeter to the [EXT SP] jack with	Pre-set to max. CW.	MAIN	R138
	AND AND THE PROPERTY OF THE PR	• [AGC] switch : IN (Fast) • [ATT] switch : OFF • [NB] switch : OFF • [PRE] switch : ON • [SQL] control : Max. CCW • Set the signal generator; Level : 0.16 µV (-123 dBm) Modulation: OFF • Receiving		an 8 Ω load.	Maximum audio output level		L33, L34, L35, L36, L16, L17, L21, L22, L23, L79, L78, L77
TOTAL GAIN	1	Displayed frequency: 14.10000 MHz Mode: USB [PRE] switch: OFF Set the signal generator; Level: 1.0 mV (-47 dBm) Modulation: OFF Receiving	Rear panel	Connect the AC millivoltmeter to the [EXT SP] jack with an 8 Ω load.	1.0 V (0 dB)	Front panel	[AF] control
	2	Set the signal generator; Level : OFF			30 mV (-30 dB)	MAIN	R138
S-METER	1	Displayed frequency: 14.10000 MHz Mode: USB [PRE] switch: OFF Set the signal generator; Level: 50 µV (-73 dBm) Modulation: OFF Receiving	Front panel	Meter	S9	MAIN	R116
	2	Set the signal generator; Level : 50 mV (-13 dBm)			S9+60 dB		R110
	3	Repeat above adjustments 1 and 2 a c	ouple of	times.			

RECEIVER ADJUSTMENT (CONTINUED)

ADJUSTMENT		ADJUSTMENT CONDITIONS	MEASUREMENT		VALUE	ADJUSTMENT POINT	
ADJUSTME	.14 1	ADJUSTMENT CONDITIONS	UNIT	LOCATION	VALUE	UNIT	ADJUST
NOISE BLANKER	1	Displayed frequency: 14.10000 MHz Mode: USB [NB] switch: ON Apply an RF signal including the following pulse noise to the antennal connector. RF signal level: 3.2 μV (-97 dBm) Receiving	MAIN	Connect the oscilloscope to the cathode of D13.	Adjust for maximum waveform on the oscilloscope.	MAIN	L25, L26

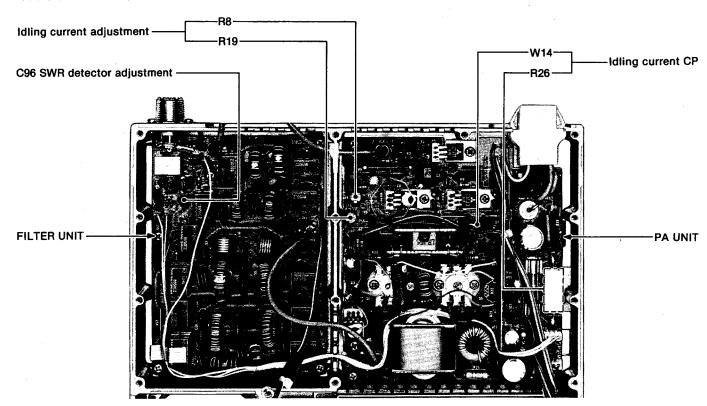
MAIN UNIT



6-4 TRANSMITTER ADJUSTMENT

AD WICTME	\.T	AD HISTMENT CONDITIONS	MEASUREMENT		VALUE	ADJUSTMENT POINT	
ADJUSTMENT		ADJUSTMENT CONDITIONS	UNIT	LOCATION	VALUE	UNIT	ADJUST
IDLING CURRENT (A) For drive transistors	1	Displayed frequency: 14.10000 MHz Mode : CW TRANSMIT] switch: IN [KEY] jack : No connection	PA	Unsolder W14 and connect the ammeter to the unsoldering points.	50 mA	PA	R8
				w14 C11 side			
For final transistors	2		PA	Unsolder R26 and connect the ammeter to the unsoldering points. ammeter O O O O O O O O O O O O O O O O O O O	300 mA	PA	R19
		After adjustment, re-solder W14 and R	26.				

PA AND FILTER UNITS



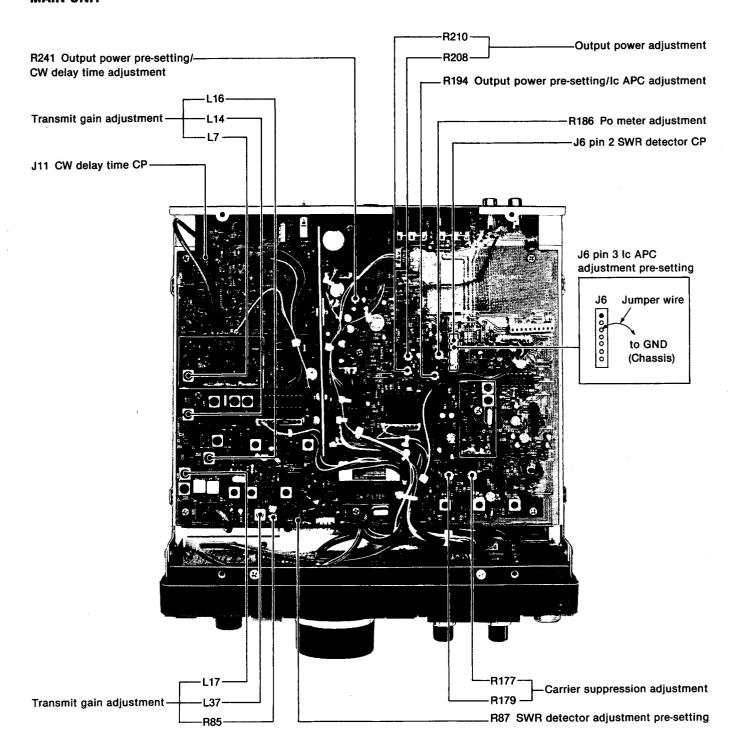
TRANSMITTER ADJUSTMENT (CONTINUED)

ADJUSTMENT		ADJUSTMENT CONDITIONS	MEASUREMENT		VALUE	ADJUSTMENT POINT	
ADJUSIME	IN I	ADJUSTMENT CONDITIONS	UNIT LOCATION		VALUE	UNIT	ADJUST
SWR DETECTOR	1	Displayed frequency: 14.10000 MHz Mode : USB [RF PWR] control : Max. CW	Rear panel	Connect the RF power meter to the antenna connector.	100 W	Front panel	[MIC] control
	2	Connect a jumper wire between R87 front side and ground. Apply an RF signal to the [MIC] connector. Level : 10 mV/1.5 kHz Transmitting	MAIN	Connect the DC voltmeter to J6 pin 2.	Minimum	FILTER	C96 (See p. 6-6)
	3	After adjustment, remove the jumper w	vire from	R87.			
TRANSMIT GAIN	1	Displayed frequency: 14.10000 MHz Mode : USB	Rear panel	Connect the RF power meter to the	Pre-set to max. CCW.	MAIN	R85
		[RF PWR] control : Max. CW Apply an AF signal to the [MIC] connector.		antenna connector.	50 W	Front panel	[MIC] control
	:	Level : 1 mV/1.5 kHz • Transmitting			Maximum level	MAIN	L37, L17, L16, L14, L7
	2	•[MIC] control : Max. CW			50 W		R85
		NOTE: Adjust the [MIC] control to keep	the outp	out power at 50 W for ea	ach adjustment.		
OUTPUT POWER	1	Displayed frequency: 1.91000 MHz Mode : CW	Rear panel	Connect the RF power meter to the	Pre-set to max. CCW.	MAIN	R194, R241
	2	[RF PWR] control : Max. CW Connect a key to the [KEY] jack and keep the key down.		antenna connector.	100 W		R210
	3	• [RF PWR] control : Max. CCW			10 W		R208
	4	Repeat steps 2 and 3 a couple of times	s.	1			
Ic APC	-1	Displayed frequency: 14.10000 MHz Mode: CW [RF PWR] control: Max. CW Connect a jumper wire between J6 pin 3 and ground. Connect a key to the [KEY] jack and keep the key down.	Rear panel	Connect the ammeter between the AC power supply and IC-725.	22 A	MAIN	R194
	2	After adjustment, remove the jumper w	vire from	J6 pin 3.	<u> </u>		
Po METER	1	Displayed frequency: 14.10000 MHz Mode: CW IRF PWR] control: Max. CW Connect a key to the [KEY] jack and keep the key down.	Front panel	Meter	100 % (full scale)	MAIN	R186
CW DELAY TIME	1	Displayed frequency: 14.10000 MHz Mode: CW BK IN] switch: ON DELAY control: Max. CCW Connect an external electronic keyer to the [KEY] jack and close the key.	MAIN	Connect the oscilloscope to J11 and the electronic keyer.	Adjust as follows: Keying J11 12 msec.	MAIN	R241

TRANSMITTER ADJUSTMENT (CONTINUED)

ADJUSTMENT	AD IJICTMENT CONDITIONS	MEASUREMENT		VALUE	ADJUSTMENT POINT		
	:N• i	ADJUSTMENT CONDITIONS	UNIT	LOCATION	VALUE	UNIT	ADJUST
CARRIER SUPPRESSION	1	Displayed frequency: 1.91000 MHz Mode: USB and LSB [MIC] control: Max. CCW Apply no signal to tage [MIC] connector. Transmitting	Rear panel	Connect the spectrum analyzer to the antenna connector via the attenuator.	Minimum carrier level (Less than -50 dB)	MAIN	R177, R179 (Altemately adjust)

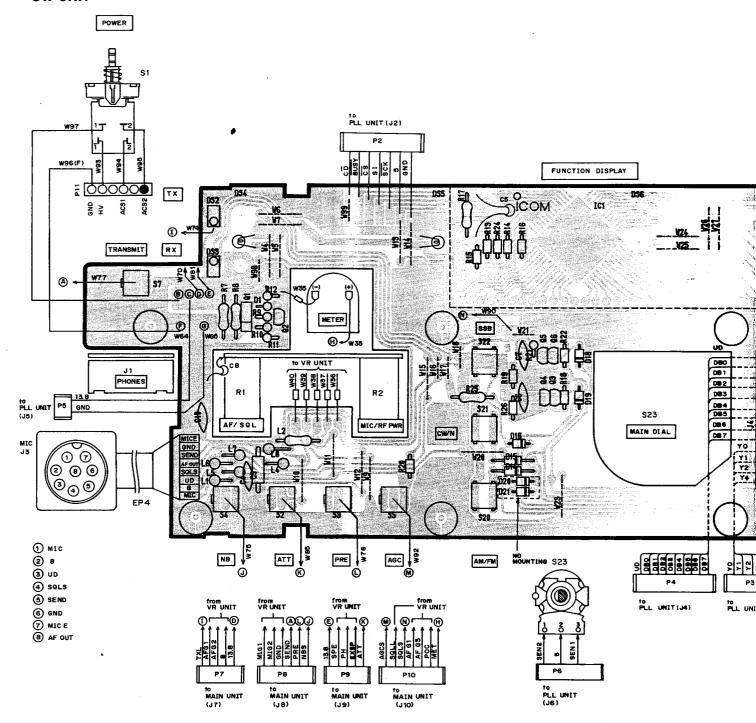
MAIN UNIT



SECTION 7 BOARD LAYOUTS

7-1 FRONT UNIT

• SW UNIT





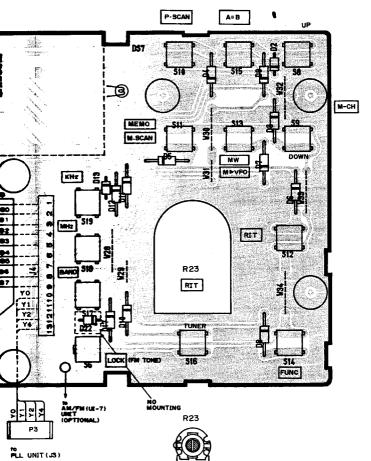






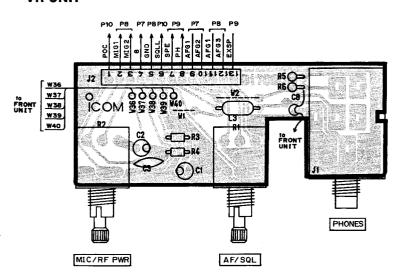
RN1204 Q5





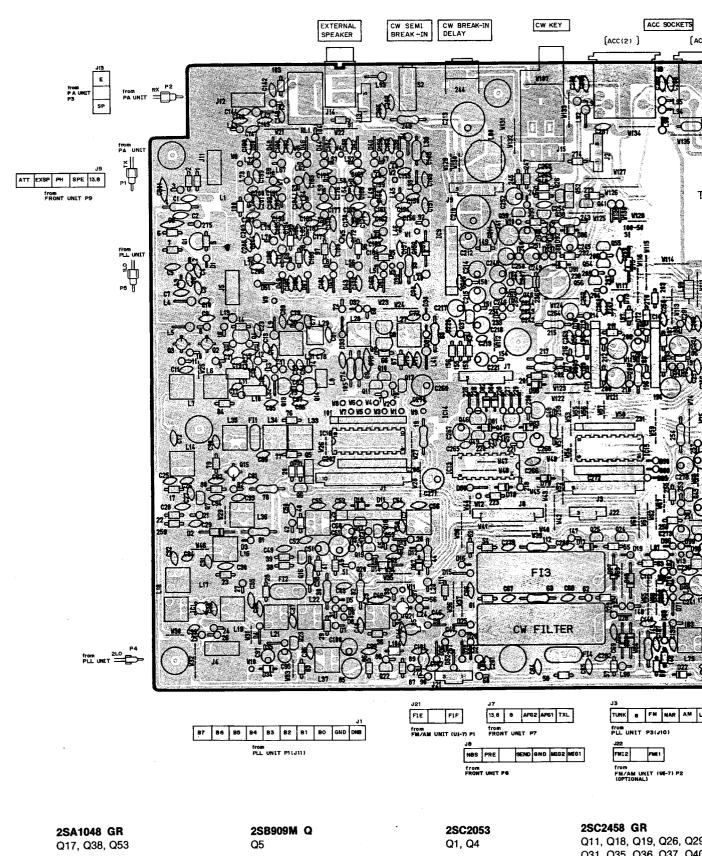
to PLL UNIT (J1)

• VR UNIT

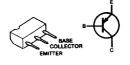


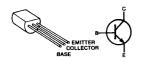
7 **—** 1

7-2 MAIN UNIT



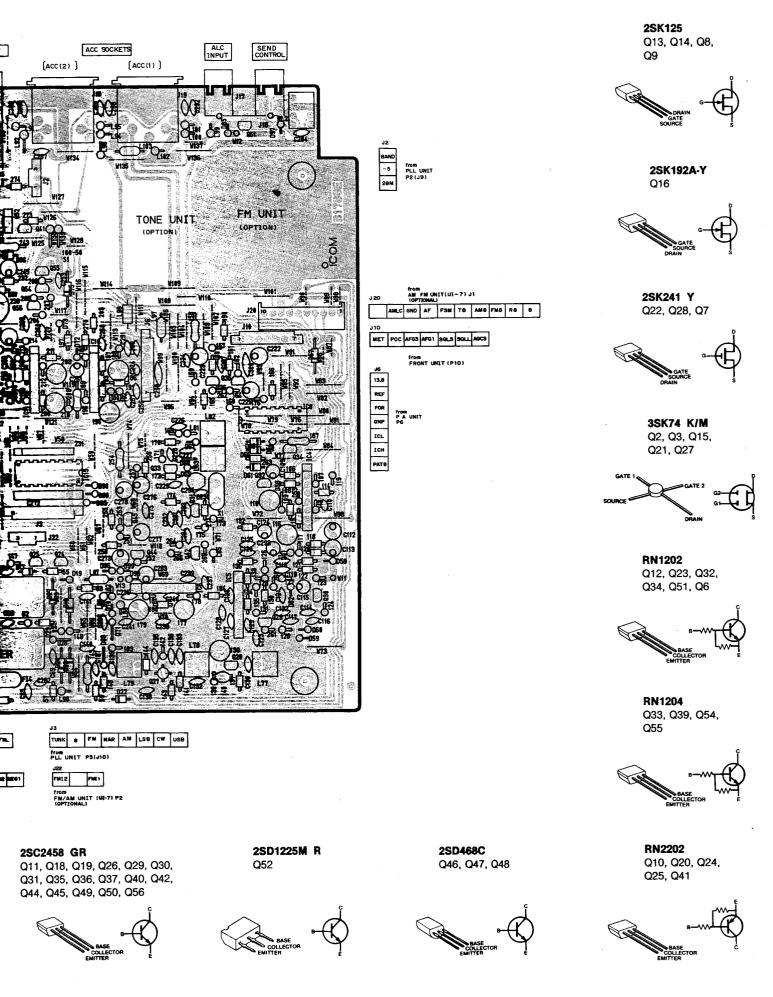




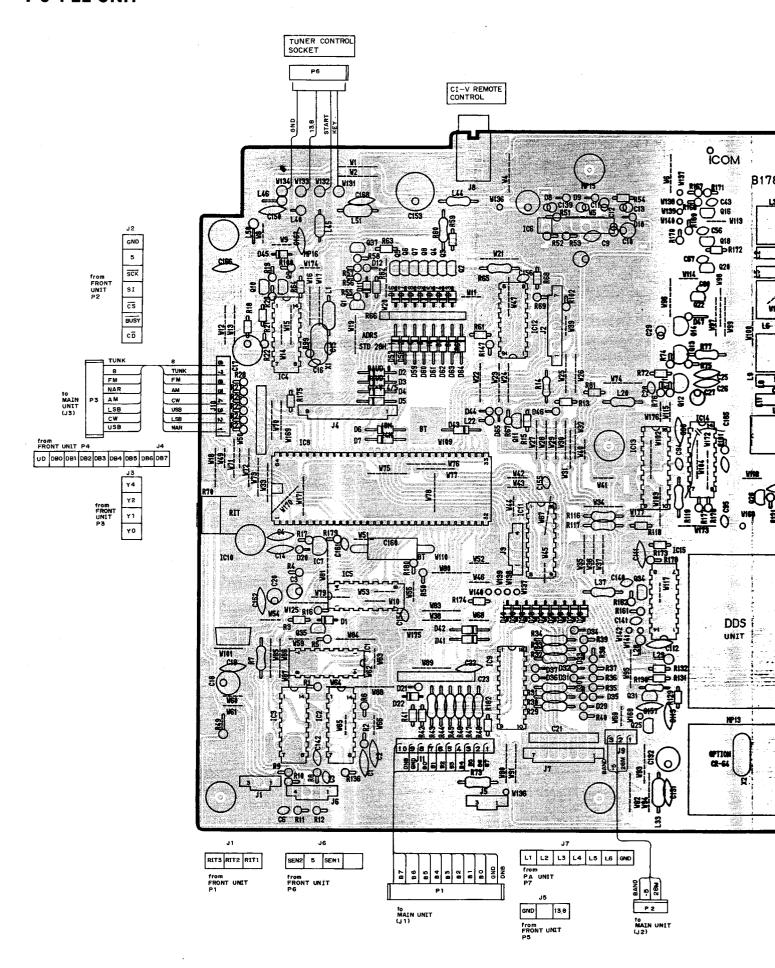


Q11, Q18, Q19, Q26, Q29 Q31, Q35, Q36, Q37, Q40 Q44, Q45, Q49, Q50, Q56





7-3 PLL UNIT



СОМ B1789F MAIN UNIT V120 LG. **DDS** UNIT HP13 2LO P4 10 MAIN UNIT

2SA1048 GR

Q37



2SC1571G Q12



2SC2458 GR/Y

Q1, Q10, Q11, Q13, Q14, Q16, Q18, Q2, Q20, Q22, Q3, Q33, Q4, Q5, Q6, Q7, Q8, Q9, Q32

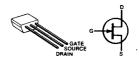


2SC2668 O

Q23, Q24, Q26, Q27, Q30, Q34, Q36



2SK192A GR Q15, Q17, Q19, Q21, Q29



RN1202 Q25, Q35

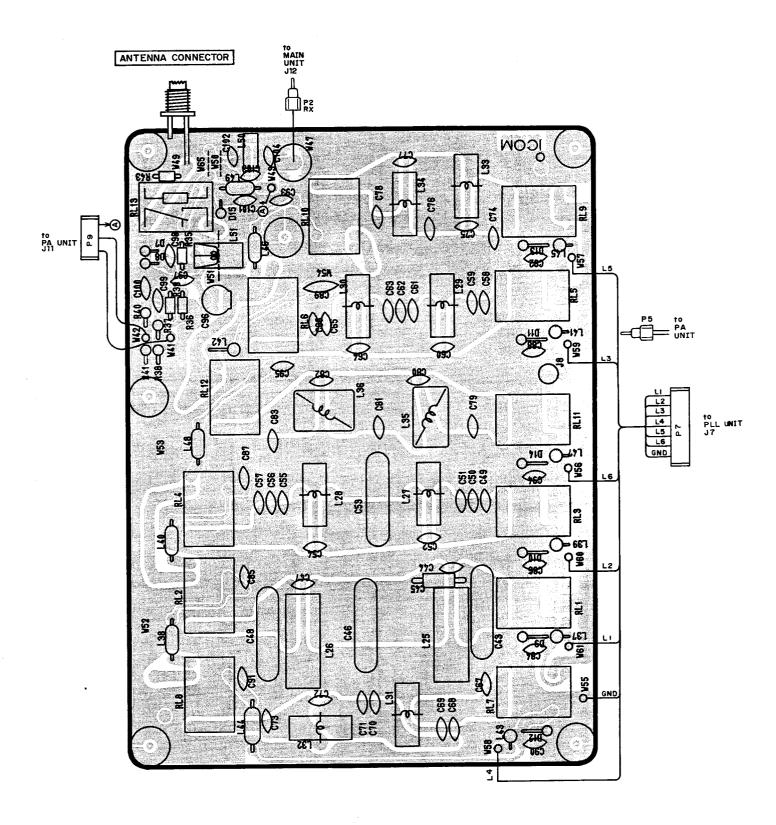


RN2202 Q31

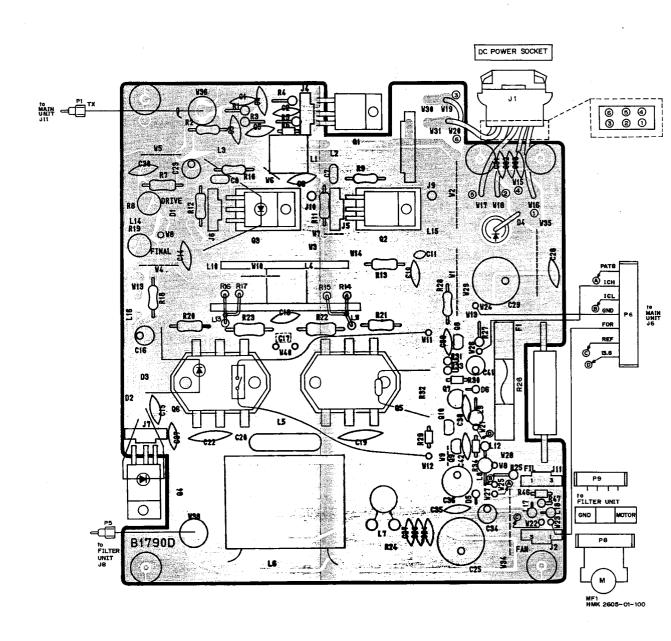


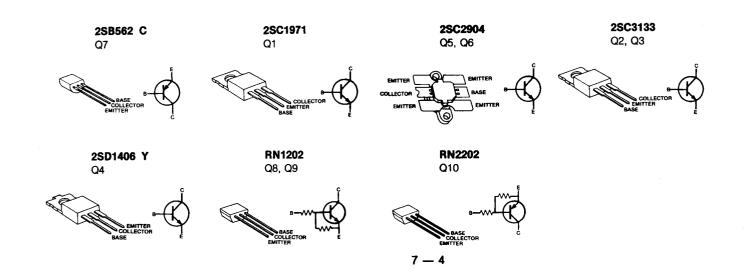
7-4 PA UNIT

• FILTER UNIT



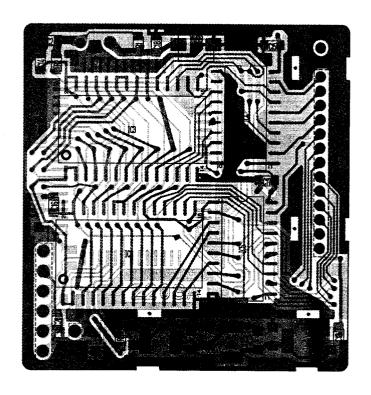
to PLL UNIT J7





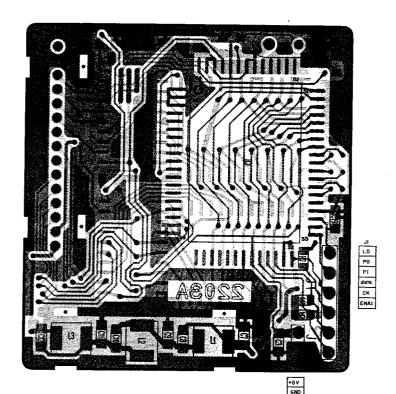
7-5 DDS UNIT

COMPONENT SIDE



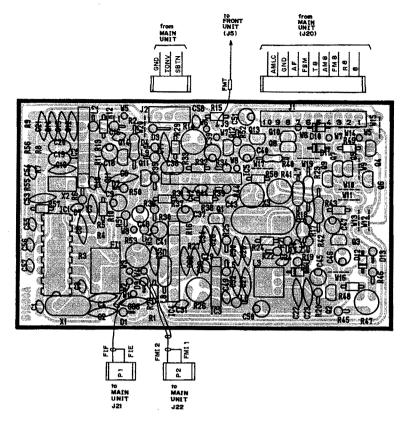


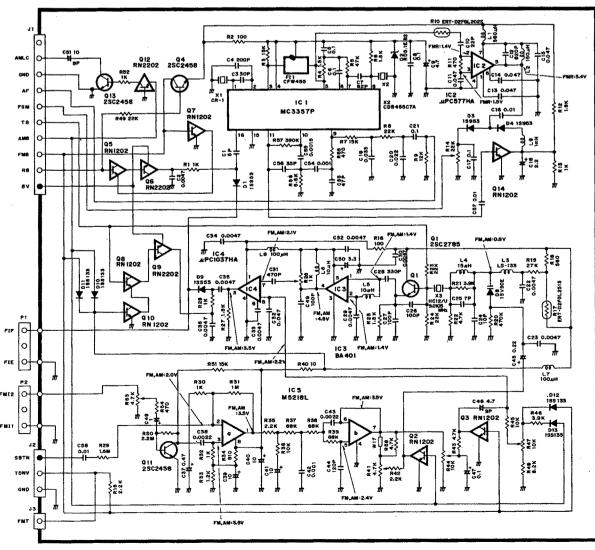
FOIL SIDE





7-6 AM • FM UNIT (OPTIONAL)





SECTION 8 PARTS LIST

[FRONT UNIT]

[1 11011			
REF. NO.	ORDER NO.	. 0	ESCRIPTION
IC1	1130000790	IC ·	μPD7225G
Q1	1520000230	Transistor	2SB909M Q
Q2	1530000110	Transistor	2SC2458-GR
Q3	1530000110	Transistor	2SC2458-GR
Q4	1530000110	Transistor	2SC2458-GR
Q5	1590000350	Transistor	RN1204
Q6	1530000110	Transistor	2SC2458-GR
	•		
D1	1730000180	Zener	RD8.2E B2
D2	1710000160	Diode	1SS133
D3	1710000160	Diode	1SS133
D4	1710000160	Diode	188133
D5	1710000160	Diode	188133
D6	1710000160	Diode	188133
D7	1710000160	Diode	188133
D8	1710000160	Diode	1SS133
D9	1710000160	Diode	1SS133
D10	1710000160 1710000160	Diode Diode	1SS133 1SS133
D11 D12	1710000160	Diode	1SS133
D12	1710000160	Diode	1SS133
D14	1710000160	Diode	1SS133
D15	1710000160	Diode	1SS133
D16	1710000160	Diode	1SS133
D17	1710000160	Diode	1SS133
D18	1710000160	Diode	1SS133
D19	1710000160	Diode	1SS133
L1	6180000900	Coil	LAL 03NA 101K
12	6180000900	Coil	LAL 03NA 101K
L3	6180000900	Coil	LAL 03NA 101K
L4	6180000900	Coil	LAL 03NA 101K
L5	6180000900	Coil	LAL 03NA 101K
L6 L7	6180000900 6180000900	Coil Coil	LAL 03NA 101K LAL 03NA 101K
L8	6180000900	Coil	LAL 03NA 101K
R ₁	7210001320	Variable Resistor	RK124221002DA (AF/SQL)
R2	7210001550	Variable Resistor	
			10KB-10KB (MIC/RF PWR)
R3	7010004030	Resistor	R20J 47 Ω
R4	7010004190	Resistor	R20J 1 kΩ
R5	7010003280	Resistor	ELR20J 100 Ω
R6	7010003280 7010004720	Resistor Resistor	ELR20J 100 Ω R50XJ 100 Ω
R7 R8	7010004720	Resistor	R50XJ 100 Ω
R9	7010003400	Resistor	ELR20J 1 kΩ
R10	7010003520	Resistor	ELR20J 8.2 kΩ
R11	7010003480	Resistor	ELR20J 4.7 kΩ
R12	7010003400	Resistor	ELR20J 1 kΩ
R13	7010004250	Resistor	R20J 3.3 kΩ
R14	7010004320 7010004320	Resistor Resistor	R20J 10 kΩ R20J 10 kΩ
R15 R16	7010004320	Resistor	R20J 180 kΩ
R17	7010004480	Resistor	R20J 47 kΩ
R18	7010004320	Resistor	R20J 10 kΩ
R19	7010004320	Resistor	R20J 10 kΩ
R20	7010004170	Resistor	R20J 680 Ω
R21	7010004320	Resistor	R20J 10 kΩ
R22	7010004320	Resistor	R20J 10 kΩ
R23 R24	7210000570 7010004320	Variable Resistor Resistor	RK1631110D5FA (RIT) R20J 10 kΩ
R25	7010004320	Resistor	R25J 100 kΩ
R26	7010004450	Resistor	R20J 100 kΩ
			•

[FRONT UNIT]

REF.	ORDER	<u> </u>	
NO.	NO.		DESCRIPTION
C1	4510000970	Electrolytic	10 MS9 100 μF
C2	4510001150	Electrolytic	50 MS7 R47 μF
C3	4010000520	Ceramic	DD108 B 472K 50V
C4	4010000520	Ceramic	DD108 B 472K 50V
C5	4040000260	Barrier Layer	UZE 08X 104M
C6	4010000520	Ceramic	DD108 B 472K 50V
C7	4010000520	Ceramic	DD108 B 472K 50V
C8	4020000250	Cylinder	UP125 X 472M
C10	4020000250 4010000520	Cylinder Ceramic	UP125 X 472M DD108 B 472K 50V
1000	4010000520	Ceramic	DD 100 B 472K 304
DS1	5030000380	LCD	HLC9599-01-3210
DS2	5040001290	LED	SLP153B
DS3	5040001300	LED	SLP253B
DS4	5080000170	LED	HRS7219A-Y2-30
DS5	5080000170	LED	HRS7219A-Y2-30
DS7	5080000170	LED	HRS7219A-Y2-30
Ì			
ME1	5510000300	Meter	KL-218U-43 (M610)
S1	2230000120	Switch	SDDSA3159A [POWER]
S2	2230000550	Switch	SPPH23079A [ATT]
S3	2230000550	Switch	SPPH23079A [PRE]
84	2230000550	Switch	SPPH23079A [NB]
S5	2230000550	Switch	SPPH23079A [AGC]
S6	2230000550	Switch	SPPH23079A [LOCK]
S7	2230000550	Switch	SPPH23079A [TRANSMIT]
S8	2260000070	Switch	SKHHAK013A [M-CH UP]
S9	2260000070	Switch .	SKHHAK013A
040		0	[M-CH DOWN]
S10	2260000070	Switch	SKHHAK013A [VFO]
S11	2260000070	Switch	SKHHAK013A [MEMO] SKHHAK013A [RIT]
S12 S13	2260000070 2260000070	Switch Switch	SKHHAK013A [MW]
S14	2260000070	Switch	SKHHAK013A [FUNC]
S15	2260000070	Switch	SKHHAK013A [SPLIT]
S16	2260000070	Switch	SKHHAK013A [TUNER]
S17	2260000060	Switch	SKHHAJ025A [BAND]
S18	2260000060	Switch	SKHHAJ025A [MHz]
S19	2260000060	Switch	SKHHAJ025A [kHz]
S20	2260000070	Switch	SKHHAK013A [AM/FM]
S21	2260000070	Switch	SKHHAK013A [CW/N]
S22	2260000070	Switch	SKHHAK013A [SSB]
S23	7600000100	Switch	EC24B50B0013A [MAIN]
			D 47000 (0)45
EP1	0910019544	P.C. Board	B 1786D (SW)
EP2	0910019524	P.C. Board	B 1787D (VR)
EP3	0910019550	P.C. Board	B 1868 (SPEC) B 792
EP4	0910006330	Flexible Cable P.C. Board	B 1932A (LED)
EP5 EP9	0910019931 6910000630	Ferrite Bead	FSOH070RN
EP9 EP10	6910000630	Ferrite Bead	FSOH070RN
EP10	6910000630	Ferrite Bead	FSOH070RN

REF. NO.	ORDER NO.		DESCRIPTION	
IC1	1790000050	IC	ND487C1-3R	
IC2	1110001310	IC	μРС577НА	

REF. NO.	ORDER NO.		DESCRIPTION
IC4	1110000330	IC	M5218L
IC5	1110001320	IC '	μ P C1037HA
IC6	1110001320	IC	μPC1037HA
IC8	1130003900	IC	GD4066B
IC9 IC10	1110000890 1110000330	IC IC	μPC1241H M5218L
IC11	1110000330	lic	M5218L
IC13	1130003880	l ic	GD4011B
IC14	1180000470	IC	NJM7808A
IC15	1110000290	IC	BA618
IC16	1120000970	IC	M54562P
Q1	1530000810	Transistor	2SC2053
Q2	1580000100	FET	3SK74 K
Q3 Q4	1580000100 1530000810	FET Transistor	3SK74 K 2SC2053
Q5	1520000230	Transistor	2SB909M Q
Q6	1590000340	Transistor	RN1202
Q7	1560000100	FET	2SK241-Y
Q8	1560000130	FET	2SK125
Q9	1560000130	FET	2SK125 .
Q10 Q11	1590000360 1530000110	Transistor Transistor	RN2202 2SC2458-GR
Q12	1590000340	Transistor	2502456-GR RN1202
Q13	1560000130	FET	2SK125
Q14	1560000130	FET	2SK125
Q15	1580000110	FET	3SK74 M
Q16	1560000080	FET	2SK192A-Y
Q17 Q18	1510000080 1530000110	Transistor Transistor	2SA1048-GR 2SC2458-GR
Q19	1530000110	Transistor	2SC2458-GR
Q20	1590000360	Transistor	RN2202
Q21	1580000110	FET	3SK74 M
Q22	1560000100	FET	2SK241-Y
Q23 Q24	1590000340 1590000360	Transistor Transistor	RN1202 RN2202
Q25	1590000360	Transistor	RN2202
Q26	1530000110	Transistor	2SC2458-GR
Q27	1580000110	FET	3SK74 M
Q28	1560000100	FET	2SK241-Y
Q29 Q30	1530000110 1530000110	Transistor Transistor	2SC2458-GR 2SC2458-GR
Q31	1530000110	Transistor	2SC2458-GR
Q32	1590000340	Transistor	RN1202
Q33	1590000350	Transistor	RN1204
Q34	1590000340	Transistor	RN1202
Q35 Q36	1530000110 1530000110	Transistor Transistor	2SC2458-GR 2SC2458-GR
Q37	1530000110	Transistor	2SC2458-GR
Q38	1510000080	Transistor	2SA1048-GR
Q39	1590000350	Transistor	RN1204
Q40	1530000110	Transistor	2SC2458-GR
Q41 Q42	1590000360 1530000110	Transistor	RN2202
Q42 Q44	1530000110	Transistor Transistor	2SC2458-GR 2SC2458-GR
Q45	1530000110	Transistor	2SC2458-GR
Q46	1540000070	Transistor	2SD468C
Q47	1540000070	Transistor	2SD468C
Q48	1540000070	Transistor	2SD468C
Q49 Q50	1530000110 1530000110	Transistor Transistor	2SC2458-GR 2SC2458-GR
Q51	1590000340	Transistor	RN1202
Q52	1540000150	Transistor	2SD1225M R
Q53	1510000080	Transistor	2SA1048-GR
Q54	1590000350	Transistor	RN1204
Q55	1590000350	Transistor	RN1204
Q56	1530000110	Transistor	2SC2458-GR
D1	1710000050	Diode	18853
D2	1710000050	Diode	1SS53
D3	1710000050	Diode	18853
D4	1710000000	Diode	10053
D5	1710000050 1710000050	Diode Diode	1SS53 1SS53

NO.	NO.		DESCRIPTION
D6	1710000050	Diode	1SS53
D7	1710000050	Diode	1SS53
D8 D9	1710000050 1710000050	Diode Diode	1SS53 1SS53
D10	1710000160	Diode	188133
D11	1710000160	Diode	188133
D12	1710000330	Diode	1K60
D13 D14	1710000330 1710000160	Diode Diode	1K60 1SS133
D14	1710000160	Diode	1SS53
D16	1710000050	Diode	18853
D17	1710000160	Diode	1SS133
D18 D19	1710000050 1710000050	Diode Diode	1SS53 1SS53
D20	1710000050	Diode	1SS53
D21	1710000050	Diode	1SS53
D22	1710000160	Diode	1SS133
D23 D24	1710000050 1710000050	Diode Diode	1SS53 1SS53
D25	1710000050	Diode	15553
D26	1710000050	Diode	18853
D27	1710000160	Diode	1SS133
D28 D29	1710000050 1710000050	Diode Diode	1SS53 1SS53
D30	1710000050	Diode	1SS53
D31	1710000050	Diode	18853
D32	1710000050	Diode	1SS53
D33 D34	1710000050 1710000160	Diode Diode	1SS53 1SS133
D35	1710000100	Diode	1SS53
D36	1710000050	Diode	18853
D37	1710000050	Diode	18853
D38 D39	1710000050 1710000050	Diode Diode	1SS53 1SS53
D39	1710000050	Diode	1SS53
D41	1710000050	Diode	18853
D42	1710000050	Diode	19853
D43 D44	1710000050 1710000050	Diode Diode	1SS53 1SS53
D44 D45	1710000050	Diode	1SS53
D46	1710000050	Diode	1SS53
D47	1710000050	Diode	1SS53
D48 D49	1710000050 1710000050	Diode Diode	1SS53 1SS53
D50	1710000050	Diode	1SS53
D51	1710000050	Diode	18853
D52	1710000050	Diode	1SS53
D55 D56	1710000160 1710000330	Diode Diode	1SS133 1K60
D57	1710000330	Diode	188133
D58	1710000160	Diode	188133
D59	1710000330	Diode	1K60
D60	1710000330	Diode	1K60
D61 D62	1710000160 1710000330	Diode Diode	1SS133 1K60
D63	1710000050	Diode	18853
D64	1710000160	Diode	188133
D65	1710000160	Diode Diode	1SS133 1SS133
D66 D67	1710000160 1710000050	Diode Diode	1SS133 1SS53
D68	1710000050	Diode	1SS53
D69	1710000050	Diode	18853
D70	1710000050	Diode	19953
D71 D72	1710000050 1710000160	Diode Diode	1SS53 1SS133
D73	1710000160	Diode	1SS133
D75	1710000160	Diode	188133
D76	1710000160	Diode	188133
D77 D78	1710000160 1710000160	Diode Diode	1SS133 1SS133
D79	1710000160	Diode	1SS133
D80	1730000070	Zener	RD3.9E B2
D81	1710000160	Diode	1SS133
D82 D83	1710000160 1710000160	Diode Diode	1SS133 1SS133
L			

IMAIN	011111				LIMA	UNIT		
REF. NO.	ORDER NO.		DESCRIPTION		REF. NO.	ORDER NO.		DESCRIPTION
D84	1710000160	Diode	1SS133		L50	6180000820	Coil	LAL 03NA 2R7M
D85	1710000160	Diode	188133		L51	6180000830	Coil	LAL 03NA 3R3K
D86	1710000160	Diode	155133		L52	6180000900	Coil	LAL 03NA 101K
D87	1710000160	Diode	155133		L53_	6180000800	Coil	LAL 03NA 1R8M
D88	1710000160	Diode	188133		L54	6180000780	Coil	LAL 03NA 1R2M
D89	1710000160	Diode	1SS133		L55	6180000790	Coil	LAL 03NA 1R5M
D90	1710000160	Diode	188133		L56	6180000790	Coil	LAL 03NA 1R5M
D91	1710000160	Diode	188133		L57	6180000900	Coil	LAL 03NA 101K
D92	1710000160	Diode	1SS133		L58	6180000780	Coil	LAL 03NA 1R2M
D93	1710000160	Diode	1SS133		L59	6180000770	Coil	LAL 03NA 1ROM
D94	1710000160	Diode	1SS133		L60	6180000760	Coil	LAL 03NA R82M
D95	1710000160	Diode	1SS133	1	L61	6180000760	Coil	LAL 03NA R82M
D96	1710000160	Diode	1SS133	-	L62	6180000900	Coil	LAL 03NA 101K
D97	1710000030	Diode	1S1555	1	L63	6180000760	Coil	LAL 03NA R82M
D98	1710000160	Diode	188133		L64	6180000750	Coil	LAL 03NA R68M
D99	1710000160	Diode	188133		L65	6180000750	Coil	LAL 03NA R68M
				ı	L66	6180000740	Coil	LAL 03NA R56M
,	0040000040	F:14	7014454 (5) 741		L67	6180000900	Coil	LAL 03NA 101K
FI1	2010000240	Filter	70M15A (FL-71)		L68	6180000730	Coil	LAL 03NA R47M
FI2	2010000270	Filter	9M15A (FL-23)		L69	6180000730	Coil	LAL 03NA R47M
FI3	2010000320 2010000950	Filter	9M22D2 (FL-30)		L70	6180000730	Coil	LAL 03NA R47M LAL 03NA R47M
Fi4	2010000950	Filter	9M6A1 (FL-116)	j	L71	6180000730	Coil	
		1		1	L72	6180000900 6180000700	Coil	LAL 03NA 101K
X1	6050001800	Crystal	CR-49	ı	L73	6180000700	Coil Coil	LAL 03NA R27M LAL 03NA R27M
^'	0000001000	Crystai	CR-49		L74	6180000710	Coil	LAL 03NA R33M
					L76	6180000710	Coil	LAL 03NA R33M
L1	6140000080	Coil	LR-20		L77	6150001590	Coil	LS-175
12	6180000700	Coil	LAL 03NA R27M		L78	6150001390	Coil	LS-173
L3	6180000700	Coil	LAL OSNA R33M		L79	6150001590	Coil	LS-175
L4	6180000710	Coil	LAL 03NA 5R6K		L80	6170000140	Coil	LW-15
1.5	6180000960	Coil	LAL 03NA 102K		L81	6180000690	Coil	LAL 03NA R22M
L6	6140002050	Coil	LR-224	Į.	L82	6150001220	Coil	LS-134
L7	6150001770	Coil	LS-198	1	L83	6150001210	Coil	LS-133A
L8	6110001620	Coil	LA-245		L85	6180000900	Coil	LAL 03NA 101K
L9	6180000900	Coil	LAL 03NA 101K		L86	6180000900	Coil	LAL 03NA 101K
L10	6140001460	Coil	LR-170		L87	6180000900	Coil	LAL 03NA 101K
L11	6140001260	Coil	LR-151		L88	6180000880	Coil	LAL 03NA 100K
L12	6180000740	Coil	LAL 03NA R56M		L89	6180000950	Coil	LAL 03NA 150K
L13	6180000690	Coil	LAL 03NA R22M		L90	6180000950	Coil	LAL 03NA 150K
L14	6150000990	Coil	LS-114		L91	6180000900	Coil	LAL 03NA 101K
L16	6150001770	Coil	LS-198		L92	6180000900	Coil	LAL 03NA 101K
L17	6150001770	Coil	LS-198		L93	6910000670	Coil	BT01RN1-A61-001
L18	6140002060	Coil	LR-225	1	L94	6180000900	Coil	LAL 03NA 101K
L19	6140002060	Coil	LR-225	ı	L95	6180000900	Coil	LAL 03NA 101K
L20	6180000900	Coil	LAL 03NA 101K	i	L96	6910000670	Coil	BT01RN1-A61-001
L21	6150001640	Coil	LS-180B		L97	6180000900	Coil	LAL 03NA 101K
L22	6150000700	Coil	LS-90A		L98	6910000670	Coil	BT01RN1-A61-001
L23	6150000700	Coil	LS-90A		L99	6180000900	Coil	LAL 03NA 101K
L24	6180000950	Coil	LAL 03NA 150K	1	L100	6180000900	Coil	LAL 03NA 101K
L25	6150001590	Coil	LS-175		L101	6180000900	Coil	LAL 03NA 101K
L26	6150001590	Coil	LS-175	1	L102	6910000670	Coil	BT01RN1-A61-001
L27	6140000640	Coil	LR-86		L103	6180000900	Coil	LAL 03NA 101K
L28 L29	6140000060 6110001650	Coil Coil	LR-18 LA-248	1	L104	6180002460	Coil	LAL 02KR 150K
L30	6180000700	Coil	LAL 03NA R27M					
L30	6140002050	Coil	LR-224	- 1	R1	7010004150	Resistor	R20J 470 Ω
L32	6180000880	Coil	LAL 03NA 100K		R2	7010004150	Resistor	R20J 12 Ω
L33	6150001770	Coil	LS-198	- 1	R3	7010003900	Resistor	ELR20J 470 Ω
L34	6150001770	Coil	LS-254		R4	7010003300	Resistor	R25J 22 Ω
L35	6150002430	Coil	LS-254	1	R5	7010000330	Resistor	R20J 8.2 kΩ
L36	61500002400	Coil	LS-114	1	R6	7010003920	Resistor	R20J 5.6 Ω
L37	6150001470	Coil	LS-163	- 1	R7	7010003320	Resistor	R20J 680 Ω
L38	6180000940	Coil	LAL 03NA 270K		R8	7010003250	Resistor	ELR20J 56 Ω
L39	6180000930	Coil	LAL 03NA 220K	1	R9	7010003660	Resistor	ELR20J 100 kΩ
L40	6180000900	Coil	LAL 03NA 101K	Ī	R10	7010003660	Resistor	ELR20J 100 kΩ
L41	6180000900	Coil	LAL 03NA 101K	[R11	7010003530	Resistor	ELR20J 10 kΩ
L42	6180000850	Coil	LAL 03NA 4R7K	[R12	7010003240	Resistor	ELR20J 47 Ω
L43	6180000840	Coil	LAL 03NA 3R9K	1	R13	7010003200	Resistor	ELR20J 22 Ω
L44	6180000900	Coil	LAL 03NA 101K	[]	R14	7010004170	Resistor	R20J 680 Ω
L45	6180000870	Coil	LAL 03NA 6R8K	1	R15	7010003490	Resistor	ELR20J 5.6 kΩ
L46	6180000850	Coil	LAL 03NA 4R7K		R16	7010003260	Resistor	ELR20J 68 Ω
L47	6180000900	Coil	LAL 03NA 101K		R17	7010004070	Resistor	R20J 100 Ω
L48	6180000820	Coil	LAL 03NA 2R7M		R18	7010004300	Resistor	R20J 6.8 kΩ
L49	6180000810	Coil	LAL 03NA 2R2M		R19	7010000790	Resistor	R25J 1 Ω

REF. NO.	ORDER NO.		DESCRIPTION	REF. NO.	ORDER NO.	ı	DESCRIPTION
R20	7010004230	Resistor	R20J 2.2 kΩ	R95	7010004070	Resistor	R20J 100 Ω
R21	7010003510	Resistor	ELR20J 6.8 kΩ	R96	7010004070	Resistor	R20J 100 Ω
R22	7010004090	Resistor	R20J 150 Ω	R97	7010004070	Resistor	R20J 100 Ω
R23	7010004270	Resistor	R20J 4.7 kΩ	R98	7010004070	Resistor	R20J 100 Ω
R24	7010003330	Resistor	ELR20J 270 Ω	R99	7010004070	Resistor	R20J 100 Ω R20J 100 Ω
R25	7010003330	Resistor	ELR20J 270 Ω ELR20J 18 Ω	R100 R101	7010004070 7410000180	Resistor Resistor Array	RMX- 8 103K
R26 R27	7010003190 7010003460	Resistor Resistor	ELR20J 18 Ω ELR20J 3.3 kΩ	R102	7010003350	Resistor	ELR20J 390 Ω
R28	7010003430	Resistor	R20J 2.2 kΩ	R103	7010004040	Resistor	R20J 56 Ω
R29	7010004230	Resistor	R20J 2.2 kΩ	R104	7010003620	Resistor	ELR20J 47 kΩ
R30	7010001190	Resistor	R25J 2.2 kΩ	R105	7010000870	Resistor	R25J 4.7 Ω
R31	7010003320	Resistor	ELR20J 220 Ω	R106	7010004270	Resistor	R20J 4.7 kΩ
R32	7010000990	Resistor	R25J 47 Ω	R10#	7010003740	Resistor	ELR20J 470 kΩ
R33	7010003740	Resistor	ELR20J 470 kΩ	R108	7010004370	Resistor	R20J 22 kΩ
R34	7010003580	Resistor	ELR20J 22 kΩ	R109	7010004420	Resistor	R20J 56 kΩ
R35	7510000110	Thermistor	ERT-D2FGL251S	R110	7310000750	Trimmer	RH0651C14J2WA (103) R20J 10 kΩ
R36 R37	7010004130 7010003280	Resistor Resistor	R20J 330 Ω ELR20J 100 Ω	R111 R112	7010004320 7010001030	Resistor Resistor	R25J 100 Ω
R38	7010003280	Resistor	R20J 100 kΩ	R113	7010001030	Resistor	ELR20J 3.3 MΩ
R39	7010004090	Resistor	R20J 150 Ω	R114	7010004570	Resistor	R20J 1 MΩ
R40	7010004070	Resistor	R20J 100 Ω	R115	7010004370	Resistor	R20J 22 kΩ
R41	7010003950	Resistor	R20J 10 Ω	R116	7310000750	Trimmer	RH0651C14J2WA (103)
R42	7010003620	Resistor	ELR20J 47 kΩ	R117	7010003580	Resistor	ELR20J 22 kΩ
R43	7010003660	Resistor	ELR20J 100 kΩ	R118	7010004610	Resistor	R20J 3.3 MΩ
R44	7010001030	Resistor	R25J 100 Ω	R119	7010003530	Resistor	ELR20J 10 kΩ
R45	7010003620	Resistor	ELR20J 47 kΩ	R120	7010004070	Resistor	R20J. 100 Ω
R46	7010003660	Resistor	ELR20J 100 kΩ	R121	7010004320	Resistor	R20J 10 kΩ R20J 3.3 kΩ
R47	7010003530	Resistor	ELR20J 10 kΩ	R122	7010004250 7010003360	Resistor Resistor	ELR20J 470 Ω
R48 R49	7010003510 7010004130	Resistor Resistor	ELR20J 6.8 kΩ R20J 330 Ω	R123 R124	7010003380	Resistor	ELR20J 4.7 kΩ
R50	7010004130	Resistor	ELR20J 22 kΩ	R125	7010003550	Resistor	ELR20J 15 kΩ
R51	7010003400	Resistor	ELR20J 1 kΩ	R126	7010003510	Resistor	ELR20J 6.8 kΩ
R52	7010004320	Resistor	R20J 10 kΩ	R127	7010003640	Resistor	ELR20J 68 kΩ
R53	7010004320	Resistor	R20J 10 kΩ	R128	7010003660	Resistor	ELR20J 100 kΩ
R54	7010004230	Resistor	R20J 2.2 kΩ	R129	7010003400	Resistor	ELR20J 1 kΩ
R55	7010004230	Resistor	R20J 2.2 kΩ	R130	7010004150	Resistor	R20J 470 Ω
R56	7010003460	Resistor	ELR20J 3.3 kΩ	R131	7010003700	Resistor	ELR20J 220 kΩ
R57	7010004230	Resistor	R20J 2.2 kΩ	R132	7010004340	Resistor	R20J 15 kΩ R20J 6.8 kΩ
R58	7010004070 7010004230	Resistor Resistor	R20J 100 Ω R20J 2.2 kΩ	R133	7010004300 7010004250	Resistor Resistor	R20J 3.3 kΩ
R59 R60	7010004230	Resistor	ELR20J 2.2 kΩ	R135	7010003240	Resistor	ELR20J 47 Ω
R61	7010004230	Resistor	R20J 2.2 kΩ	R136	7010004030	Resistor	R20J 47 Ω
R62	7010003440	Resistor	ELR20J 2.2 kΩ	R137	7010004070	Resistor	R20J 100 Ω
R63	7010001030	Resistor	R25J 100 Ω	R138	7310000740	Trimmer	RH0651CS3J2KA (472)
R64	7010004230	Resistor	R20J 2.2 kΩ	R139	7010003530	Resistor	ELR20J 10 kΩ
R65	7010001110	Resistor	R25J 470 Ω	R140	7510000120	Thermistor	ERT-D2FGL332S
R66	7010004110	Resistor	R20J 220 Ω	R141	7010004070	Resistor	R20J 100 Ω
R67	7010003990	Resistor	R20J 22 Ω	R142	7010003300	Resistor	ELR20J 150 Ω R20J 470 Ω
R68	7010003320	Resistor	ELR20J 220 Ω R25J 4.7 Ω	R143 R144	7010004150 7010004410	Resistor Resistor	R20J 47 kΩ
R69 R70	7010000870 7010003440	Resistor Resistor	ELR20J 2.2 kΩ	R145	7010004410	Resistor	R25J 100 Ω
R71	7010003400	Resistor	ELR20J 1 kΩ	R146	7010004230	Resistor	R20J 2.2 kΩ
R72	7010003400	Resistor	ELR20J 1 kΩ	R147	7010003440	Resistor	ELR20J 2.2 kΩ
R73	7010003360	Resistor	ELR20J 470 Ω	R148	7010003530	Resistor	ELR20J 10 kΩ
R74	7010003360	Resistor	ELR20J 470 Ω	R149	7010003830	Resistor	R20J 1 Ω
R75	7010003530	Resistor	ELR20J 10 kΩ	R150	7010003300	Resistor	ELR20J 150 Ω
R76	7010004030	Resistor	R20J 47 Ω	R151	7010003400	Resistor	ELR20J 1 kΩ
R77	7010004090	Resistor	R20J 150 Ω	R152	7010003530	Resistor	ELR20J 10 kΩ
R78	7010001530	Resistor	R25J 1 MΩ	R153	7010004320	Resistor	R20J 10 kΩ ELR20J 10 kΩ
R79	7010003990 7010004090	Resistor Resistor	R20J 22 Ω R20J 150 Ω	R154 R155	7010003530 7010004320	Resistor Resistor	R20J 10 kΩ
R80 R81	7010004090	Resistor	R25J 47 Ω	R156	7010004190	Resistor	R20J 1 kΩ
R82	7010003440	Resistor	ELR20J 2.2 kΩ	R157	7010003480	Resistor	ELR20J 4.7 kΩ
R83	7010004230	Resistor	R20J 2.2 kΩ	R158	7010001150	Resistor	R25J 1 kΩ
R84	7010004030	Resistor	R20J 47 Ω	R159	7010003400	Resistor	ELR20J 1 kΩ
R85	7310000760	Trimmer	RH0651CJ4J01A (223)	R160	7010004390	Resistor	R20J 33 kΩ
R86	7010004070	Resistor	R20J 100 Ω	R161	7010003990	Resistor	R20J 22 Ω
R87	7010004950	Resistor	R20J 1.5 MΩ	R162	7010003400	Resistor	ELR20J 1 kΩ
R88	7010003360	Resistor	ELR20J 470 Ω	R164	7010003660	Resistor	ELR20J 100 kΩ
R89	7510000100	Thermistor	ERT-D2FGL601S	R165	7010004070	Resistor Resistor	R20J 100 Ω R20J 100 kΩ
R90	7010003530 7010004030	Resistor Resistor	ELR20J 10 kΩ R20J 47 Ω	R166 R167	7010004450 7010001400	Resistor	R25J 100 kΩ
R91 R92	7010004030	Resistor	ELR20J 330 Ω	R168	7010001400	Resistor	ELR20J 100 kΩ
R93	7010003340	Resistor	R25J 470 Ω	R169	7010003440	Resistor	ELR20J 2.2 kΩ
R94	7010000330	Resistor	ELR25J 470 Ω	R170	7010004230	Resistor	R20J 2.2 kΩ
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REF. NO.	ORDER NO.	P	ESCRIPTION		REF. NO.	ORDER NO.	DESCRIPTION	
R171	7010003440	Resistor	ELR20J 2.2 kΩ		R244	7210001540	Variable Resistor	RK09K1110AEFA
R172	7010004230	Resistor	R20J 2.2 kΩ	1	R245	7010004320	Resistor	R20J 10 kΩ
R173	7010003480	Resistor	ELR20J 4.7 kΩ		R246	7010004190	Resistor	R20J 1 kΩ
R174	7010004260	Resistor	R20J 3.9 kΩ		R247	7010004300	Resistor	R20J 6.8 kΩ
R175	7010003420	Resistor	ELR20J 1.5 kΩ		R248	7010004570	Resistor	R20J 1 MΩ
R176	7010003660	Resistor	ELR20J 100 kΩ	1	R249	7010001030	Resistor	R25J 100 Ω
R177	7310000750	Trimmer	RH0651C14J2WA (103)		R250	7010004030	Resistor	R20J 47 Ω
R178	7010003660	Resistor	ELR20J 100 kΩ		R251	7010003440	Resistor	ELR20J 2.2 kΩ
R179	7310000750	Trimmer	RH0651C14J2WA (103)	ł	R252	7010003660	Resistor	ELR20J 100 kΩ
R180	7010004490	Resistor	R20J 220 kΩ	١.	R253	7010003660	Resistor	ELR20J 100 kΩ
R181	7010003440	Resistor	ELR20J 2.2 kΩ		R254	7010001280	Resistor	R25J 10 kΩ
R182	7010003480	Resistor	ELR20J 4.7 kΩ		R255	7010004190	Resistor	R20J 1 kΩ
R183	7010003530	Resistor	ELR20J 10 kΩ		R256	7010004270	Resistor	R20J 4.7 kΩ ELR20J 4.7 kΩ
R184	7010004230	Resistor	R20J 2.2 kΩ		R257 R258	7010003480 7010001360	Resistor	R25J 47 kΩ
R185	7010003720	Resistor	ELR20J 330 kΩ RH0651C15J1UA (104)	١.,	R259	7010001300	Resistor Resistor	R20J 4.7 kΩ
R186	7310000790 7010004410	Trimmer Resistor	R20J 47 kΩ		R260	7010003400	Resistor	ELR20J 1 kΩ
R187 R188	7010004410	Resistor	ELR20J 47 kΩ		R261	7010003360	Resistor	ELR20J 470 Ω
R189	7010003020	Resistor	R25J 470 Ω		R262	7010003460	Resistor	ELR20J 3.3 kΩ
R190	7010001110	Resistor	R20J 1 kΩ	1	R263	7010004230	Resistor	R20J 2.2 kΩ
R191	701000410	Resistor	R20J 47 kΩ	1	R264	7010003580	Resistor	ELR20J 22 kΩ
R192	7010003620	Resistor	ELR20J 47 kΩ		R265	7010003530	Resistor	ELR20J 10 kΩ
R193	7010004390	Resistor	R20J 33 kΩ		R266	7010001150	Resistor	R25J 1 kΩ
R194	7310000750	Trimmer	RH0651C14J2WA (103)		R267	7010003480	Resistor	ELR20J 4.7 kΩ
R195	7010003600	Resistor	ELR20J 33 kΩ		R268	7010003360	Resistor	ELR20J 470 Ω
R196	7010003780	Resistor	ELR20J 1 MΩ		R269	7010003120	Resistor	ELR20J 4.7 Ω
R197	7010004150	Resistor	R20J 470 Ω		R270	7010004300	Resistor	R20J 6.8 kΩ
R198	7010004570	Resistor	R20J 1 MΩ		R271	7010004320	Resistor	R20J 10 kΩ
R199	7010005220	Resistor	ELR20J 10 MΩ		R272	7010003380	Resistor	ELR20J 680 Ω
R200	7010004570	Resistor	R20J 1 MΩ		R273	7010004450	Resistor	R20J 100 kΩ
R201	7010004270	Resistor	R20J 4.7 kΩ		R274	7010004320	Resistor	R20J 10 kΩ
R202	7010001110	Resistor	R25J 470 Ω		R275	7010003040	Resistor	ELR20J 1 Ω
R203	7010004500	Resistor	R20J 270 kΩ					
R204	7010003720	Resistor	ELR20J 330 kΩ			4010000520	Ceramic	DD108 B 472K 50V
R205	7010003360	Resistor	ELR20J 470 Ω		C1 C2	4040000260	Barrier Layer	UZE 08X 104M
R206	7010003650	Resistor Resistor	ELR20J 82 kΩ #03 ELR20J 82 kΩ #04		C3	4010000380	Ceramic	DD107 SL 221J 50V
R206 R206	7010003650 7010003480	Resistor	ELR20J 62 KΩ #04 ELR20J 4.7 kΩ #01	1	C4	4010000360	Ceramic	DD104 SL 470J 50V
R206	7010003480	Resistor	ELR20J 4.7 kΩ #02		C5	4010000380	Ceramic	DD107 SL 221J 50V
R207	7010003510	Resistor	ELR20J 6.8 kΩ	ı	C6	4010000150	Ceramic	DD104 SL 150J 50V
R208	7310000740	Trimmer	RH0651CS3J2KA (472)	1	C7	4010000350	Ceramic	DD106 SL 151J 50V
R209	7010003530	Resistor	ELR20J 10 kΩ	1	C8	4040000110	Barrier Layer	UAT 04X 222K
R210	7310000790	Trimmer	RH0651C15J1UA (104)		C9	4040000260	Barrier Layer	UZE 08X 104M
R211	7010004530	Resistor	R20J 470 kΩ	ļ	C10	4040000130	Barrier Layer	UAT 05X 332K
R212	7010003480	Resistor	ELR20J 4.7 kΩ	1	C11	4010000050	Ceramic	DD104 SL 030C 50V
R213	7010003810	Resistor	ELR20J 2.2 MΩ	1	C12	4020000730	Cylinder	UP050 SL 150J
R214	7010003360	Resistor	ELR20J 470 Ω		C13	4010000340	Ceramic	DD105 SL 121J 50V
R215	7010001050	Resistor	R25J 150 Ω		C14	4010000520	Ceramic	DD108 B 472K 50V
R216	7010003530	Resistor	ELR20J 10 kΩ	1	C15	4010000520	Ceramic	DD108 B 472K 50V
R217	7010001400	Resistor	R25J 100 kΩ		C16	4010000020	Ceramic	DD104 SL 010C 50V
R218	7010004190	Resistor	R20J 1 kΩ		C17	4010000120	Ceramic	DD104 SL 100D 50V DD104 SL 080D 50V
R220	7010003740	Resistor	ELR20J 470 kΩ ELR20J 470 kΩ		C18 C19	4010000100 4010000020	Ceramic Ceramic	DD104 SL 000D 50V DD104 SL 010C 50V
R221 R222	7010003740 7010003530	Resistor Resistor	ELR20J 470 kΩ		C20	4010000020	Ceramic	DD104 B 102K 50V
R223	7010003530	Resistor	R20J 100 Ω		C21	4010000330	Ceramic	DD105 SL 101J 50V
R224	7010004070	Resistor	ELR20J 10 kΩ		C23	4010000220	Ceramic	DD104 SL 330J 50V
R225	7010000090	Resistor	ELR25J 4.7 Ω		C25	4010000500	Ceramic	DD104 B 102K 50V
R226	7010000370	Resistor	ELR25J 1 kΩ]	C26	4010000100	Ceramic	DD104 SL 080D 50V
R227	7010000090	Resistor	ELR25J 4.7 Ω	1	C27	4040000150	Barrier Layer	UAT 05X 472K
R228	7010000370	Resistor	ELR25J 1 kΩ		C28	4010000520	Ceramic	DD108 B 472K 50V
R229	7010000090	Resistor	ELR25J 4.7 Ω		C29	4010000500	Ceramic	DD104 B 102K 50V
R230	7010003280	Resistor	ELR20J 100 Ω	1	C30	4010000520	Ceramic	DD108 B 472K 50V
R231	7410000140	Resistor Array	RMX- 6 472K		C31	4010000070	Ceramic	DD104 SL 050C 50V
R232	7010004110	Resistor	R20J 220 Ω		C32	4010000070	Ceramic	DD104 SL 050C 50V
R233	7010003480	Resistor	ELR20J 4.7 kΩ		C33	4010000300	Ceramic	DD104 SL 680J 50V
R234	7010003480	Resistor	ELR20J 4.7 kΩ		C34	4010000020	Ceramic	DD104 SL 010C 50V
R235	7010003490	Resistor	ELR20J 5.6 kΩ		C35	4010000520	Ceramic	DD108 B 472K 50V
R236	7010004310	Resistor	R20J 8.2 kΩ		C36	4010000430	Ceramic Ceramic	DD109 SL 471J 50V DD105 SL 121J 50V
R237	7010003380	Resistor	ELR20J 680 Ω	1	C37 C38	4010000340 4020000030	Cylinder	UP125 SL 2R2K
R238 R239	7310000860 7010003540	Trimmer Resistor	RH1051D13J0JA (102) ELR20J 12 kΩ		C39	4010000030	Ceramic	DD104 SL 050C 50V
R240	7010003340	Resistor	ELR20J 2.2 kΩ		C40	4040000260	Barrier Layer	UZE 08X 104M
R241	7310000750	Trimmer	RH0651C14J2WA (103)		C42	4040000260	Barrier Layer	UZE 08X 104M
R242	7010004320	Resistor	R20J 10 kΩ		C43	4010000520	Ceramic	DD108 B 472K 50V
R243	7010001030	Resistor	R25J 100 Ω		C44	4010000520	Ceramic	DD108 B 472K 50V
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REF.	ORDER NO.		DESCRIPTION
C46	4010000520	Ceramic	DD108 B 472K 50V
C47	4010000320	Ceramic	DD108 B 472K 30V DD104 SL 270J 50V
C49	4010000520	Ceramic	DD108 B 472K 50V
C50	4040000150	Barrier Layer	UAT 05X 472K
C51 C52	4510001100 4040000150	Electrolytic Barrier Layer	16 MS7 10 μF UAT 05X 472K
C53	4040000150	Barrier Layer	UAT 05X 472K
C54	4040000150	Barrier Layer	UAT 05X 472K
C55 C56	4010000520 4010000520	Ceramic Ceramic	DD108 B 472K 50V DD108 B 472K 50V
C58	4010000340	Ceramic	DD105 SL 121J 50V
C59	4010000180	Ceramic	DD104 SL 220J 50V
C60 C61	4510001100 4510002640	Electrolytic Electrolytic	16 MS7 10 μF 25 SS 47 μF
C62	4040000260	Barrier Layer	UZE 08X 104M
C64	4010000520	Ceramic	DD108 B 472K 50V
C65 C66	4010000520 4040000260	Ceramic Barrier Layer	DD108 B 472K 50V UZE 08X 104M
C67	4040000150	Barrier Layer	UAT 05X 472K
C68	4040000150	Barrier Layer	UAT 05X 472K
C69	4040000260	Barrier Layer	UZE 08X 104M UAT 08X 473M
C70 C71	4040000250 4040000250	Barrier Layer Barrier Layer	UAT 08X 473M UAT 08X 473M
C72	4010000330	Ceramic	DD105 SL 101J 50V
C73	4040000250	Barrier Layer	UAT 08X 473M
C74 C75	4040000250 4040000250	Barrier Layer Barrier Layer	UAT 08X 473M UAT 08X 473M
C77	4010000330	Ceramic	DD105 SL 101J 50V
C78	4010000350	Ceramic	DD106 SL 151J 50V
C79 C80	4010000120 4010000320	Ceramic Ceramic	DD104 SL 100D 50V DD104 SL 820J 50V
C81	4040000260	Barrier Layer	UZE 08X 104M
C82	4010000120	Ceramic	DD104 SL 100D 50V
C83 C84	4010004840 4010004840	Ceramic Ceramic	DD305 F 104Z 12V DD305 F 104Z 12V
C85	4010004840	Ceramic	DD104 B 102K 50V
C86	4040000260	Barrier Layer	UZE 08X 104M
C87	4010000070	Ceramic	DD104 SL 050C 50V
C89 C90	4010000100 4010000100	Ceramic Ceramic	DD104 SL 080D 50V DD104 SL 080D 50V
C91	4040000260	Barrier Layer	UZE 08X 104M
C92	4010000520	Ceramic	DD108 B 472K 50V
C93 C94	4010000080 4010000520	Ceramic Ceramic	DD104 SL 060D 50V DD108 B 472K 50V
C95	4510001150	Electrolytic	50 MS7 R47 μF
C96	4010000520	Ceramic	DD108 B 472K 50V
C97 C99	4510001180 4010000520	Electrolytic Ceramic	50 MS7 3R3 μF DD108 B 472K 50V
C100	4510002640	Electrolytic	25 SS 47 μF
C101	4040000260	Barrier Layer	UZE 08X 104M
C102 C109	4010000500 4510001100	Ceramic Electrolytic	DD104 B 102K 50V 16 MS7 10 μF
C110	4040000190	Barrier Layer	UAT 05X 103K
C112	4510001100	Electrolytic	16 MS7 10 μF
C113 C114	4510001160 4010000520	Electrolytic Ceramic	50 MS7 1 μF DD108 B 472K 50V
C115	4510002640	Electrolytic	25 SS 47 μF
C116	4010000330	Ceramic	DD105 SL 101J 50V
C117 C118	4010000350 4010000520	Ceramic Ceramic	DD106 SL 151J 50V DD108 B 472K 50V
C118	4010000520	Ceramic	DD108 B 472K 50V
C120	4040000260	Barrier Layer	UZE 08X 104M
C121	4010000520 4010000520	Ceramic Ceramic	DD108 B 472K 50V DD108 B 472K 50V
C122 C123	4010000320	Ceramic Ceramic	DD108 B 472K 50V DD107 SL 221J 50V
C124	4510001140	Electrolytic	50 MS7 R22 μF
C125	4040000250	Barrier Layer	UAT 08X 473M
C126 C127	4010000520 4010000520	Ceramic Ceramic	DD108 B 472K 50V DD108 B 472K 50V
C128	4010000350	Ceramic	DD106 SL 151J 50V
C129	4010000180	Ceramic	DD104 SL 220J 50V
C130 C132	4010000520 4010000520	Ceramic Ceramic	DD108 B 472K 50V DD108 B 472K 50V
C133	4010000520	Ceramic	DD108 B 472K 50V
C135	4010000520	Ceramic	DD108 B 472K 50V

REF.	ORDER NO.	D	ESCRIPTION
C136	4010000520	Ceramic	DD108 B 472K 50V
C137	4010000180	Ceramic	DD104 SL 220J 50V
C138	4010000520	Ceramic	DD108 B 472K 50V
C139	4010000500 4010000520	Ceramic	DD104 B 102K 50V DD108 B 472K 50V
C140 C141	4010000520	Ceramic Ceramic	DD108 B 472K 50V
C142	4010000080	Ceramic	DD104 SL 060D 50V
C143	4040000080	Barrier Layer	UAT 04X 122K
C144	4040000170		UAT 05X 682K
C145 C146	4040000460 4040000210	Barrier Layer Barrier Layer	RAU 08SA 821K UAT 06X 153K
C146	4040000210	Barrier Layer	UAT 04X 152K
C148	4040000070	Barrier Layer	UAT 04X 102K
C149	4020000630	Cylinder	UP050 B 101K
C150	4040000070	Barrier Layer	UAT 04X 102K
C151 C152	4040000250 4040000260	Barrier Layer Barrier Layer	UAT 08X 473M UZE 08X 104M
C153	4040000260	Barrier Layer	UZE 08X 104M
C154	4010000520	Ceramic	DD108 B 472K 50V
C155	4040000090	Barrier Layer	UAT 04X 152K
C156 C157	4040000110 4010000410	Barrier Layer Ceramic	UAT 04X 222K DD107 SL 331J 50V
C157	4010000410	Ceramic	DD107 SE 3313 30V DD108 B 472K 50V
C159	4040000080	Barrier Layer	UAT 04X 122K
C160	4010000360	Ceramic	DD106 SL 181J 50V
C161	4040000080	Barrier Layer	UAT 04X 122K UAT 04X 222K
C162 C163	4040000110 4040000210	Barrier Layer Barrier Layer	UAT 04X 222K UAT 06X 153K
C164	4040000210	Barrier Layer	UAT 04X 122K
C165	4040000250	Barrier Layer	UAT 08X 473M
C166	4010000520	Ceramic	DD108 B 472K 50V
C167	4010000440 4010000330	Ceramic	DD109 SL 511J 50V DD105 SL 101J 50V
C168 C169	4010000330	Ceramic Ceramic	DD109 SL 471J 50V
C170	4040000080	Barrier Layer	UAT 04X 122K
C171	4040000160	Barrier Layer	UAT 05X 562K
C172	4040000460	Barrier Layer	RAU 08SA 821K UAT 08X 473M
C173 C174	4040000250 4010000520	Barrier Layer Ceramic	DD108 B 472K 50V
C175	4010000410	Ceramic	DD107 SL 331J 50V
C176	4010000270	Ceramic	DD104 SL 510J 50V
C177	4010000410	Ceramic	DD107 SL 331J 50V
C178 C179	4010000410 4040000120	Ceramic Barrier Laver	DD107 SL 331J 50V UAT 05X 272K
C180	4010000410	Ceramic	DD107 SL 331J 50V
C181	4040000250	Barrier Layer	UAT 08X 473M
C182	4010000520	Ceramic	DD108 B 472K 50V
C183 C184	4010000410 4010000260	Ceramic Ceramic	DD107 SL 331J 50V DD104 SL 470J 50V
C185	4010000380	Ceramic	DD107 SL 221J 50V
C186	4010000380	Ceramic	DD107 SL 221J 50V
C187	4040000100	Barrier Layer	UAT 04X 182K
C188 C189	4010000370 4040000250	Ceramic Barrier Layer	DD106 SL 201J 50V UAT 08X 473M
C190	4010000230	Ceramic	DD108 B 472K 50V
C191	4010000380	Ceramic	DD107 SL 221J 50V
C192	4010000160	Ceramic	DD104 SL 180J 50V
C193 C194	4010000330 4010000380	Ceramic Ceramic	DD105 SL 101J 50V DD107 SL 221J 50V
C194 C195	4040000380	Barrier Layer	UAT 04X 122K
C196	4010000350	Ceramic	DD106 SL 151J 50V
C197	4040000250	Barrier Layer	UAT 08X 473M
C198	4010000520	Ceramic	DD108 B 472K 50V DD104 SL 330J 50V
C199 C200	4010000220 4010000340	Ceramic Ceramic	DD104 SL 330J 50V DD105 SL 121J 50V
C201	4010000240	Ceramic	DD104 SL 390J 50V
C202	4010000300	Ceramic	DD104 SL 680J 50V
C203	4010000340	Ceramic	DD105 SL 121J 50V
C204 C205	4040000460 4010000330	Barrier Layer Ceramic	RAU 08SA 821K DD105 SL 101J 50V
C206	4040000250	Barrier Layer	UAT 08X 473M
C207	4010000520	Ceramic	DD108 B 472K 50V
C208	4530000350	Capacitor Array	B8ZC0111-32N DD108 B 472K 50V
C209 C210	4010000520 4510002380	Ceramic Electrolytic	16 SS 470 μF (10X12.5)
<u></u>	.5.5552500		pr. (10/1120)

IMAIN	OMIT		
REF. NO.	ORDER NO.	C	DESCRIPTION
C211	4040000260	Barrier Layer	UZE 08X 104M
C212	4510003040	Electrolytic	16 SS 100 μF
C213	4510000310	Electrolytic	16 MS16 1000 μF (12.5X16)
C214	4510002640	Electrolytic	25 SS 47 μF
C215	4510002730	Electrolytic	10 SS 100 μF
C216	4040000250	Barrier Layer	UAT 08X 473M
C217	4510001140	Electrolytic	50 MS7 R22 μF
C218 C219	4510002730 4040000110	Electrolytic Barrier Layer	10 SS 100 μF UAT 04X 222K
C220	4310000060	Mylar	F2D 50V 223K
C221	4510001100	Electrolytic	16 MS7 10 μF
C222	4510002640	Electrolytic	25 SS 47 μF
C223	4510001170	Electrolytic	50 MS7 2R2 μF
C224 C225	4040000150 4510001150	Barrier Layer Electrolytic	UAT 05X 472K 50 MS7 R47 μF
C226	4040000210	Barrier Layer	UAT 06X 153K
C227	4010000520	Ceramic	DD108 B 472K 50V
C228	4040000150	Barrier Layer	UAT 05X 472K
C229 C230	4040000150 4010000840	Barrier Layer Ceramic	UAT 05X 472K DD105 CH 390J 50V
C230	4010000040	Ceramic	DD111 CH 221J 50V
C232	4010001020	Ceramic	DD111 CH 221J 50V
C233	4010000520	Ceramic	DD108 B 472K 50V
C234	4010000520	Ceramic	DD108 B 472K 50V
C235 C236	4010000520 4040000250	Ceramic Barrier Layer	DD108 B 472K 50V UAT 08X 473M
C237	4010000180	Ceramic	DD104 SL 220J 50V
C238	4010000520	Ceramic	DD108 B 472K 50V
C239	4010000520	Ceramic	DD108 B 472K 50V
C240	4010000520 4010000220	Ceramic Ceramic	DD108 B 472K 50V DD104 SL 330J 50V
C241 C242	4310000220	Mylar	F2D 50V 223K
C243	4310000060	Mylar	F2D 50V 223K
C244	4310000060	Mylar	F2D 50V 223K
C245	4510001100 4510002850	Electrolytic	16 MS7 10 μF 25 SS 22 μF
C246 C247	4040000150	Electrolytic Barrier Layer	UAT 05Χ 472K
C248	4510002640	Electrolytic	25 SS 47 μF
C249	4510001160	Electrolytic	50 MS7 1 μF
C250	4510001170	Electrolytic	50 MS7 2R2 μF
C251 C252	4510001160 4510001160	Electrolytic Electrolytic	50 MS7 1 μF 50 MS7 1 μF
C253	4010000520	Ceramic	DD108 B 472K 50V
C254	4010000520	Ceramic	DD108 B 472K 50V
C255	4010000520 4010000520	Ceramic	DD108 B 472K 50V DD108 B 472K 50V
C256 C257	4010000520	Ceramic Ceramic	DD108 B 472K 50V
C258	4010000330	Ceramic	DD105 SL 101J 50V
C259	4010000520	Ceramic	DD108 B 472K 50V
C260	4040000260	Barrier Layer	UZE 08X 104M 16 MS7 10 µF
C261 C262	4510001100 4040000250	Electrolytic Barrier Layer	UAT 08X 473M
C263	4010000500	Ceramic	DD104 B 102K 50V
C264	4510001160	Electrolytic	50 MS7 1 μF
C265	4040000190	Barrier Layer	UAT 05X 103K
C266 C267	4040000190 4510001150	Barrier Layer Electrolytic	UAT 05X 103K 50 MS7 R47 uF
C268	4510001150	Electrolytic	50 MS7 R47 μF
C269	4510002440	Electrolytic	16 SS 220 μF (8X11)
C270	4040000260	Barrier Layer	UZE 08X 104M
C271 C272	4510002810 4530000350	Electrolytic Capacitor Array	16 SS 47 μF B8ZC0111-32N
C272	4510001160	Electrolytic	50 MS7 1 μF
C274	4010000460	Ceramic	DD104 B 471K 50V
C275	4010000520	Ceramic	DD108 B 472K 50V
C276	4510001770	Electrolytic	16 RBP 10 μF 10 SS 220 μF
C277 C278	4510002740 4510001190	Electrolytic Electrolytic	10 SS 220 μF 50 MS7 4R7 μF
C279	4040000150	Barrier Layer	UAT 05X 472K
C280	4040000150	Barrier Layer	UAT 05X 472K
C281	4010000240	Ceramic	DD104 SL 390J 50V
C282 C283	4010000160 4510001150	Ceramic Electrolytic	DD104 SL 180J 50V 50 MS7 R47 µF
C284	4010000520	Ceramic	DD108 B 472K 50V
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[MAIN UNIT]

REF. NO.	ORDER NO.		DESCRIPTION
C285	4010000520	Ceramic	DD108 B 472K 50V
C286	4010000520	Ceramic	DD108 B 472K 50V
C287	4010000520	Ceramic	DD108 B 472K 50V
C288	4010000520	Ceramic	DD108 B 472K 50V
C289	4010000520	Ceramic	DD108 B 472K 50V
C290	4010000520	Ceramic	DD108 B 472K 50V
C291	4010000430	Ceramic	DD109 SL 471J 50V
C292	4010000520	Ceramic	DD108 B 472K 50V
C293	4510001140	Electrolytic	50 MS7 R22 μF
C294	4610001200	Trimmer	CVSSE3001
C295	4010000500	Ceramic	DD104 B 102K 50V
C297	4040000250	Barrier Layer	UAT 08X 473M
C298	4040000260	Barrier Layer	UZE 08X 104M
C299	4040000260	Barrier Layer	UZE 08X 104M
C300	4040000250	Barrier Layer	UAT 08X 473M
C301	4010000520	Ceramic	DD108 B 472K 50V
RL1	6330000180	Relay	MZ-12HG
RL2	6330000560	Relay	OUC-SH-114D
S2	2230000700	Switch	SPPJ31309A [BK IN]
SO1	6510006640	Switch	50864-1
EP1	0910019635	P.C. Board	B 1788E
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[PLL UNIT]

REF. NO.	ORDER NO.		DESCRIPTION
IC1	1130000670	IC	μPD4071BC
IC2	1130000970	l IC	μPD4030BC
IC3	1130003870	IC	GD4001B
IC4	1130001270	IC	μPD4069UBC
IC5	1130003890	IC .	GD4024B
IC6	1110000240	IC .	BA222-V
IC7	1110001680	IC	S-8054ALB
IC8	1140000910	IC	HD63A01Y0G83P
IC9	1120000970	IC .	M54562P
IC10	1180000340	IC	TA78005AP
IC11	1130001360	IC	TC4021BP
IC12	1130003860	IC	MB4052M-G
IC13	1130002960	IC	TC9181P
IC14	1120001620	IC	M74ALS74AP
1C15	1120001620	IC	M74AL\$74AP
IC16	1110001320	IC	μPC1037HA
IC17	1110001320	IC	μPC1037HA
		·	
Q1	1530000110	Transistor	2SC2458-GR
Q2	1530000110	Transistor	2SC2458-GR
Q3	1530000110	Transistor	2SC2458-GR
Q4	1530000110	Transistor	2SC2458-GR
Q5	1530000110	Transistor	2SC2458-GR
Q6	1530000110	Transistor	2SC2458-GR
Q7	1530000110	Transistor	2SC2458-GR
Q8	1530000110	Transistor	2SC2458-GR
Q9	1530000110	Transistor	2SC2458-GR
Q10	1530000110	Transistor	2SC2458-GR
Q11	1530000110	Transistor	2SC2458-GR
Q12	1530000940	Transistor	2SC1571G
Q13	1530000110	Transistor	2SC2458-GR
Q14	1530000110	Transistor	2SC2458-GR

[PLL_UNIT]

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REF. NO.	ORDER NO.		DESCRIPTION	REF. NO.	ORDER NO.		DESCRIPTION
Q15	1560000090	FET	2\$K192A-GR	D55	1710000050	Diode	15553
	1530000110	Transistor	2SC2458-GR	D56	1720000050	Varicap	1SV50E
Q16 Q17	1560000000	FET	2SK192A-GR	D60	1710000160	Diode	1SS133
Q18	1530000110	Transistor	2SC2458-GR	D62	1710000160	Diode	1SS133
Q19	1560000090	FET	2SK192A-GR	D64	1710000160	Diode	1SS133
Q20	1530000110	Transistor	2SC2458-GR	D65	1710000050	Diode	1SS53
Q21	1560000090	FET	2SK192A-GR	1 500			
Q22	1530000110	Transistor	2SC2458-GR	i I			
Q23	1530000150	Transistor	2SC2668-O	X1	6060000120	Crystal	CSA4.91MG
Q24	1530000150	Transistor	2SC2668-O	X2	6050001520	Crystal	CR-21
Q25	1590000340	Transistor	RN1202	i 1		1	•
Q26	1530000150	Transistor	2SC2668-O				1
Q27	1530000150	Transistor	2SC2668-O	L1	6180000880	Coil	LAL 03NA 100K
Q29	1560000090	FET	2SK192A-GR	1 12	6140000580	Coil	LR-79
Q30	1530000150	Transistor	2SC2668-O	L3	6130000990	Coil	LB-135
Q31	1590000360	Transistor	RN2202	L4	6170000180	Coil	LW-19
Q32	1530000100	Transistor	2SC2458-Y	L5	6140000580	Coil	LR-79
Q33	1530000110	Transistor	2SC2458-GR	L6	6130000990	Coil	LB-135
Q34	1530000150	Transistor	2SC2668-O	L7	6170000180	Coil	LW-19
Q35	1590000340	Transistor	RN1202	L8	6140000580	Coil	LR-79
Q36	1530000150	Transistor	2SC2668-O	L9	6130000990	Coil	LB-135
Q37	1510000080	Transistor	2SA1048-GR	L10	6170000180	Coil	LW-19
QUI	1510000000	Transistor	20/110-10-10/11	L11	6140000580	Coil	LR-79
				L12	6130000990	Coil	LB-135
D1	1710000160	Diode	1SS133	L13	6170000180	Coil	LW-19
D3	1710000160	Diode	1SS133	L14	6180000900	Coil	LAL 03NA 101K
D3	1710000160	Diode	155133	L15	6180000900	Coil	LAL 03NA 101K
D5	1710000160	Diode	1SS133	L16	6180000740	Coil	LAL 03NA R56M
D8	1710000160	Diode	1SS133	L17	6110001560	Coil	LA-236
D9	1710000160	Diode	1SS133	L18	6110001560	Coil	LA-236
D10	1730000100	Zener	RD5.1E B2	L19	6110001550	Coil	LA-235
D10 \	1710000160	Diode	1SS133	L20	6180000900	Coil	LAL 03NA 101K
D12	1710000160	Diode	1SS133	1.22	6180000880	Coil	LAL 03NA 100K
	1710000160	Diode	1SS133	L23	6180000720	Coil	LAL 03NA R39M
D13 D14	1710000160	Diode	188133	L24	6180000700	Coil	LAL 03NA R27M
		Diode	1SS133	L25	6180000690	Coil	LAL 03NA R22M
D15	1710000160		1SS133	L26	6180000960	Coil	LAL 03NA 102K
D16	1710000160	Diode	1SS133	L27	6180000900	Coil	LAL 03NA 101K
D17	1710000160	Diode Diode	1SS133	L28	6180000900	Coil	LAL 03NA 101K
D18	1710000160 1710000160	Diode	1SS133	L29	6180000900	Coil	LAL 03NA 101K
D19		Diode	1SS133	L30	6110001650	Coil	LA-248
D20	1710000160 1710000160	Diode	1SS133	L31	6170000180	Coil	LW-19
D21 D22	1710000160	Diode	1SS133	L32	6180000850	Coil	LAL 03NA 4R7K
D23	1710000160	Diode	1SS133	L33	6910000670	Coil	BT01RN1-A61-001
D23 D24	1710000160	Diode	1SS133	L34	6170000180	Coil	LW-19
D24 D25	1710000160	Diode	1SS133	L35	6150000760	Coil	LS-94
	1710000160	Diode	1SS133	L36	6180000900	Coil	LAL 03NA 101K
D26 D27	1710000160	Diode	1SS133	L37	6180000900	Coil	LAL 03NA 101K
D27 D28	1710000160	Diode	1SS133	L38	6150000990	Coil	LS-114
D29	1710000100	Diode	1SS53	L39	6150000990	Coil	LS-114
D30	1710000050	Diode	1SS53	L40	6910000670	Coil	BT01RN1-A61-001
	1710000050	Diode	18853	L41	6110001640	Coil	LA-247
D31 D32	1710000050	Diode	1SS53	L42	6180000880	Coil	LAL 03NA 100K
D32	1710000050	Diode	1SS53	L43	6180000900	Coil	LAL 03NA 101K
D33	1710000050	Diode	1SS53	L44	6910000670	Coil	BT01RN1-A61-001
D35	1710000050	Diode	1SS133	L45	6180000960	Coil	LAL 03NA 102K
D36	1710000160	Diode	1SS133	L46	6910000670	Coil	BT01RN1-A61-001
D36	1710000160	Diode	1SS133	L47	6180000900	Coil	LAL 03NA 101K
D38	1710000160	Diode	155133	L48	6180000960	Coil	LAL 03NA 102K
D39	1710000160	Diode	155133	L49	6110001560	Coil	LA-236
D39	1710000160	Diode	155133	L50	6180000960	Coil	LAL 03NA 102K
D40 D41	1710000160	Diode	1SS133	L51	6180000960	Coil	LAL 03NA 102K
		l .		l 155.	0.0000000	55	
D42	1710000160 1710000040	Diode Diode	1SS133 1S953				
D43	1710000040	Diode	1\$\$53	R1	7010003780	Resistor	ELR20J 1 MΩ
D44		Diode	1SS133	R2	7010003760	Resistor	ELR20J 15 kΩ
D45	1710000160 1710000160	Diode Diode	1\$\$133	R3	7010003330	Resistor	R20J 10 kΩ -
D46	1710000160	Diode	1SS53	R4	7010004320	Resistor	ELR20J 2.2 MΩ
D47	1720000050	Varicap	1SV50E	R5	7010003780	Resistor	ELR20J 1 MΩ
D48 D49	1720000050	Diode	1\$\$53	R6	7010003750	Resistor	ELR20J 15 kΩ
	1720000050	Varicap	1\$V50E	R7	7010003330	Resistor	R25J 100 kΩ
D50 D51	1710000050	Diode	1SS53	R8	7010001400	Resistor	ELR20J 220 kΩ
D51	1720000050	Varicap	1SV50E	R9	7010003700	Resistor	ELR20J 100 kΩ
D52 D53	1710000050	Diode	1SS53	R10	7010003000	Resistor	ELR20J 220 kΩ
D53	1720000050	Varicap	1SV50E	R11	7010003760	Resistor	ELR20J 100 kΩ
DU4	1120000000	ranoap	.0400	l L	7.0.000000		

[PLL UNIT]

REF. NO.	ORDER NO.	DI	ESCRIPTION		REF. NO.	ORDER NO.		DESCRIPTION
R12	7010003660	Resistor	ELR20J 100 kΩ		R87	7010003310	Resistor	ELR20J 180 Ω
R13	7010004320	Resistor	R20J 10 kΩ		R88	7010003660	Resistor	ELR20J 100 kΩ
R14	7010001280	Resistor	R25J 10 kΩ		R89	7010003660	Resistor	ELR20J 100 kΩ
R15	7010004210	Resistor	R20J 1.5 kΩ		R90	7010003310	Resistor	ELR20J 180 Ω R20J 150 Ω
R16	7010003530	Resistor	ELR20J 10 kΩ ELR20J 47 kΩ		R91 R92	7010004090 7010004250	Resistor Resistor	R20J 3.3 kΩ
R17 R18	7010003620 7010004450	Resistor Resistor	R20J 100 kΩ	١.	R93	7010004250	Resistor	R20J 150 Ω
R19	7010003430	Resistor	ELR20J 47 kΩ		R94	7010004250	Resistor	R20J 3.3 kΩ
R20	7010003620	Resistor	ELR20J 47 kΩ		R95	7010003300	Resistor	ELR20J 150 Ω
R21	7010004320	Resistor	R20J 10 kΩ		R96	7010004250	Resistor	R20J 3.3 kΩ
R22	7010003620	Resistor	ELR20J 47 kΩ		R97	7010003300	Resistor	ELR20J 150 Ω ELR20J 3.3 kΩ
R23	7010003400 7010003400	Resistor Resistor	ELR20J 1 kΩ ELR20J 1 kΩ		R98 R99	7010003460 7010003780	Resistor Resistor	ELR203 3.3 K2 ELR20J 1 MΩ
R24 R25	7010003400	Resistor	ELR20J 1 kΩ		R100	7010003780	Resistor	ELR20J 1 MΩ
R26	7010003400	Resistor	ELR20J 1 kΩ		R101	7010003360	Resistor	ELR20J 470 Ω
R27	7010003400	Resistor	ELR20J 1 kΩ	l	R102	7010003530	Resistor	ELR20J 10 kΩ
R28	7010003400	Resistor	ELR20J 1 kΩ		R103	7010000990	Resistor	R25J 47 Ω
R29	7010001150	Resistor	R25J 1 kΩ	1	R104	7010003480 7010004110	Resistor Resistor	ELR20J 4.7 kΩ R20J 220 Ω
R30 R31	7010001150 7010001150	Resistor Resistor	R25J 1 kΩ R25J 1 kΩ	ł	R105 R106	7010004110	Resistor	ELR20J 330 Ω
R32	7010001150	Resistor	R25J 1 kΩ		R107	7010003990	Resistor	R20J 22 Ω
R33	7010001150	Resistor	R25J 1 kΩ		R108	7010003530	Resistor	ELR20J 10 kΩ
R34	7010001150	Resistor	R25J 1 kΩ		R109	7010003580	Resistor	ELR20J 22 kΩ
R35	7010005230	Resistor	ELR20J 750 Ω		R110	7010004070	Resistor	R20J 100 Ω
R36	7010003430	Resistor	ELR20J 1.8 kΩ		R111 R112	7010003200 7010003320	Resistor Resistor	ELR20J 22 Ω ELR20J 220 Ω
R37 R38	7010003460 7010003490	Resistor Resistor	ELR20J 3.3 kΩ ELR20J 5.6 kΩ		R113	7010003320	Resistor	ELR20J 270 Ω
R39	7010003490	Resistor	ELR20J 10 kΩ	1	R114	7010003980	Resistor	R20J 18 Ω
R40	7010003480	Resistor	ELR20J 4.7 kΩ	ĺ	R115	7010003330	Resistor	ELR20J 270 Ω
R41	7010004190	Resistor	R20J 1 kΩ	1	R116	7010001150	Resistor	R25J 1 kΩ
R42	7010004190	Resistor	R20J 1 kΩ	l	R117	7010001150	Resistor	R25J 1 kΩ R20J 1 kΩ
R43	7010001150	Resistor	R25J 1 kΩ R25J 1 kΩ	i	R118 R119	7010004190 7010001070	Resistor Resistor	R25J 220 Ω
R44 R45	7010001150 7010001150	Resistor Resistor	R25J 1 kΩ	ł	R121	7010001070	Resistor	ELR20J 4.7 kΩ
R46	7010001150	Resistor	R25J 1 kΩ	l	R123	7010003280	Resistor	ELR20J 100 Ω
R47	7010001150	Resistor	R25J 1 kΩ		R124	7010004150	Resistor	R20J 470 Ω
R48	7010001150	Resistor	R25J 1 kΩ	1	R125	7010003620	Resistor	ELR20J 47 kΩ
R49	7010004670	Resistor	R50XJ 22 Ω		R126	7010003420	Resistor	ELR20J 1.5 kΩ R20J 220 Ω
R50	7010003530 7010003240	Resistor Resistor	ELR20J 10 kΩ ELR20J 47 Ω		R127 R128	7010004110 7010003360	Resistor Resistor	ELR20J 470 Ω
R51 R52	7010003240	Resistor	ELR20J 100 kΩ		R129	7010004110	Resistor	R20J 220 Ω
R53	7010003530	Resistor	ELR20J 10 kΩ		R130	7010001150	Resistor	R25J 1 kΩ
R54	7010004030	Resistor	R20J 47 Ω		R131	7010004190	Resistor	R20J 1 kΩ
R55	7010003480	Resistor	ELR20J 4.7 kΩ	1	R132	7010004190	Resistor	R20J 1 kΩ R25J 4.7 kΩ
R56	7010003440	Resistor	ELR20J 2.2 kΩ ELR20J 47 kΩ		R133 R134	7010001230 7010003160	Resistor Resistor	ELR20J 10 Ω
R57 R58	7010003620 7010003620	Resistor Resistor	ELR20J 47 kΩ	l	R136	7010003100	Resistor	ELR20J 22 kΩ
R59	7010003020	Resistor	R20J 47 kΩ		R137	7010003660	Resistor	ELR20J 100 kΩ
R60	7010001400	Resistor	R25J 100 kΩ	1	R138	7010004090	Resistor	R20J 150 Ω
R61	7010004410	Resistor	R20J 47 kΩ		R139	7010003440	Resistor	ELR20J 2.2 kΩ
R62	7010004410	Resistor	R20J 47 kΩ		R140	7010003530	Resistor	ELR20J 10 kΩ ELR20J 4.7 kΩ
R63	7010004410	Resistor Resistor	R20J 47 kΩ R20J 47 kΩ		R141 R142	7010003480 7010003340	Resistor Resistor	ELR20J 330 Ω
R64 R65	7010004410 7010001360	Resistor	R25J 47 kΩ		R143	7010003340	Resistor	R20J 220 Ω
R66	7410000180	Resistor Array	RMX-8 103K		R144	7010003280	Resistor	ELR20J 100 Ω
R67	7010003530	Resistor	ELR20J 10 kΩ	1	R145	7010003240	Resistor	ELR20J 47 Ω
R68	7010004410	Resistor	R20J 47 kΩ	1	R146	7010003280	Resistor	ELR20J 100 Ω
R69	7010003640	Resistor	ELR20J 68 kΩ		R147 R149	7010003530 7010004070	Resistor Resistor	ELR20J 10 kΩ , R20J 100 Ω
R70 R71	7210001530 7010003460	Resistor	RK09K1110AEGA (RIT) . ELR20J 3.3 kΩ	1	R150	7010004070	Resistor	R20J 1 kΩ
R72	7010003480	Resistor	R20J 100 Ω		R151	7010003600	Resistor	ELR20J 33 kΩ
R73	7010004670	Resistor	R50XJ 22 Ω		R152	7010003440	Resistor	ELR20J 2.2 kΩ
R74	7010003400	Resistor	ELR20J 1 kΩ		R153	7010003280	Resistor	ELR20J 100 Ω
R75	7010003700	Resistor	ELR20J 220 kΩ		R155	7010004190	Resistor	R20J 1 kΩ ELR20J 4.7 kΩ
R76	7010003440 7010001150	Resistor Resistor	ELR20J 2.2 kΩ R25J 1 kΩ		R156 R157	7010003480 7010003550	Resistor Resistor	ELR20J 4.7 kΩ ELR20J 15 kΩ
R77	7010001150	Resistor	ELR20J 100 kΩ	1	R158	7010003350	Resistor	ELR20J 470 Ω
R79	7010003660	Resistor	ELR20J 100 kΩ	1	R159	7010003240	Resistor	ELR20J 47 Ω
R80	7010001060	Resistor	R25J 180 Ω	•	R160	7010003320	Resistor	ELR20J 220 Ω
R81	7010004090	Resistor	R20J 150 Ω	•	R161	7010003530	Resistor	ELR20J 10 kΩ
R82	7010003660	Resistor	ELR20J 100 kΩ		R162 R163	7010003410 7010003530	Resistor Resistor	ELR20J 1.2 kΩ ELR20J 10 kΩ
R83 R84	7010003660 7010003310	Resistor Resistor	ELR20J 100 kΩ ELR20J 180 Ω		R164	7010003530	Resistor	R20J 22 kΩ
R85	7010003660	Resistor	ELR20J 100 kΩ		R165	7010003300	Resistor	ELR20J 150 Ω
R86	7010004450	Resistor	R20J 100 kΩ	ĺ	R166	7010001030	Resistor	R25J 100 Ω
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[PLL UNIT]

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REF. NO.	ORDER NO.	D	ESCRIPTION		REF. NO.	ORDER NO.	DESCRIPTION	
R167	7010003530	Resistor	ELR20J 10 kΩ		C60	4010000860	Ceramic	DD106 CH 470J 50V
R168	7010003530	Resistor	ELR20J 10 kΩ		C61	4510002640	Electrolytic	25 SS 47 μF
R169	7010003530	Resistor	ELR20J 10 kΩ		C62	4010000680	Ceramic	DD104 CH 080D 50V
R170	7010003530	Resistor	ELR20J 10 kΩ		C63	4010000720	Ceramic	DD104 CH 120J 50V
R171	7010003620	Resistor	ELR20J 47 kΩ		C64	4010000520	Ceramic	DD108 B 472K 50V
R172	7010004410	Resistor	R20J 47 kΩ		C65	4010000520	Ceramic	DD108 B 472K 50V
R173	7010004150	Resistor	R20J 470 Ω	-	C66	4010000020	Ceramic	DD104 SL 010C 50V
R174	70,10004320	Resistor	R20J 10 kΩ		C67	4010000500	Ceramic	DD104 B 102K 50V
R175	7010004190	Resistor	R20J 1 kΩ	l l	C68	4010000860	Ceramic	DD106 CH 470J 50V
R176	7010003360	Resistor	ELR20J 470 Ω		C69	4010000630	Ceramic	DD104 CJ 030C 50V
R177	7010003360	Resistor	ELR20J 470 Ω	1	C70	4610001000	Trimmer	CVSSA0701
R178	7010003360	Resistor	ELR20J 470 Ω		C71	4010000820	Ceramic	DD105 CH 330J 50V
R179	7010003400	Resistor	ELR20J 1 kΩ	- [C72	4510002640	Electrolytic	25 SS 47 μF
R180	7010003460	Resistor	ELR20J 3.3 kΩ		C73	4010000660	Ceramic	DD104 CH 060D 50V
R181	7010003760	Resistor	ELR20J 680 kΩ	1	C74	4010000720	Ceramic	DD104 CH 120J 50V
R182	7010004320	Resistor	R20J 10 kΩ	1	C75	4010000520	Ceramic	DD108 B 472K 50V
	1 .				C76	4040000260	Barrier Layer	UZE 08X 104M
	ļ				C77	4510003040	Electrolytic	16 SS 100 μF
C1	4010000500	Ceramic	DD104 B 102K 50V	- 1	C78	4010000520	Ceramic	DD108 B 472K 50V
C2	4010000500	Ceramic	DD104 B 102K 50V		C79	4010000020	Ceramic	DD104 SL 010C 50V
C3	4510001150	Electrolytic	50 MS7 R47 μF		C80	4010000500	Ceramic	DD104 B 102K 50V
C4	4010000520	Ceramic	DD108 B 472K 50V		C81	4010000260	Ceramic	DD104 SL 470J 50V
C5	4010000500	Ceramic	DD104 B 102K 50V		C82	4040000150	Barrier Layer	UAT 05X 472K
C6	4010000500	Ceramic	DD104 B 102K 50V		C83	4010000460	Ceramic	DD104 B 471K 50V
C8	4020000400	Cylinder	UP050 B 102K		C84	4040000250	Barrier Layer	UAT 08X 473M
C9	4310000010	Mylar	F2D 50V 102K		C85	4010000380	Ceramic	DD107 SL 221J 50V
C10	4510001100	Electrolytic	16 MS7 10 μF		C86	4010000500	Ceramic	DD104 B 102K 50V
C11	4510001100	Electrolytic	16 MS7 10 μF	- }	C87	4010000240	Ceramic	DD104 SL 390J 50V
C12	4550000350	Tantalum	DN 1V 010M	ŀ	C88	4010000150	Ceramic	DD104 SL 150J 50V
C13	4550000400	Tantalum	DN 1C 2R2M		C89	4010000240	Ceramic	DD104 SL 390J 50V
C14	4040000260	Barrier Layer	UZE 08X 104M	-	C90	4010000160	Ceramic	DD104 SL 180J 50V
C15	4010000810	Ceramic	DD105 CH 300J 50V	ı	C91	4010000200	Ceramic	DD104 SL 270J 50V
C16	4010000810	Ceramic	DD105 CH 300J 50V		C92	4010000230	Ceramic	DD104 SL 360J 50V
C17	4550000400	Tantalum	DN 1C 2R2M		C93	4010000180	Ceramic	DD104 SL 220J 50V
C18	4510002640	Electrolytic	25 SS 47 μF		C94	4010000120	Ceramic	DD104 SL 100D 50V
C19	4040000260	Barrier Layer	UZE 08X 104M		C95	4040000150	Barrier Layer	UAT 05X 472K
C20	4510003040	Electrolytic	16 SS 100 μF		C96	4010000520	Ceramic	DD108 B 472K 50V
C21	4530000150	Capacitor Array		- 1	C97	4040000150	Barrier Layer	UAT 05X 472K
C22	4010000520	Ceramic	DD108 B 472K 50V	- 1	C98	4010000520	Ceramic	DD108 B 472K 50V
C23	4530000270	Capacitor Array			C99	4010000300	Ceramic	DD104 SL 680J 50V
C24	4040000250 4040000260	Barrier Layer	UAT 08X 473M	ł	C100	4010000080 4010000320	Ceramic	DD104 SL 060D 50V
C25 C26	4010000520	Barrier Layer Ceramic	UZE 08X 104M DD108 B 472K 50V		C101 C102	4010000320	Ceramic Ceramic	DD104 SL 820J 50V DD104 SL 180J 50V
C27	4510003040	Electrolytic	16 SS 100 μF		C102	4010000100	Ceramic	DD104 SL 750J 50V
C28	4010000500	Ceramic	DD104 B 102K 50V		C103	4010000510	Ceramic	DD104 3L 7300 30V
C29	4510001750	Electrolytic	50 RBP 2.2 μF	ł	C105	4040000320	Barrier Layer	UZE 08X 104M
C31	4010003460	Ceramic	DD104 UJ 330J 50V	ľ	C106	4010000520	Ceramic	DD108 B 472K 50V
C32	4040000250	Barrier Layer	UAT 08X 473M	- 1	C107	4040000250	Barrier Layer	UAT 08X 473M
C33	4010000940	Ceramic	DD107 CH 101J 50V	Į.	C108	4010000520	Ceramic	DD108 B 472K 50V
C34	4010000770	Ceramic	DD104 CH 200J 50V	ı	C109	4010000320	Ceramic	DD104 B 471K 50V
C35	4610001130	Trimmer	CVSSA1001		C110	4010000210	Ceramic	DD104 SL 300J 50V
C36	4010000900	Ceramic	DD107 CH 680J 50V	- 1	C111	4010000410	Ceramic	DD107 SL 331J 50V
C37	4510002640	Electrolytic	25 SS 47 μF	- 1	C112	4010000520	Ceramic	DD108 B 472K 50V
C38	4010000720	Ceramic	DD104 CH 120J 50V	1	C113	4040000260	Barrier Layer	UZE 08X 104M
C39	4010000720	Ceramic	DD104 CH 120J 50V		C114	4550000400	Tantalum	DN 1C 2R2M
C40	4010000520	Ceramic	DD108 B 472K 50V		C115	4010000520	Ceramic	DD108 B 472K 50V
C41	4010000520	Ceramic	DD108 B 472K 50V		C116	4010000740	Ceramic	DD104 CH 150J 50V
C42	4010000020	Ceramic	DD104 SL 010C 50V		C117	4010000810	Ceramic	DD105 CH 300J 50V
C43	4010000500	Ceramic	DD104 B 102K 50V	- 1	C118	4010000900	Ceramic	DD107 CH 680J 50V
C44	4010000900	Ceramic	DD107 CH 680J 50V	ı	C119	4010000720	Ceramic	DD104 CH 120J 50V
C45	4010000740	Ceramic	DD104 CH 150J 50V	į	C120	4010000720	Ceramic	DD104 CH 120J 50V
C46	4610001130	Trimmer	CVSSA1001		C121	4040000150	Barrier Layer	UAT 05X 472K
C47	4010000860	Ceramic	DD106 CH 470J 50V		C122	4510001100	Electrolytic	16 MS7 10 μF
C48	4510002640	Electrolytic	25 SS 47 µF		C123	4010000500	Ceramic	DD104 B 102K 50V
C49	4010000720	Ceramic	DD104 CH 120J 50V	.	C124	4010000520	Ceramic	DD108 B 472K 50V
C50	4010000720	Ceramic	DD104 CH 120J 50V		C125	4010000520	Ceramic	DD108 B 472K 50V
C51	4010000520	Ceramic	DD108 B 472K 50V	ı	C126	4010000380	Ceramic	DD107 SL 221J 50V
C52	4010000520	Ceramic	DD108 B 472K 50V	İ	C127	4040000260	Barrier Layer	UZE 08X 104M
C53	4010000020	Ceramic	DD104 SL 010C 50V		C128	4040000260	Barrier Layer	UZE 08X 104M
C54	4010000260	Ceramic	DD104 SL 470J 50V		C129	4010000520	Ceramic	DD108 B 472K 50V
C55	4010000270	Ceramic	DD104 SL 510J 50V		C130	4020000400	Cylinder	UP050 B 102K
C56	4010000500	Ceramic	DD104 B 102K 50V		C131	4040000260	Barrier Layer	UZE 08X 104M
C57	4010000870	Ceramic	DD106 CH 510J 50V		C132	4510002640	Electrolytic	25 SS 47 μF
C58	4010000700	Ceramic	DD104 CH 100D 50V	}	C133	4010000270	Ceramic	DD104 SL 510J 50V
C59	4610001000	Trimmer	CVSSA0701		C134	4610001120	Trimmer	CVSSC2001

[PLL UNIT]

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REF. NO.	ORDER NO.	D	ESCRIPTION
C135	4010003100	Ceramic	DD106 TH 820J 50V
C136	4010000520	Ceramic	DD108 B 472K 50V
C137	4010000520	Ceramic	DD108 B 472K 50V
C138	4010003100	Ceramic	DD106 TH 820J 50V
C139	4550000320	Tantalum	DN 1V OR1M
C140	4040000150	Barrier Layer	UAT 05X 472K
C141	4010000500	Ceramic	DD104 B 102K 50V
C142	4010000500	Ceramic	DD104 B 102K 50V
C143	4010000500	Ceramic	DD104 B 102K 50V
C144	4010000380	Ceramic	DD107 SL 221J 50V
C145	4040000260	Barrier Layer	UZE 08X 104M
C146	4010000100	Ceramic	DD104 SL 080D 50V
C147	4010000520	Ceramic	DD108 B 472K 50V
C148	4010000010	Ceramic	DD104 SL 0R5C 50V
C149	4010000100	Ceramic	DD104 SL 080D 50V
C150	4010000520	Ceramic	DD108 B 472K 50V
C151	4040000260	Barrier Layer	UZE 08X 104M
C152	4040000260	Barrier Layer	UZE 08X 104M
C153	4510000310	Electrolytic	16 MS16 1000 μF
			(12.5X16)
C154	4040000190	Barrier Layer	UAT 05X 103K
C155	4040000190	Barrier Layer	UAT 05X 103K
C156	4040000190	Barrier Layer	UAT 05X 103K
C157	4010000520	Ceramic	DD108 B 472K 50V
C158	4010000520	Ceramic	DD108 B 472K 50V
C159	4010000520	Ceramic	DD108 B 472K 50V
C160	4020000180	Cylinder	UP125 B 471K
C161	4040000190	Barrier Layer	UAT 05X 103K
C162	4010000210	Ceramic	DD104 SL 300J 50V
C163	4010000180	Ceramic	DD104 SL 220J 50V
C164	4010000210	Ceramic	DD104 SL 300J 50V
C165	4020000260	Cylinder	TP125 X 103M
C166	4040000250	Barrier Layer	UAT 08X 473M
C167	4040000250	Barrier Layer	UAT 08X 473M
C168	4040000250	Barrier Layer	UAT 08X 473M
BT1	3020000020	Lithium Battery	BR2032-1T2
EP1	6910000600	Ferrite Bead	FSOH050RN
EP2	0910019436	P.C. Board	B 1789F

[DDS UNIT]

REF. NO.	ORDER NO.	ı	DESCRIPTION
IC1	1140000500	IC	SC1051
IC2	1130002600	l ic	SC1052
1C3	1130002610	IC	SC1053
IC4	1130002460	IC	TC74HCT374F
IC5	1130002460	IC	TC74HCT374F
X1	6050003230	Crystal	CR-180
L1	6200000040	Coil	LQN 5N 331K
L2	6200000040	Coil	LQN 5N 331K
L3	6200000040	Coil	LQN 5N 331K
R1	7030000740	Resistor	MCR10EZHJ 1 MΩ (105)
R2	7030000360	Resistor	MCR10EZHJ 680 Ω (681)
R3	7030000420	Resistor	MCR10EZHJ 2.2 kΩ (222)
R4	7410000320	Resistor Array	GF 5096
R5	7030000500	Resistor	MCR10EZHJ 10 kΩ (103)
R6	7030000500	Resistor	MCR10EZHJ 10 kΩ (103)
R7	7030000500	Resistor	MCR10EZHJ 10 kΩ (103)

[DDS UNIT]

REF. NO.	ORDER NO.		DESCRIPTION
C1 C2 C3 C7	4610000520 4030000950 4030001150 4030000720	Trimmer Ceramic Ceramic Ceramic	TZB04N100BA006 GRM40 CH 330J 50PT GRM40 F 104Z 25PT GRM40 SL 680J 50PT
C8 C9 C10 C11 C12 C13 C14 C15 C16 C17 C18	403000560 403000750 403000610 403000750 403000640 403000720 4030001150 4030001150 4030001150 4030001150	Ceramic	GRM40 SL 020C 50PT GRM40 SL 121J 50PT GRM40 SL 070D 50PT GRM40 SL 121J 50PT GRM40 SL 120J 50PT GRM40 SL 680J 50PT GRM40 F 104Z 25PT GRM40 F 104Z 25PT
C19 C20 EP1	4030001100 4030001100 0910022511	Ceramic Ceramic P.C. Board	GRM40 B 102K 50PT GRM40 B 102K 50PT B 2203A
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[PA UNIT]

REF. NO.	ORDER NO.		DESCRIPTION
Q1	1530000790	Transistor	2SC1971
Q2	1530000190	Transistor	2SC3133
Q3	1530000190	Transistor	2SC3133
Q4	1540000200	Transistor	2SD1406 Y
Q5	1530000200	Transistor	2SC2904
Q6	1530000200	Transistor	2SC2904
Q7	1520000060	Transistor	2SB562C
Q8	1590000340	Transistor	RN1202
Q9	1590000340	Transistor	RN1202
Q10	1590000360	Transistor	RN2202
D1	1790000010	Diode	MV5
D2	1790000010	Diode	MV5
D3	1790000010	Diode	MV5
D4	1710000010	Diode	15CD11
D5	1710000030	Diode	1S1555
D6	1710000030	Diode	1S1555
D7	1710000330	Diode	1K60
D8	1710000330	Diode	1K60
D9	1710000030	Diode	1S1555
D10	1710000030	Diode	1S1555
D11	1710000030	Diode	1S1555
D12	1710000030	Diode	1S1555
D13	1710000030	Diode	1S1555
D14	1710000030	Diode	1S1555
D15	1710000030	Diode	1S1555
		:	
L1	6140001170	Coil	LR-142
L2	6910000670	Coil	BT01RN1-A61-001
L3	6910000670	Coil	BT01RN1-A61-001
L4 .	6140001300	Coil	LR-155
L5	6140000610	Coil	LR-83
L6	6140001310	Coil	LR-156
L7	6140001210	Coil	LR-146
L8	6180001230	Coil	LAL 04NA 8R2K LAL 04NA 4R7K
L9	6180001570	Coil	BT01RN1-A61-001
L10 L11	6910000670 6910000670	Coil	BT01RN1-A61-001
L112	6180000880	Coil	LAL 03NA 100K
L12	6910000670	Coil	BT01RN1-A61-001
L13	6910000670	Coil	BT01RN1-A61-001
L15	6910000670	Coil	BT01RN1-A61-001
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[PA UNIT]

REF. ORDER DESCRIPTION Registor REF. ORDER DESCRIPTION Registor REF. ORDER ORDER Registor REF. ORDER Registor REF. ORDER Registor REF. ORDER Registor Registor REF. ORDER Registor REF. ORDER Registor Registor REF. ORDER Registor Registor REF. ORDER Registor Registor Registor REF. ORDER Registor Registor Registor REF. ORDER OR	IFA OI	-			[FA ONIT]		,	
Coli				DESCRIPTION				DESCRIPTION
Cell LAL CSNA 101K EA7 7010003550 Resistor ELRSU 8.2 kG Caranic Coll LAL CSNA 101K Cell Cell	L16	6910000670	Coil	BT01RN1-A61-001		1		
128					R47	7010003520	Resistor	ELR20J 8.2 kΩ
128	L	i						
228 6140001780 Coil	3				C1	4010000520	Ceramic	DD108 B 472K 50V
14.0001739 Coli	1							· ·
140001800 Coil							Barrier Layer	UAT 08X 473M
132 140001910 Coll	L29	6140001800	Coil					
1430019320 Coll		I	•					
13.4		· ·				1		
1.35						3		
L36	B.	1						
1.33 6180000000 Coil	3	6110001490	Coil	LA-196	C10	4040000250	Barrier Layer	
1.38		ł				I .	1	
1.39 1580000900 Coll		1				I .	1	
L44			1			1		
142		[1			1		
142 6180009900 Coil			5					
Assessment Colin LAL 039A 1010K Colin LAL 039A 1010K Colin LAL 039A 100K Colin LAL		1	ì		C17	4030001340	Ceramic	
L48	L43		1			I .	i .	
L47 6180000880 Coil LAL 03NA 100K Coil LAL 03NA 100K Coil LAL 03NA 100K Coil LAL 03NA 100K Coil LAL 03NA 101K		1			i l	I .		
Care	4		4			ı	1 .	
L49		1	1			· ·		
Li50 6140001400 Coil LAL 03NA 101K C24 4510000310 Ceramic D0108 B 472K 50V LS0 Electrolytic 16 Ms16 1000 μF (12.5X16) C28 440000250 Ceramic D0107 SL 221J 50V Ceramic D0107 SL 22J 50V Ceramic Ceramic D0107 SL 22J 50V Ceramic D0108 SL 42K 50V Cera	1					I .	1 ' '	
L51					C24	4010000520	Ceramic	DD108 B 472K 50V
Resistor Resistor REAPS 330 Ω C28 4040000250 Barrier Layer UZE 08X 104M D107 SL 221 J 50V A710000330 Resistor REAPS 120 Ω C29 4510000310 Resistor REAPS 120 Ω C30 A040000250 Barrier Layer UAT 08X 473M C29 A510000310 Resistor REAPS 120 Ω C30 A040000250 Resistor REAPS 120 Ω C31 A040000250 Resistor REAPS 120 Ω C31 A040000250 Resistor REAPS 120 Ω C31 A040000250 Resistor REAPS 120 Ω C32 A010000380 Ceramic D107 SL 221 J 50V C40 A010000250 Resistor REAPS 120 Ω C33 A010000380 Ceramic D107 SL 221 J 50V C40 A010000250 Resistor REAPS 120 Ω C33 A010000380 Ceramic D107 SL 221 J 50V C40 A010000520 Ceramic D108 B 472K 50V RESISTOR RESISTO	L50	6140001460	ŧ		C25	4510000310	Electrolytic	·
R1 7010000310 Resistor R251 150 Ω C28 4010000310 Resistor R251 150 Ω C28 4010000310 Resistor R251 150 Ω C28 4510000310 Resistor R251 150 Ω C28 A010000250 Resistor R251 170 Ω C31 A040000250 Resistor R251 170 Ω C31 A040000250 Resistor R251 170 Ω C32 A010000380 Resistor R251 170 Ω C34 A010000380 Resistor R251 170 Ω C34 A010000380 C47 A010000380 Resistor R251 170 Ω C34 A010000380 C47 A010000380 C47 A01000380 C47 A01000380 C47 A01000380 C47 A01000380 C47 A010000380 C47 A01000380 C47	L51	6140001340	Coil	LR-163				· · · · · · · · · · · · · · · · · · ·
R1						I .		
R3	l _{B1}	7010000310	Resistor	FI R25.1 330 O		I .	1	
R3						1	1 -	
Resistor		Resistor	ELR25J 220 Ω				(12.5X16)	
Resistor Resistor Resistor Resistor Resistor R50XJ 120 Ω C32 A010000380 Ceramic DD107 SL 221J 50V C37 Common C34 A010002780 Ceramic DD108 B 472K 50V C35 A010000520 Ceramic DD108 B 472K 50V C37 A040000250 Ceramic DD108 B 472K 50V C47 A040000550 Ceramic C47 A040000550 Ceramic C47 A040000550 Ceramic C47 A040000550 Ceramic DD108 B 472K 50V		1	Resistor			I .	1	
R8						I .		
R8			i .			I .		
Resistor R25J 47 Ω C35			i			1		
R11	L .			, ,		I .		· ·
R12 7010004730 Resistor R50XJ 120 Ω C38 4010000520 Ceramic DD108 B 472K 50V R13 7010004650 Resistor R50XJ 10 Ω C39 4010000520 Ceramic DD108 B 472K 50V R15 7080000650 Resistor RSS1P 3R3 Ω C40 4030001340 Ceramic C41 4510002640 Electrolytic 25 SS 47 µF R16 7080000650 Resistor RSS1P 3R3 Ω C42 4010000520 Ceramic DD108 B 472K 50V R17 7080000650 Resistor RSS1P 3R3 Ω C43 4320000290 Dip Mica DM20C 152J5 DD108 R19 7310000710 Resistor R50XJ 120 Ω C44 4010004040 Ceramic DD108 L 151K 500V R19 7310000710 Resistor R50XJ 10 Ω C45 4010004100 Ceramic DD10 SL 151K 500V R22 708000650 Resistor R50XJ 10 Ω C46 4320000330 Dip Mica DM20C 272J5 R21 7010004650 Resistor R50XJ 10 Ω C47 4010004030 Ceramic DD10 SL 121K 500V R22 708000650 Resistor RSS1P 3R3 Ω C48 4320000330 Dip Mica DM20C 272J5 R23 7080000650 Resistor RSS1P 3R3 Ω C48 4320000290 Dip Mica DM20C 152J5 R24 7070000250 Resistor RSS1P 3R3 Ω C48 4320000290 Dip Mica DM20C 152J5 R24 7070000250 Resistor CRH200 R02J 4.7 Ω (4R7) C50 4010004050 Ceramic DD12 SL 221K 500V R25 7010000370 Resistor ELR25J 1 kΩ C52 4010004070 Ceramic DD12 SL 221K 500V R28 7010000370 Resistor R25J 330 Ω C54 4010004070 Ceramic DD12 SL 221K 500V R29 7010004150 Resistor R20J 470 Ω C55 4010004070 Ceramic DD12 SL 221K 500V R31 7010003400 Resistor R20J 470 Ω C55 4010004070 Ceramic DD12 SL 221K 500V R33 7010003400 Resistor ELR20J 39 kΩ C56 4010004070 Ceramic DD12 SL 221K 500V R33 7010003600 Resistor ELR20J 39 kΩ C56 4010004070 Ceramic DD12 SL 221K 500V R33 7010003600 Resistor R20J 4.7 kΩ C66 4010004070 Ceramic DD12 SL 221K 500V R33 7010003600 Resistor ELR20J 39 kΩ C66 4010004070 Ceramic DD12 SL 221K 500V R33 7010003660 Resistor ELR20J 39 kΩ C66 4010004070 Ceramic DD12	R10	7010000990	Resistor	R25J 47 Ω		•		• • • • • • • • • • • • • • • • • • •
R13								
R14								
R15						P .		
R16							1	
R18	li .		1		C42	4010000520	Ceramic	DD108 B 472K 50V
R19	R17	7080000650	Resistor					
R20					I I	i i		
R21 7010004650 Resistor R50XJ 10 Ω C47 4010004030 Ceramic DD10 SL 121K 500V R22 7080000650 Resistor RSS1P 3R3 Ω C48 4320000290 Dip Mica DM20C 152J5 R24 7070000250 Resistor CRH200 R-02J 4.7 Ω (4R7) C50 4010004070 Ceramic DD12 SL 221K 500V R25 7010000370 Resistor CP-5AJ 0.012 Ω C52 4010004070 Ceramic DD10 SL 151K 500V R26 710000370 Resistor CP-5AJ 0.012 Ω C52 4010004070 Ceramic DD10 SL 121K 500V R27 701000370 Resistor REL75J 1 kΩ C53 4320000280 Dip Mica DM20C 122J5 R28 701000190 Resistor R25J 330 Ω C54 4010004070 Ceramic DD12 SL 221K 500V R29 7010004150 Resistor R20J 470 Ω C55 4010004070 Ceramic DD12 SL 221K 500V R30 7010004190 Resistor ELR20J 36 kΩ C57 401	1	,				1		
R22 708000650 Resistor RSS1P 3R3 Ω C48 4320000290 Dip Mica DM20C 152J5	1		i			I .		
R23 7080000650 Resistor RSS1P 3R3 Ω C49 4010004070 Ceramic DD12 SL 221K 500V		(I .		DM20C 152J5
R25 7010000370 Resistor ELR25J 1 kΩ C51 4010004040 Ceramic DD10 SL 151K 500V R26 7100000510 Resistor CP-5AJ 0.012 Ω C52 4010004070 Ceramic DD12 SL 221K 500V R27 701000370 Resistor ELR25J 1 kΩ C53 4320000280 Dip Mica DM20C 122J5 R28 7010001090 Resistor R25J 330 Ω C54 4010003990 Ceramic DD09 SL 680K 500V R29 7010004150 Resistor R20J 470 Ω C55 4010004070 Ceramic DD12 SL 221K 500V R30 7010004190 Resistor R20J 1 kΩ C56 4010004070 Ceramic DD12 SL 221K 500V R31 7010003490 Resistor ELR20J 5.6 kΩ C57 4010004070 Ceramic DD12 SL 221K 500V R33 7010003610 Resistor ELR20J 39 kΩ C59 4010004070 Ceramic DD12 SL 221K 500V R34 7010004020 Resistor R20J 39 Ω C60 4010004070 Ceramic				RSS1P 3R3 Ω		I .	•	
R26			1	• • •			1	
R27	1	1	i			I		
R28	1	1				1		
R29	3		T .				1 '	
R30						I	1	DD12 SL 221K 500V
R32 7510000070 Thermistor ERT-D2FHL503S C58 4010004070 Ceramic DD12 SL 221K 500V	1					1	1	
R33 7010003610 Resistor ELR20J 39 kΩ C59 4010004050 Ceramic DD12 SL 181K 500V		1	i e			1		
R34 7010004020 Resistor R20J 39 Ω C60 4010004010 Ceramic DD09 SL 101K 500V	E .		l .			ľ		
R35 7010004060 Resistor R20J 82 Ω C61 4010004070 Ceramic DD12 SL 221K 500V	E		1					
R36 7010004270 Resistor R20J 4.7 kΩ C62 4010004070 Ceramic DD12 SL 221K 500V	4		l			· ·	1	
R38 7010003660 Resistor ELR20J 100 kΩ C64 4010003950 Ceramic DD06 SL 330K 500V R39 7010004270 Resistor R20J 4.7 kΩ C65 4010004070 Ceramic DD12 SL 221K 500V R40 7010003550 Resistor ELR20J 15 kΩ C66 4010004050 Ceramic DD12 SL 121K 500V R41 7010003660 Resistor ELR20J 100 kΩ C67 4010004030 Ceramic DD10 SL 121K 500V		1	1		C62	4010004070		
R39 7010004270 Resistor R20J 4.7 kΩ C65 4010004070 Ceramic DD12 SL 221K 500V R40 7010003550 Resistor ELR20J 15 kΩ C66 4010004050 Ceramic DD12 SL 181K 500V R41 7010003660 Resistor ELR20J 100 kΩ C67 4010004030 Ceramic DD10 SL 121K 500V		t i	l			1		
R40 7010003550 Resistor ELR20J 15 kΩ C66 4010004050 Ceramic DD12 SL 181K 500V R41 7010003660 Resistor ELR20J 100 kΩ C67 4010004030 Ceramic DD10 SL 121K 500V		[1	•		1		
R41 7010003660 Resistor ELR20J 100 kΩ C67 4010004030 Ceramic DD10 SL 121K 500V	1						I .	
	1							
THE TOWOOD INDUDE DOM-OUTER TITOUS FEBRUARD DESCRIPTION DESCRIPTION	R42	7540000010	Absorber	DSA-301LA	C68	4010004000	Ceramic	DD09 SL 820K 500V
R43 7010004390 Resistor R20J 33 kΩ C69 4010003930 Ceramic DD06 SL 270K 500V	1		t			E .		
	L	L					-	

[PA UNIT]

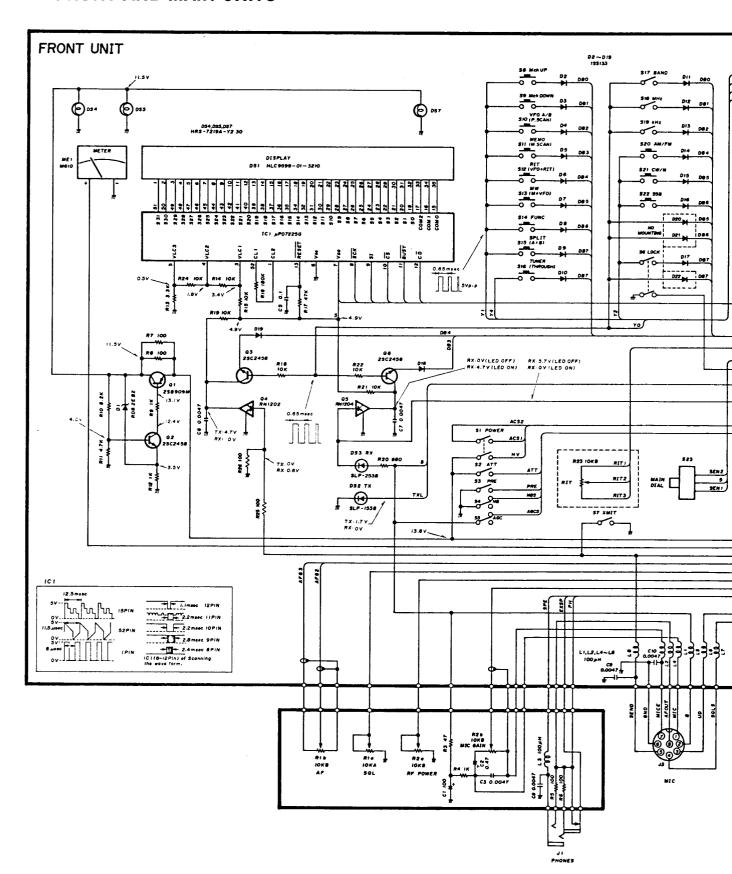
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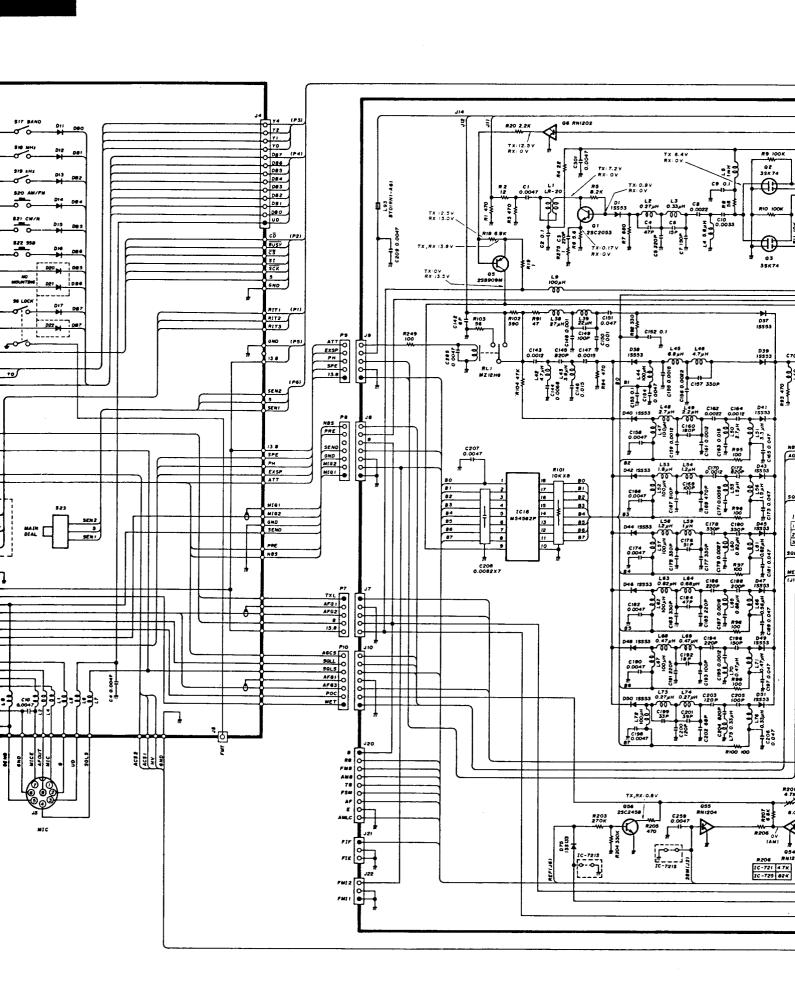
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C70	4010004030	Ceramic	DD10 SL 121K 500V
C71	4010004050	Ceramic	DD12 SL 181K 500V
C72	4010003960	Ceramic	DD06 SL 390K 500V
C73	4010004050	Ceramic	DD12 SL 181K 500V DD09 SL 101K 500V
C74	4010004010 4010003870	Ceramic Ceramic	DD09 SL 101K 500V
C76	4010003070	Ceramic	DD12 SL 221K 500V
C77	4010003950	Ceramic	DD06 SL 330K 500V
C78	4010004010	Ceramic	DD09 SL 101K 500V
C79	4010003990	Ceramic	DD09 SL 680K 500V
C80 C81	4010003960 4010004040	Ceramic Ceramic	DD06 SL 390K 500V DD10 SL 151K 500V
C82	4010003870	Ceramic	DD06 SL 120K 500V
C83	4010003990	Ceramic	DD09 SL 680K 500V
C84	4040000250	Barrier Layer	UAT 08X 473M
C85	4040000250	Barrier Layer	UAT 08X 473M
C86 C87	4040000250 4040000250	Barrier Layer Barrier Layer	UAT 08X 473M UAT 08X 473M
C88	4040000250	Barrier Layer	UAT 08X 473M
C89	4040000250	Barrier Layer	UAT 08X 473M
C90	4010000520	Ceramic	DD108 B 472K 50V
C91	4010000520	Ceramic	DD108 B 472K 50V
C92 C93	4010000520 4010000520	Ceramic Ceramic	DD108 B 472K 50V DD108 B 472K 50V
C93	4010000520	Ceramic	DD108 B 472K 50V
C95	4010000520	Ceramic	DD108 B 472K 50V
C96	4610001120	Trimmer	CVSSC2001
C97	4010000410	Ceramic	DD107 SL 331J 50V
C98	4010000410	Ceramic	DD107 SL 331J 50V DD109 SL 471J 50V
C99 C100	4010000430 4010000430	Ceramic Ceramic	DD109 SL 471J 50V
C101	4040000250	Barrier Layer	UAT 08X 473M
C102	4010000330	Ceramic	DD105 SL 101J 50V
C103	4010000120	Ceramic	DD104 SL 100D 50V
C104	4010000330	Ceramic	DD105 SL 101J 50V
RL1	6330000180	Relay	MZ-12HG MZ-12HG
RL2 RL3	6330000180 6330000180	Relay Relay	MZ-12HG
RL4	6330000180	Relay	MZ-12HG
RL5	6330000180	Relay	MZ-12HG
RL6	6330000180	Relay	MZ-12HG
RL7	6330000180	Relay	MZ-12HG
RL8	6330000180 6330000180	Relay Relay	MZ-12HG MZ-12HG
RL10	6330000180	Relay	MZ-12HG
RL11	6330000180	Relay	MZ-12HG
RL12	6330000180	Relay	MZ-12HG
RL13	6330000720	Relay	DS1-M-DC12V (AG2013)
F1	5210000130	Fuse	FGB 4A
F2	5220000020	Holder	S-N5051
F3	5220000020	Holder	S-N5051
S1	6910000060	Thermostat	OHD-3 90M
SP1	2510000040	Speaker	C065K12i0810
MF1	2710000160	Fan Motor	HMK2605-01-100
EP1	6910000600	Ferrite Bead	FSOH050RN
EP2	6910000600	Ferrite Bead	FSOH050RN
EP3	6910000600	Ferrite Bead	FSOH050RN
EP4 EP5	6910000600 6910000600	Ferrite Bead Ferrite Bead	FSOH050RN FSOH050RN
EP6	6910000600	Ferrite Bead	FSOH050RN
EP13	0910019444	P.C. Board	B 1790D (PA)
EP14	0910018743	P.C. Board	B 1791C (FILTER)
EP15	6910000600	Ferrite Bead	FSOH050RN

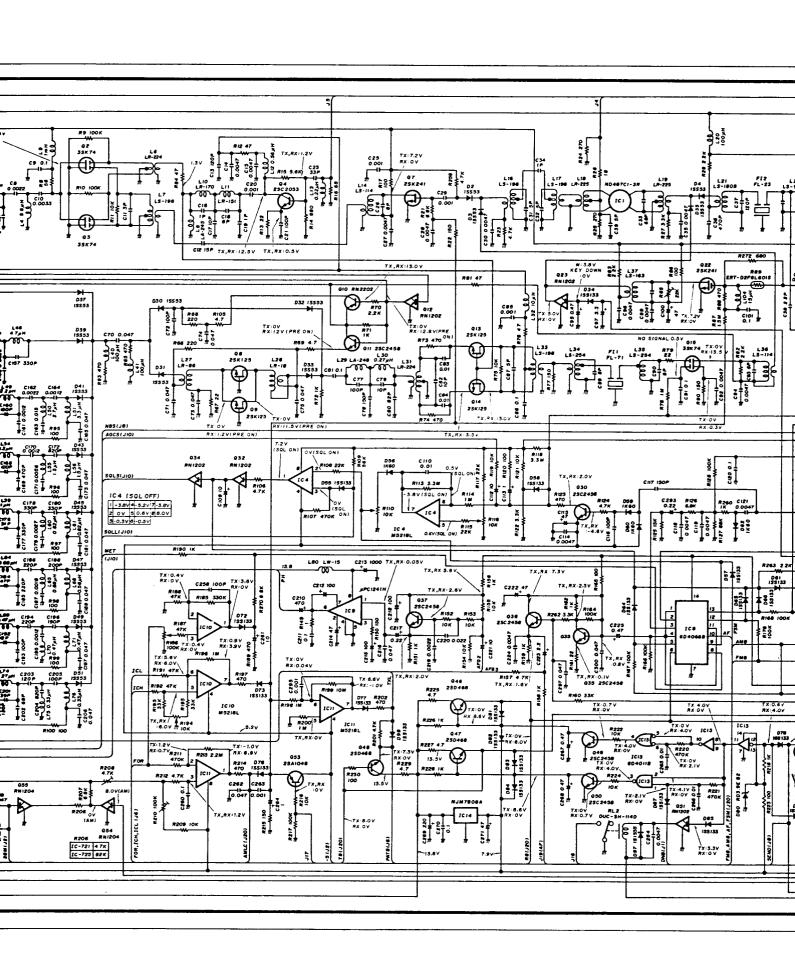
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EP16 EP20 EP21 EP33	6910000600 6910000630 6910000630 6910000630	Ferrite Bead Ferrite Bead Ferrite Bead Ferrite Bead	FSOH050RN FSOH070RN FSOH070RN FSOH070RN	
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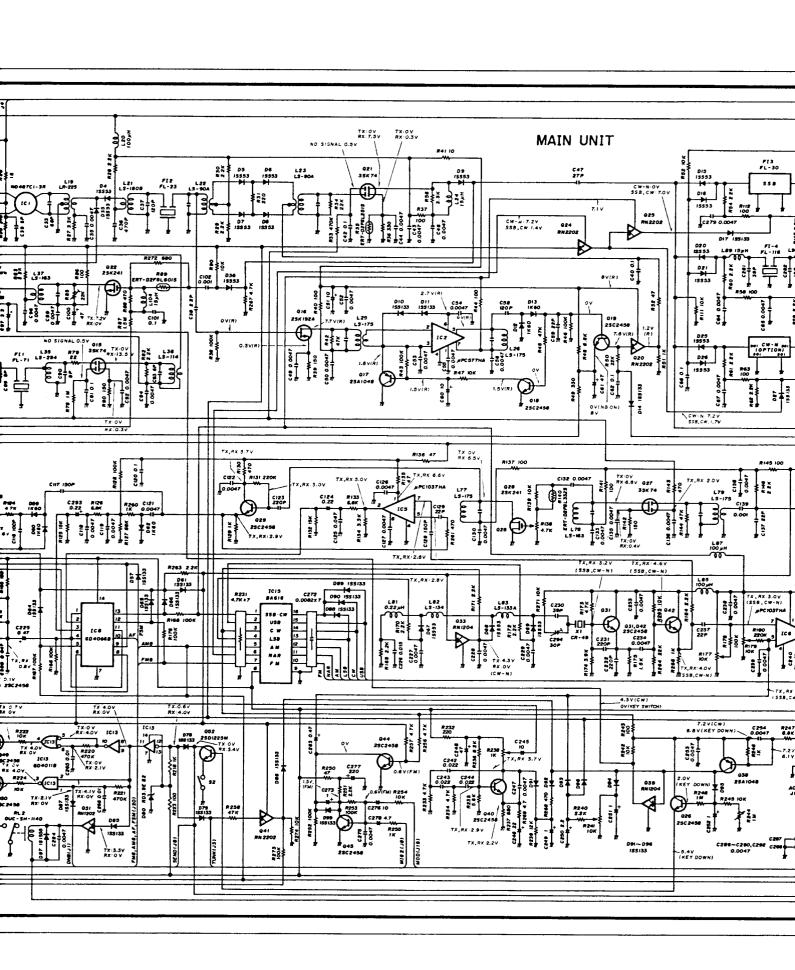
SECTION 9 VOLTAGE DIAGRAMS

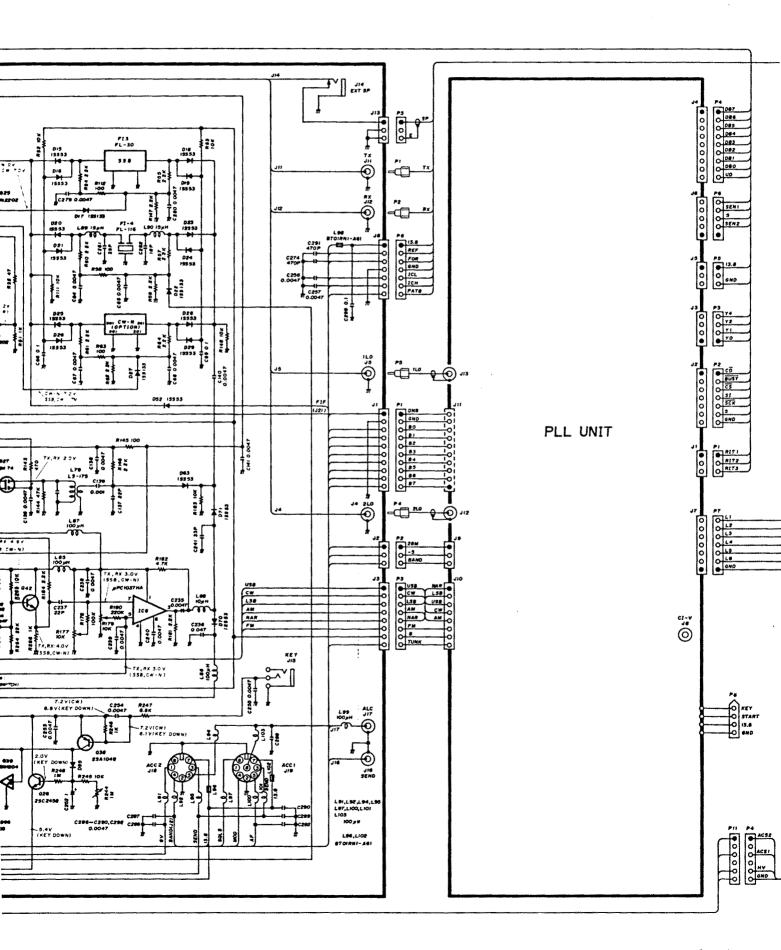
9-1 FRONT AND MAIN UNITS

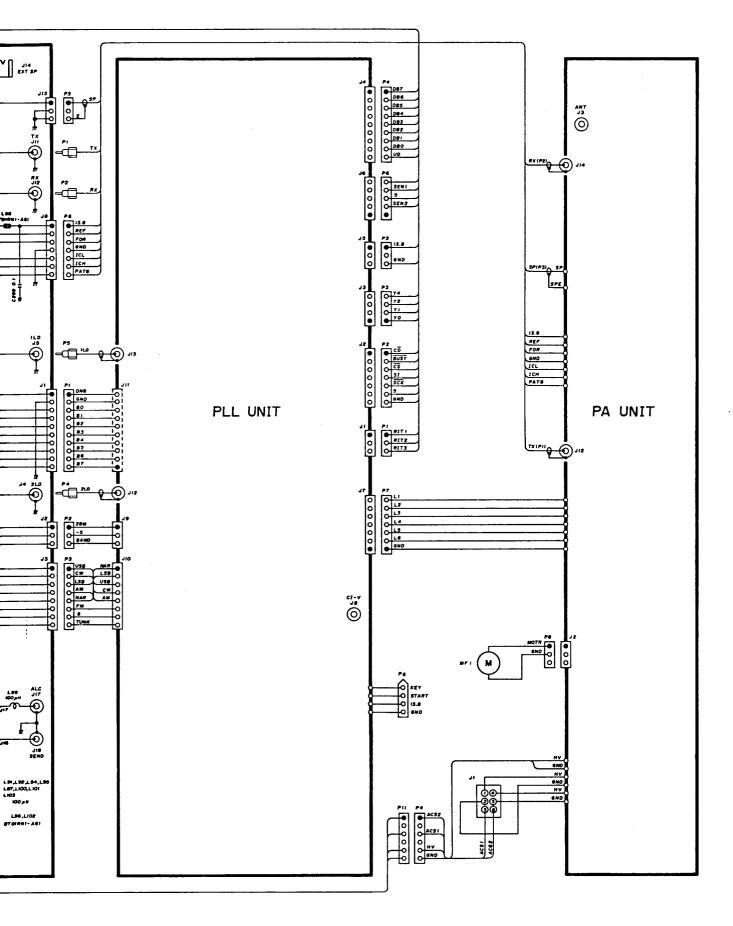


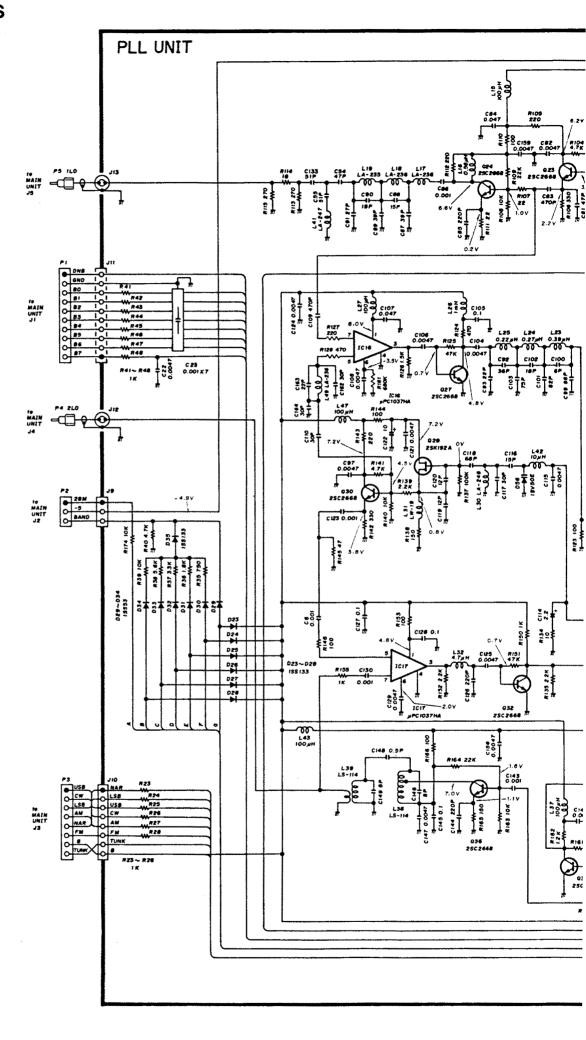


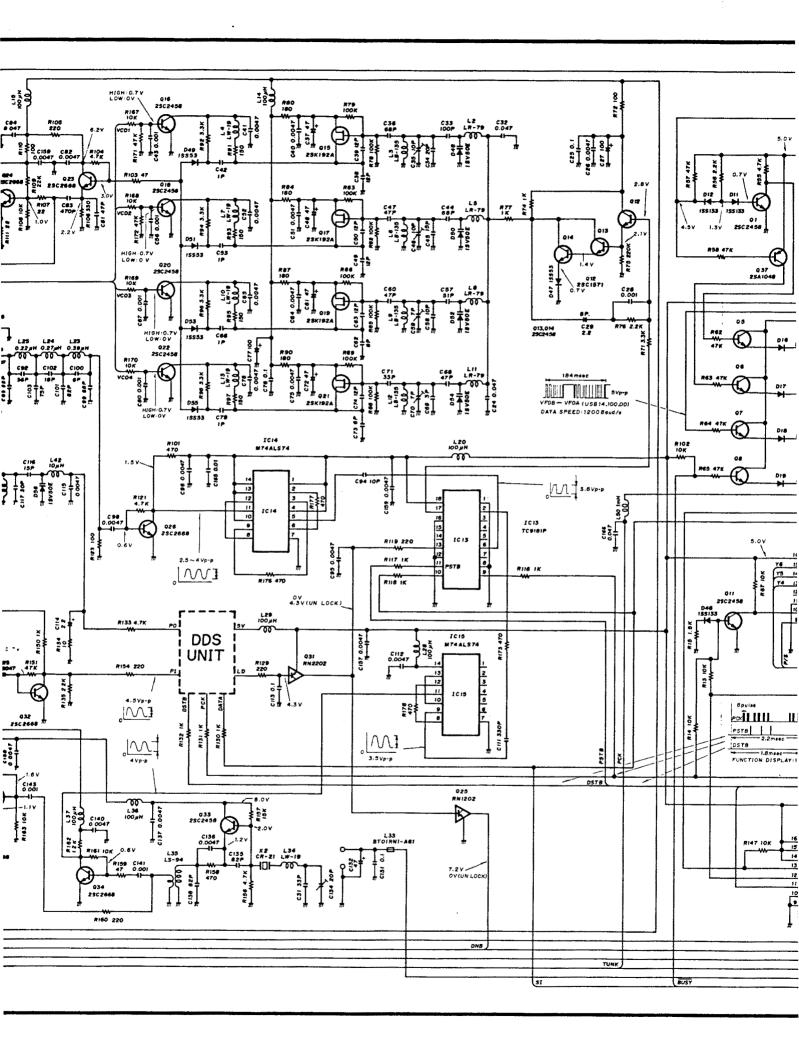


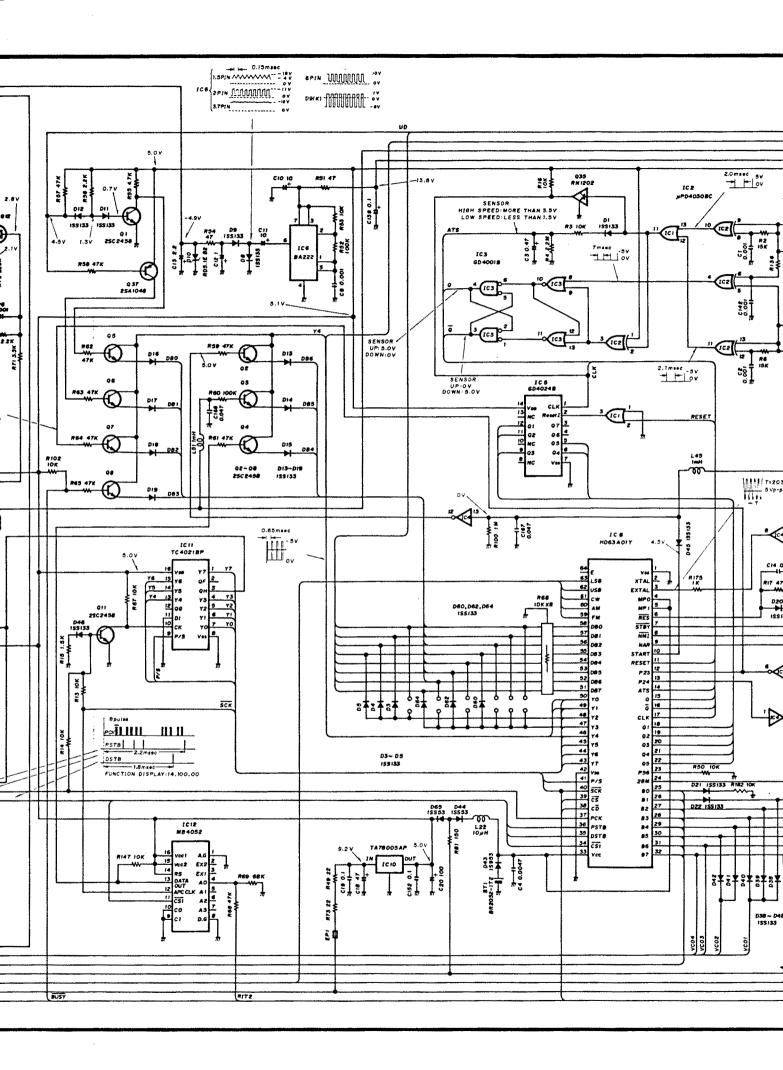


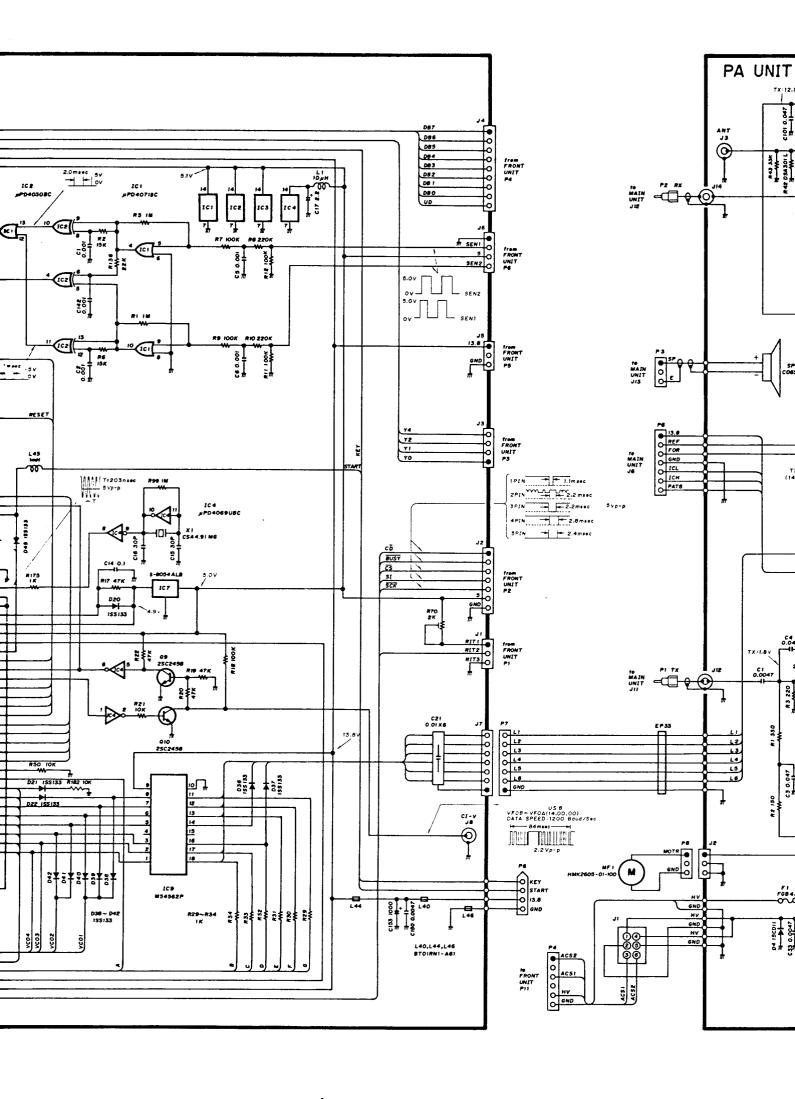


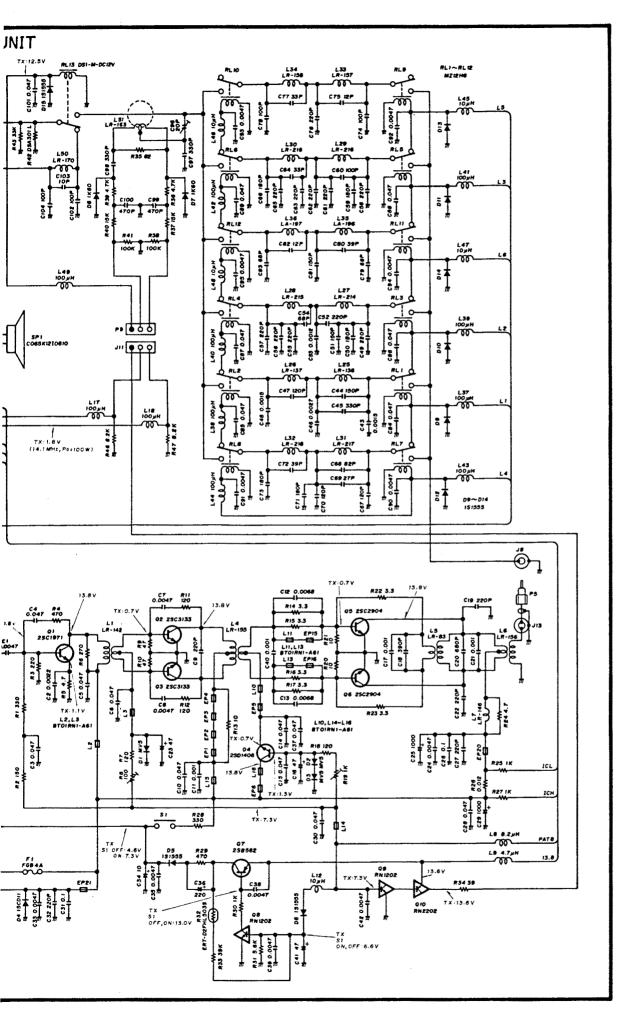












Icom Inc.

6-9-16, Kamihigashi, Hirano-ku, Osaka 547, Japan

Phone: 06 793 5301 Fax : 06 793 0013 Telex: 05277822 ICOMTR J

Icom America Inc.

<Corporate Headquarters>

Corporate Headquarters
 2380 116th Avenue N.E., Bellevue, WA 98004, U.S.A.
 Phone: (206) 454-8155
 Fax : (206) 454-1509
 Telex : 152210 ICOM AMER BVUE

<Customer Service> Phone: (206) 454-7619

<Regional Customer Service Centers> 3150 Premier Drive, Suite 126, Irving, TX 75063, U.S.A. Phone: (214) 550-7525 Fax : (214) 550-7423

1777 Phoenix Parkway, Suite 201, Atlanta, GA 30349, U.S.A. Phone : (404) 991-6166 Fax : (404) 991-6327

Icom Canada

A Division of Icom America Inc. 3071 #5 Road, Unit 9, Richmond, B.C., V6X 2T4, Canada Phone: (604) 273-7400 Fax : (604) 273-1900

Icom France S.a 120 Route de Revel, BP4063, 31029 Toulouse Cedex, France

Phone : 61. 20. 31. 49
Fax : 61. 34. 05. 91
Telex : 521515 ICOM FRA

Icom (Europe) GmbH

Communication Equipment Communication Equipment Himmelgeister Str. 100, 4000 Düsseldorf 1, W. Germany Phone: 0211 346047 Fax : 0211 333639 Telex: 8588082 ICOM D

Icom (Australia) Pty. Ltd.

Incorporated In Victoria

Incorporated in victoria 7 Duke Street, Windsor, Victoria, 3181, Australia Phone: 03 529 7582 Fax : 03 529 8485 Telex : AA 35521 ICOM AS

Icom (UK) Ltd.

Unit 9, Sea St., Herne Bay, Kent, U.K.

Phone: 0227 363859 Fax: 0227 360155 Telex: 965179 ICOM G

